

APPLICATION OF CHARGE SIMULATION METHOD FOR ESTIMATION
OF HIGH VOLTAGE FIELDS

A thesis Submitted
in Partial Fulfilment of the Requirements
for the Degree of

MASTER OF TECHNOLOGY

By

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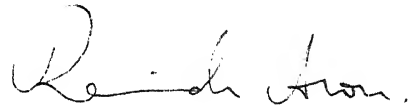
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CERTIFICATE

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ABSTRACT

The subject for estimation of HV fields gained importance ever since the beginning of Electrical Engineering by the advent of digital computers. The conventional method for the estimation like field sketching by hand and by electrolytic tanks gave up their way. Numerical methods like FDM & FEM found their breakthrough in this field, however, a revolutionary change was brought up by Steinbegler in the late 1960's when he introduced CSM, a method most appropriate and suitable for the estimation of electric field between complicated unsymmetrical electrode configurations. Although this method is being used in practice in advanced countries it has just made a breakthrough in India.

In this thesis computer programmes using CSM have been developed for simple electrode configuration having rotational symmetry and involving one and two dielectrics. Also, basic mathematical background such as plotting of equipotential surfaces, for finding vertical and horizontal components of electric fields on arbitrarily inclined interfaces and arbitrary location of simulation charges etc. has been developed for further work in this field. Certain missing links in the existing theory have been found out.

Thus this work can provide a good starting for tackling complicated electrode configuration and involving multidielectric cases.

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INTRODUCTION

The optimum design of insulation in high voltage apparatus between phase and earth is based on the knowledge of electric field distribution and the dielectric properties of the combination of insulating materials used in the system. The principal aim is that the insulation should withstand the stresses with adequate reliability and at the same time the insulation should not be overdimensioned.

The withstand voltage of the insulation of apparatus design with non-self-restoring insulation is determined by the field intensity developed at any point at the sparking gap on the electrodes. Corona discharge can be eliminated by employing properly designed high voltage shielding electrodes. Corona threshold voltage of shielding electrodes is a parameter which governs the radio and TV interferences and also in most cases the breakdown of the insulation between the electrode arrangement. Therefore, it requires a comprehensive study of the characteristics of corona discharges of the high voltage electrode system.

The pre-estimation of the electric stresses makes it possible to design apparatus with a high withstand voltage, free from corona discharge and generating low electric stresses and even resulting electric field low enough to

provide sufficient safety margin against insulation failure. Corona discharge magnitude and surface flux density of an existing electrode system can be determined experimentally with moderate accuracy but the pre-estimation of the electric stress magnitude at operating voltage can be calculated accurately with the help of computation before finalization of shield design.

Several methods are used today to calculate electric field either analytically or numerically.

For estimating electric fields, analytical solution of Laplace's equation can be obtained for relatively simple conductor configurations. However, field distributions of some of the geometries that are frequently used in high voltage apparatus, cannot be expressed in simple analytical terms.

As an alternative to purely analytical techniques, numerical methods are often used to solve such problems. These include the Finite Difference Method (FDM), the Finite Element Method (FEM), and the Charge Simulation Method (CSM).

FDM & FEM are directly based on the differential form of the Maxwell's equation. Solving differential equations either analytically or numerically involve difficulties inherent in

the formulation of inaccuracies arising within numerical procedures. These methods are also quite time consuming. On the other hand CSM is relatively simple as field strengths can be calculated analytically with reasonable accuracy because HV apparatus curved surfaces are generally preferred over sharp edges. It is also less time consuming for many geometries in HV technology.

This thesis work describes the application of CSM for some simple rotation symmetry fields as a numerical extension of image charge method (used for calculation of electric fields analytically for some simple configurations), thus, eliminating the need for formal solution of Laplace's and Poisson's equations in differential form.

CHAPTER 1

THEORY & DISCUSSION

1.1 Image charges and their applications :

Directly related to the application of Gauss's Law is the method of images (or image charges), which could be used to compute analytically some important problems by means of ready-made solutions, thus eliminating the need for formal solutions of Laplace's or Poisson's equations in differential form.

The image charge theory and the CSM are based on the uniqueness theorem which states that a solution $V(x,y,z)$ to a problem consisting of a charge distribution $\rho(x,y,z)$ and grounded conducting boundaries S_1 through S_n , is the unique solution if it satisfies the differential equation

$$\nabla^2 V = -\rho(x,y,z)/\epsilon$$

and the boundary conditions

$$V(x,y,z) = 0 \quad \text{on } S_1, S_2, \dots, S_n \quad [5]$$

The principle of uniqueness can be applied to replace the effect of conducting boundaries with image charges. Some of the important cases are presented in the following. These cases are :

1. point charge and a grounded conducting plate (or say Earth) of semi-infinite dimensions.
2. point charge and a grounded conducting sphere.
3. point charge and a sphere at voltage V .
4. a line charge and a conducting cylinder at voltage V .
5. Two conducting cylinders at voltage $+V$ and $-V$ respectively.
6. A conducting cylinder at voltage V and a grounded conducting plate (or earth surface).
7. Two conducting spheres at voltages $+V$ and $-V$ respectively.
8. A conducting sphere at voltage $+V$ and a grounded conducting plate (or earth surface); and similar few other cases.

Now the thesis discusses each of the above cases one by one. Significance of this lies in the fact that analytical methods are used to determine the location as well as the value of charges accurately. In CSM location is generally assumed (surely with certain optimization criteria) and the charge values are determined numerically.

Case 1 : Point charge and grounded conducting plate (or say Earth) of Semi-infinite dimension (Fig. 1).

Here the plate forms an equipotential surface at Voltage = 0. Thus, this plate can be replaced by a charge equal in magnitude and opposite in polarity placed symmetrically on the other side of the plate as shown in Fig. 1.

Thus voltage at any point P(r,z) would simply be

$$V(r,z) = KQ \left[\frac{1}{\sqrt{r^2 + (Z-a)^2}} - \frac{1}{\sqrt{r^2 + (Z+a)^2}} \right]$$

and Electric field components would be

$$E_r = \frac{-\partial V}{\partial r} = -2KQr \left[\frac{1}{\sqrt{r^2 + (Z-a)^2}} - \frac{1}{\sqrt{r^2 + (Z+a)^2}} \right]$$

and

$$E_z = \frac{-\partial V}{\partial z} = -2KQr \left[\frac{(z-a)}{r^2 + (z-a)^2} - \frac{(z+a)}{r^2 + (z+a)^2} \right]$$

Case 2 : Point charge and a grounded conducting sphere (Fig. 2)

Let the image charge of q be placed at x_0 and let it's magnitude be q' . Now potential at any point (x,y,z) on the sphere is

$$\nabla(x, y, z) = 0 = \frac{Kq}{\sqrt{(x-x_0)^2 + y^2 + z^2}} - \frac{Kq'}{\sqrt{(x-x_0)^2 + y^2 + z^2}}$$

$$\text{or } q^2((x-x_0)^2 + y^2 + z^2) = q'^2((x-b)^2 + y^2 + z^2)$$

i.e.

$$q^2(x-x_0)^2 - q'^2(x-b)^2 + (q^2 - q'^2)y^2 + (q^2 - q'^2)z^2 = 0$$

i.e.

$$(q^2 - q'^2)(x^2 + y^2 + z^2) = 2xx_0q^2 - 2xbq'^2 + b^2q'^2 - x_0^2q^2$$

Comparing with $x^2 + y^2 + z^2 = a^2$ we get

$$x_0q^2 - bq'^2 = 0 \rightarrow x_0 = \frac{bq'^2}{q^2} \quad (i)$$

and

$$\frac{b^2q'^2 - x_0^2q^2}{q^2 - q'^2} = a^2$$

i.e.

$$b^2q'^2 - x_0^2q^2 = a^2q^2 - a^2q'^2 \quad (ii)$$

$$\rightarrow (b^2 + a^2)q'^2 = (a^2 + x_0^2)q^2$$

Therefore,

$$b^2 q'^2 - \left[\frac{b q'^2}{q^2} \right] \cdot q^2 = a^2 q^2 - a^2 q'^2$$

$$b^2 q'^2 - \frac{b^2 q'^4}{q^2} = a^2 q^2 - a^2 q'^2$$

$$\begin{aligned} b^2 q'^2 \left(1 - \frac{q'^2}{q^2} \right) &= a^2 (q^2 - q'^2) \\ &= a^2 q^2 (1 - q'^2/q^2) \end{aligned}$$

$$\rightarrow b^2 q'^2 = a^2 q^2$$

$$\rightarrow q' = \frac{a}{b} q \quad \rightarrow \quad x_0 = \frac{a^2}{b}$$

Thus the grounded conducting sphere can be replaced by a image charge q' , placed at a distance x_0 from the centre.

The potential at any point (x, y, z) outside the sphere would be

$$V(x, y, z) = Kq \left[\frac{1}{\sqrt{(x-b)^2 + y^2 + z^2}} \right] - Kq' \left[\frac{1}{\sqrt{(x-x_0)^2 + y^2 + z^2}} \right]$$

$$K^{-1} = 4\pi\epsilon_0$$

and $\underline{E} = -\nabla \underline{V}$ which can also be calculated.

Case III : Point charge and a sphere at voltage V

In this case apart from the image charge q' placed at x_0 , one more charge $Q_0 = 4\pi\epsilon_0 V$ is placed which gives a voltage V on the sphere surface.

Thus voltage and electric field at any point outside the sphere can be calculated as

$$V(x,y,z) = \frac{Kq}{\sqrt{(x-b)^2 + y^2 + z^2}} - \frac{Kq'}{\sqrt{(x-x_0)^2 + y^2 + z^2}} + \frac{KQ_0}{\sqrt{x^2 + y^2 + z^2}}$$
$$\underline{E} = -\nabla \underline{V}$$

Case IV, Case V & Case VI [6] :

A line charge and a cylinder at voltage V (Fig. 3) or two parallel cylinders at voltage +ve and -ve, respectively.

Consider a line charge ρ_1 running parallel to a conducting cylinder of radius R and carrying a charge $Q_1 = -\rho_1$ per unit length. The cross-section of the system is shown in Fig. 4. If the electric field of charges induced on the surface of the cylinder can be reduced to the field of a certain image line charge ρ'_1 , by symmetry the image line charge ρ'_1 must be somewhere in the plane of the line charge ρ_1 and the axis of the cylinder, as indicated in Fig.4. The magnitude of the

charge ρ'_1 and its position x with respect to the cylinder axis are unknown. If possible, we must determine these so that the surface of the cylinder is equipotential.

Now, according to Gauss' law, the total charge enclosed by a cylinder coinciding with the conductor surface equals the flux of the electric field intensity through the cylinder, multiplied by ϵ_0 . If the field is assumed to be identical in the real case and that, when the cylinder is removed and the image line charge introduced instead, the flux of the electric field intensity is also the same, it follows that ρ'_1 , that is to $-\rho'_1$ must be equal to Q_1 , that is to $-\rho_1$, as indicated in Fig.4.

The potential at a point M' at a distance r from a line charge ρ_1 , with respect to a reference point at a distance r_R from the line charge, is

$$V = \int_r^{r_R} \frac{\rho_1}{2\pi\epsilon_0 r} dr = \frac{\rho_1}{2\pi\epsilon_0} \ln \frac{r_R}{r} . \quad (i)$$

The distance r_R cannot be taken to be infinite, since in this case there are charges at infinity. If we denote by r'_R and r' the corresponding from the line charge $\rho'_1 = -\rho_1$, then the potential at the same point due to ρ'_1 is

$$V' = \frac{\rho'_1}{2\pi\epsilon_0} \ln \frac{r'_R}{r'} = - \frac{\rho_1}{2\pi\epsilon_0} \ln \frac{r'_R}{r'} .$$

So the total potential at M' is

$$V_{\text{total}} = V + V' = \frac{\rho_1}{2\pi\epsilon_0} \left[\ln \frac{r_R}{r} - \ln \frac{r'_R}{r'} \right] = \frac{\rho_1}{2\pi\epsilon_0} \ln \left[\frac{r_R}{r'} \frac{r'}{R} \right]$$

(ii)

From (ii) it is clear that the equation of any equipotential surface due to the two equal line charges of opposite signs is $r'/r = \text{constant}$. Hence, if the distance x of the image line charge ρ'_1 from the axis of the cylinder can be determined so that $r'/r = \text{constant}$ for all points on the surface of the cylinder, the image line charge is completely determined.

From Fig. 4, if triangles OM'P and OP'M' are similar (if x is chosen appropriately, this can always be the case for a fixed point M') then

$$r'/r = R/b = x/R$$

[b stands for $(x+d)$, that is, for the distance from the line charge ρ_1 to the cylinder axis.] Thus, equation $r'/r = \text{constant}$ can be satisfied for any point on the cylinder surface is

$$x = R^2/b.$$

The Program 1 calculates for various points along the line joining the centres of the cylinder. The ratio of electric field at that point to the max field using image charge method.

Case VII & Case VIII : Two conducting spheres/A conducting sphere in front of a grounded conducting plate (See Fig.4) [5].

Some fields may be determined by the method of images through successive approximations. As an illustration the case of a charged sphere near a grounded plane has been considered. Both the spheres and the plane have been replaced by a set of point charges which will maintain these surfaces as equipotentials.

First a charge Q_0 is put at the centre of the sphere, as in Fig. 6. This makes the sphere, but not the plane, an equipotential. Next we put the image $-Q_0$ of Q_0 to the right of the plane. This makes the plane an equipotential but destroys the spherical equipotential, so we put the image Q_1 of $-Q_0$ inside the sphere. This makes the sphere again an equipotential but upsets the plane. We continue the process, which converges rapidly, until we have the required precision.

The maximum field strength at the points M and M' is given by

$$E_{\max} = \frac{1}{4\pi\epsilon_0} \left\{ \sum_{n=0}^{\infty} \frac{Q_n}{(a-x_n)^2} + \sum_{n=0}^{\infty} \frac{Q_n}{(2D-a-x_n)^2} \right\}$$

where

$$Q_n = Q_{n-1} \left(\frac{R}{2D - x_{n-1}} \right)$$

and
$$x_n = \frac{a^2}{(2D - x_{n-1})} \quad \text{with } n = 1, 2, 3, \dots$$

and $x_0 = 0.$

Above equations are used to calculate the field intensities between two oppositely charged metal spheres along a field line of highest field strength, i.e. between the shortest distance M-M'.

Numerical calculation of image charges has been used for above case and the error in voltage at the tip obtained by numerical technique is extremely small for a fairly large number of charges.

In case of sphere and a plate, another hypothetical sphere is assumed to be placed symmetrically on the other side of the plate for the simulation purpose.

1.2 CSM Theory [11] :

CSM as mentioned above is the numerical counterpart of the image charge method which is an analytical method. CSM for field estimation is generally applied for complex electrode configurations which cannot be easily solved analytically using methods such as the Gausse's Law or the above mentioned image charges method.

The basic principle of CSM is very easy to formulate. Using the superposition principle, the potential functions of the fields of individual charges of any type (point, line or ring charges, for instance) can be found by a summation of the potentials (scalars) resulting from the individual charges. Let Q_j be a number n of individual charges, and ϕ_i be the potential at any point within the space (independent of the coordinate system used). The superposition principle results in

$$\phi_i = \sum_{j=1}^n p_{ij} Q_j \quad (i)$$

where p_{ij} are the potential coefficients, which are known for many types of individual charges by particular solutions of Laplace's or Poisson's equations mentioned earlier.

Whereas the potential coefficients p_{ij}, \dots are known, only additional boundary conditions enable us to relate ϕ_i with Q_j quantitatively. If the individual charges are placed outside the space in which the field is to be computed (or inside of a closed metal electrode, whose surface is an equipotential, the magnitude of these charges are related to the distributed surface charges which are physically bonded by the electric flux leaving or entering the surface of any electrode or conductor surrounding these charges. If n charges Q_j are assumed, we require also at least n known potentials to solve

eqn.(i) for the priori unknown charge magnitudes. This can easily be done by identifying the potentials ϕ_i with n potentials on the surface of the conductors ("contour points"), which are adequately placed at a given electrode configuration. If this potential is $\phi_i = \phi_c$, we may rewrite eqn. (i) as

$$\sum_{j=1}^n p_{ij} Q_j = \phi_c \quad (ii)$$

This equation leads to a system of n linear equations for the n unknown charges

$$\begin{bmatrix} p_{11} & p_{12} & \cdots & p_{1n} \\ p_{21} & p_{22} & \cdots & p_{2n} \\ \vdots & & & \\ p_{n1} & p_{n2} & \cdots & p_{nn} \end{bmatrix} \begin{Bmatrix} Q_1 \\ Q_2 \\ \vdots \\ Q_n \end{Bmatrix} = \begin{Bmatrix} \phi_1 \\ \phi_2 \\ \vdots \\ \phi_n \end{Bmatrix} \quad (iii)$$

$$[p]\{Q\} = \{\phi\}.$$

After this system has been solved, it is necessary to check whether the set of calculated charges fits the actual boundary conditions. It must be emphasized that only n discrete contour points of the real electrode system have been used to solve eqn. (ii) and thus the potentials at any other contour points considered in this calculation might still be

different from ϕ_c . Therefore, eqn. (i) must be additionally used to compute the potentials at a number of "check points" located on the electrode boundary (with known potential). The difference between these potentials and the given boundary potential is then a measure of the accuracy and applicability of the simulation. The development and introduction of special objective functions is thus an important procedure within the optimization of the CSM.

As soon as an adequate charge system has been adopted the potentials and the field strength within the space can be computed. Whereas the potentials are found by superposition, i.e. by eqn. (i) or the corresponding set of linear equations [compare with eqn. (ii)], the field stresses are calculated by superposition of magnitudes and directional components. For a cartesian coordinate system for resistance, the x-coordinate E_x would then be for a number of n charges.

$$E_x = \sum_{j=1}^n \frac{\partial p_{ij}}{\partial x} Q_j = \sum_{j=1}^n (f_{ij})_x Q_j \quad (\text{iv})$$

where f_{ij} are "field intensity coefficients" in the x-direction.

1.3 Steps involved in CSM Programming

This CSM programming normally involves the following steps:

- Step 1 : Assumptions about the type and number of charges to be used i.e. point, line and/or ring charges and proper location of these charges within the electrode surface.
- Step 2 : Choice of representative points i.e. "contour points" on the surface of the electrode.
- Step 3 : Calculation of potential-coefficients ' ρ_{ij} '.
- Step 4 : Inversion of potential-matrix and multiplication with the voltage vector of the representative point to calculate the charge vector.
- Step 5 : Choice of "check point" on the electrode surface for the calculation of voltage at these points to find out the deviation from the actual voltage.
- Step 6 : Location optimization based on certain objective criteria.
- Step 7 : Choice of one of the methods for calculation of equipotential lines.

Discussion about above steps :

Step 1 : In making assumptions regarding the type of charges to be used, one has to see the types of electrode surfaces to be reproduced or represented. Generally ring charges are suitable for reproducing spherical surfaces and line charges for cylindrical surfaces while point charges are appropriate for various types of surfaces as shown in Fig. 5. The complexity of computation, in general, increases with the complexity of the simulation charges used. This is because the potential coefficients become more difficult to compute numerically.

Step 2 : The "contour points" should be so chosen such that they fully take into account the critical points on the surfaces such as curves and corners etc. Larger number of contour points should be taken near such critical points.

Step 3 : Calculation of potential coefficients involves knowledge of analytical expression for voltages due to various discrete charges such as point, line and ring charges. Potential coefficients for certain discrete charges have been given in the following [1].

For Point Charges (Fig. 6)

$$P_{ij} = \frac{1}{4\pi\epsilon \sqrt{r_i^2 + (z_i - z_j)^2}} \quad \text{in } (r, z) \text{ coordinate system}$$

where $(0, z_j)$ is the location of the point charge and (r_i, z_i) is the 'contour point'.

This expressions for field stress components become.

$$E_r = \sum_{j=1}^n \frac{+Q_j}{4\pi\epsilon} \frac{r_i}{[r_i^2 + (z_i - z_j)^2]^{3/2}}$$

$$E_z = \sum_{j=1}^n \frac{Q_j}{4\pi\epsilon} \frac{(z_i - z_j)}{[r_i^2 + (z_i - z_j)^2]^{3/2}}$$

For straight line charge (Fig. 7)

$$P_{ij} = \frac{1}{4\pi\epsilon (z_{j2} - z_{j1})} \ln \left[\frac{(z_{j2} - z_i + \gamma_1)}{(z_{j1} - z_i + \delta_1)} \cdot \frac{(z_{j1} + z_i + \gamma_2)}{(z_{j2} + z_i + \delta_2)} \right]$$

$$\gamma_1 = \sqrt{\gamma_i^2 + (z_{j2} - z_i)^2}$$

$$\gamma_2 = \sqrt{\gamma_i^2 + (z_{j1} - z_i)^2}$$

$$\delta_1 = \sqrt{\gamma_i^2 + (z_{j1} - z_i)^2}$$

$$\delta_2 = \sqrt{\gamma_i^2 + (z_{j2} - z_i)^2}$$

And the electric field components become

$$E_r = \sum_{j=1}^n \frac{Q_j}{4\pi\epsilon(z_{j2}-z_{j1})} \left[\frac{z_{j2}-z_i}{r_i\gamma_1} - \frac{z_{j1}-z_i}{r_i\delta_1} + \frac{z_{j1}+z_i}{r_i\gamma_2} - \frac{z_{j2}+z_i}{r_i\delta_2} \right]$$

and

$$E_z = \sum_{j=1}^n \frac{Q_j}{4\pi\epsilon(z_{j2}-z_{j1})} \left[\frac{1}{\gamma_1} - \frac{1}{\delta_1} - \frac{1}{\gamma_2} + \frac{1}{\delta_2} \right]$$

For Ring Charges (Fig. 8)

$$P_{ij} = \frac{1}{4\pi\epsilon} \cdot \frac{2}{\pi} \left[\frac{E(k_1)}{\alpha_1} - \frac{E(k_2)}{\alpha_2} \right]$$

where

$$\alpha_1 = \sqrt{(r_i+r_j)^2 + (z_i-z_j)^2}$$

$$\alpha_2 = \sqrt{(r_i+r_j)^2 + (z_i-z_j)^2}$$

$$\beta_1 = \sqrt{(r_i+r_j)^2 + (z_i-z_j)^2}$$

$$\beta_2 = \sqrt{(r_i+r_j)^2 + (z_i-z_j)^2}$$

and

$$k_1 = \frac{2\sqrt{r_i r_j}}{\alpha_1}, \quad k_2 = \frac{2\sqrt{r_i r_j}}{\alpha_2}$$

where $E(k)$ is the complete elliptic integral of the first kind.

The field stress components become

$$E_r = \sum_{j=1}^n \frac{-Q_j}{4\pi\epsilon} \frac{1}{\pi r_i} \left\{ \frac{[r_j^2 - r_i^2 + (z_i - z_j)^2] K(k_1) - \beta_1^2 E(k_1)}{\alpha_1 \beta_1^2} - \frac{[r_j^2 - r_i^2 + (z_i + z_j)^2] K(k_1) - \beta_2^2 E(k_2)}{\alpha_2 \beta_2^2} \right\}$$

and

$$E_z = \sum_{j=1}^n \frac{-Q_j}{\pi\epsilon} \frac{2}{\pi} \left\{ \frac{(z_i - z_j) K(k_1)}{\alpha_1 \beta_1^2} + \frac{(z_i + z_j) K(k_2)}{\alpha_2 \beta_2^2} \right\}$$

where $K(k)$ is the complete elliptic integral of second kind.

Step 4 : "Check points" should be such as to correctly reflect the errors. The error is likely to be largest somewhere near middle of two "contour points". This assumption becomes more and more valid if the contour points are sufficiently close. If this is not so, then one can choose more than one point between two contour points for the calculation of error.

Step 5 : Error calculated at the check points can be used for the optimization of location of discrete charges within the electrode surface. One can also use some other objective

function for error minimisation. Greater is the accuracy required, greater is the requirement of error minimization. One such objective function is the cumulative square error at the "check points".

$$\text{i.e. optimization of } U = \sum_j (V - \phi_j)^2$$

For HV electrodes location-optimization may be carried out by simply hit and trial method. But optimization becomes necessary in EHV electrodes where slightest deviation means meaningful errors.

One can also assign different weightages to the errors at various points on the electrode, i.e. more weightage to crucial points and less to unimportant points by minimization of

$$U = \sum_j C_j (V - \phi_j)^2$$

where C_j 's are the weightage coefficients.

In this work objective function used is the accumulated squared error of the electrostatic potential at the electrode surface. This objective function is suitable if the field gradient distribution between the electrode configuration is

the aim of the computation. On the other hand this optimization criterion may lead to greater errors if the field gradient at the electrode surface is the main aim of the calculation (Fig. 9).

In general the optimization variables, which are primarily the position of the charges and their values, are subject to the following equality and inequality constraints.

$$f(x_i) = A; f(x_i) \leq B; f(x_i) \leq C; D \leq f(x_i) \leq E$$

where $f(x_i)$ can be any one of the variables x_i , or, a linear or non-linear expression involving a number of variables (e.g., $x_1 + x_2 + 5x_3 = F$). A, B, C, D and F are constants related to the physical system.

The final consideration is the choice of the optimization technique or algorithm. The technique must be capable of handling highly nonlinear objective functions, equality and inequality constraints, and constraints that are described by linear or non-linear functions of the variables. Furthermore, it should be possible to change the constraints or the objective functions without modifying the optimization algorithm.

The availability of the first and second derivatives of the objective function U , determines whether or not gradient techniques that require these derivatives are suitable for use. A number of optimization subroutines are available in the FORTRAN and WATFIV scientific subroutine manuals. Rosenbrock's method is one of the earliest and most reliable technique, but has a relatively slow rate of convergence. One of the fast-converging techniques is Davidson's method as modified by Fletcher and Powell, combined with the Created Response Surface Technique of Carroll [2].

Other optimization algorithm generally used is given by Fletcher which is currently considered as one of the most powerful techniques for unconstrained optimization. This algorithm has the advantage of rapid convergence by a skillful use of the gradient g (where $g = \bar{\nabla}U$ with U being the objective function). It has been an additional advantage due to the fact that as the gradient g is computed, the electric field intensity \vec{E} ($= -\bar{\nabla}\phi$) on the desired boundary is implicitly computed. Therefore it can be achieved without any extra computation. This is a very desirable property especially for the applications in high voltage engineering [2].

This method of optimized simulated charges usually gives surprisingly good accuracy in capacitance calculations. The accuracy in potential and electric fields is relatively not as

good. The accuracy in field calculations deteriorates when corners and edges are encountered [2].

The computation time depends mainly on the rate of convergence of the optimization method used to minimize the objective function. Fast converging techniques should be used if computer time is an important parameter. Other factors that could influence the computation time are the initial values of the optimization parameters and the effectiveness of the objective function [2].

The error minimization can either be done in an open loop by hit and trial method, or in a closed loop whereby the computer itself decides the location of the simulation charges for obtaining minimum error.

Step 6 : Calculation of equipotential surfaces

Several methods of plotting equipotential surfaces have been considered.

Method I : By finding out potentials at several points in the space around the electrode and then joining the points of the same potentials. But this would require very large number of calculations as the number of points would be very large. it would also

involve problems for plotting. Hence this method is considered impractical.

Method II: Other method could be to derive an equation for equipotential surfaces and plot these equations using computer. But in this case due to large number of charges involved the equation of equipotential surfaces is not explicit in one of the variables (r or z). Hence it cannot be plotted using digital computers using methods such as Newton-Raphson etc. which are applicable only in case of explicit equations.

Method III: In this method we exploit the fact that the electrode surface itself is an equipotential surface. Also, we keep z constant i.e. we first find points on one line parallel to the r -axis and repeat the process along several such lines.

Let us consider an electrode surface as shown in Fig. 10. Consider points a, b, c, d on the electrode surface. Their potential = V_r . Therefore, potential at infinitesimal distance dr from the electrode surface = V_{r+dr} .

We know from Taylor's series expansion that,

$$V_{r+dr} = V_r + \left. \frac{\partial V_r}{\partial r} \right|_{(r,z)} dr$$

If we take $V_{r+dr} = V_r - xV_r$ i.e. smaller by xV_r , then

$$V_r - xV_r = V_r + \left(\frac{\partial V_r}{\partial r} \right)_{r,z} \cdot dr$$

$$\rightarrow dr = \left[-xV_r / \left(\frac{\partial V_r}{\partial r} \right)_{r,z} \right]$$

Thus knowing s , V_r and $(\partial V / \partial r)_{x,z}$, dr can be found out, i.e. the distance in which the voltage would drop by some given factor x .

The new r value considered is $r_{\text{initial}} + (dr)_r$ and the z value remains the same.

Now we apply this to several points on the electrode surface and join the new points obtained as shown. This process can again be repeated at a' , b' , c' , d' and further new points can be found out. Thus the equipotential surfaces can be plotted.

Method IV: It is known that potential along an equipotential surface is constant.

$$\text{Also } V = f(r, z)$$

$$dV = (\partial f / \partial r) dr + (\partial f / \partial z)$$

Along an equipotential $dV = 0$

$$\left(\frac{dz}{dr}\right) = \frac{-(\partial f / \partial r)}{+(\partial f / \partial z)}$$

or

$$dz = - \left[(\partial f / \partial r) / (\partial f / \partial z) \right] dr$$

$$= - \left[E_r / E_z \right]_{r, z} dr \quad \text{Since } \begin{cases} -\partial f / \partial r = E_r \\ -\partial f / \partial z = E_z \end{cases}$$

where E_r and E_z are electric field component at (r, z) . By taking $dr = \text{constant value (small)}$, we can find dz by calculating Electric field components at (r, z) . The new point is given by $(r+dr, z+dz)$. Thus starting from a fixed point (r_o, z_o) the entire equipotential surface can be found passing through that point.

However, this method has one limitation. It cannot be applied to those problems where the equipotential surface is

expected to be vertical or of negative slope at some place for example in rod-plane and sphere-sphere case; because (dr) being fixed, any small step dr from such an equipotential would push the calculations out of that particular equipotential surface. This method has been used only for the 'Rogowski-electrodes' case and the rod-rod case.

Method V : The method described below is devoid of any limitations of earlier methods.

An element dL along the equipotential surface can be written as

$$(dL)^2 = (dr)^2 + (dz)^2$$

or

$$\frac{(dL)^2}{(dz)^2} = \left[1 + (dr/dz)^2 \right]$$

or

$$dL/dz = \pm \sqrt{1 + (dr/dz)^2}$$

or

$$dz = \frac{\pm dL}{\sqrt{1 + (dr/dz)^2}}$$

$$\text{Since } (dz/dr) = -(E_r/E_z) \quad (i)$$

Therefore

$$dz = \frac{\pm dL}{\sqrt{1 + (E_z/E_r)^2}} \quad (ii)$$

Thus, by taking (dL) to have a very small constant value, the equipotential surfaces can be calculated by using equations (i) and (ii). At the tip of the electrode, E_r is equal to zero. This may give overflow error in case of equation (ii) when using digital computer. Thus, care should be taken to incorporate additional statements in the programme to avoid this. dz has two possible values. Correspondingly, dr also has two values. Thus correct value of dz should be determined by storing the previous point in the programme. In case of monotonically rising equipotentials, dz would always be +ve. This method has been used in the sphere-sphere case and multidielectric case.

CHAPTER 2

SAMPLE PROBLEMS FOR CSM APPLICATION TO CONFIGURATIONS INVOLVING SINGLE DIELECTRIC

1. **Problem 1 :** A conducting cylinder/conductor running parallel to the ground. The image charge theory gives the location and value of charge to be used. This has been converted into a program with certain additional features.

Prog. 1 : This program asks the person running the program to give the number of charges N as input. It calculates the location and value of the charges given by the image-theory. It also calculates the error at the tip of the sphere.

2. **Problem 2 :** Two spherical electrodes of opposite polarity have been taken to show the rapid fall in error with increase in the number of image-charges as shown in Fig. 16.

Prog. 2 : The program asks the radius and voltage of the cylindrical conductor. It also asks for the distance of centre of the sphere from the zero potential line. It then calculates the position and value of image charge using image theory. It also calculates the ratio $F = (E/E_{\max})$ at large number of points from conductor tip to the ground.

3. Problem 3 : Two spherical electrodes with three charges have been taken and CSM applied. Further, equipotential surfaces have been plotted to check the accuracy of CSM as shown in Fig. 12.

As seen earlier, atleast three charges are required for minimizing the error. Though the location points could be chosen at the image points, but in order to show that the error does not increase substantially even if charges are located at some other points; the charges were placed equidistant along the axis i.e. at 0.15, 0.2 and 0.25 m. (for a sphere of 0.1 m. radius).

Two contour points have been taken at the tips of the diameter along the axis of sphere and one at right angle to this diameter on the sphere surface i.e. at (0.0, 0.1), (0.0, 0.3), (0.1, 0.2). This has been done so that the entire sphere can be given a good representation and to minimize the error.

Test points have been chosen on the entire sphere surface, 15° apart from each other and error has been calculated on these points with voltage of the sphere assumed to be 1 V.

Prog. 3 : This program asks for the charge location inside the spherical electrodes and the contour location of points. It also asks for the radius of the sphere and the distance of its centre from zero potential surface. The program then calculates

- (a) Simulation Charge values.
- (b) errors on the electrode surface at points 15° apart covering the electrode.
- (c) the cumulative square error.
- (d) Equipotential surfaces.

4. Two spherical tip-shaped rods of opposite polarity are considered. CSM has been applied using line and point charges. Accuracy is then checked by plotting the equipotential surfaces in the region of interest as shown in Fig. 14.

Spherical part of the rod can be best represented by considering a point charge placed at the centre while the cylindrical part can be represented by line charges most appropriately. Now one can choose line charges of equal length, progressively decreasing length or progressively increasing length. To decide this, error reduction process was resorted. It was accompanied with successive variation of parameters such as, length of first line charge and multiplying factor for the length of line charges. In this way only one parameter was changed at a time while the

others were kept constant. The result which gave the minimum error for a radius of unit length was

length of first line charge = 0.1

mulyiplyng factor A1 = 0.6

This is not to suggest that these are the optimum values but they are only one of the several possible sets of values for low error. Since the multiplying factor is less than 1, therefore, the line charges are of progressively decreasing length. Here 9 line charges were considered.

Prog. 4 : This program asks for the radius of the spherical part of the electrodes and also the distance of it's centre from the zero-potential surface. It also asks for the length of first line segment (l) and the multiplying factor (A1) for successive 8 other line segments. The program itself then calculates the contour points, some of them on the spherical part and others on the cylindrical part. It then calculates the value of point and the line charges and their location. It also calculates the equipotential surfaces.

5. Problem 5 : Rogowski-Profiled electrode has been taken and equipotential electrode surfaces for different gap spacings plotted. Ring-charges have been considered for this program as shown in Fig. 17.

CHAPTER 3

THE MULTIDIELECTRIC CASE

For a field space containing only one dielectric material, the application of the CSM to three-dimensional problems does not present fundamental difficulties. Even unsymmetrical electrode configurations can be treated by means of discrete charges [1].

In contrast to the simple solutions within the FDM or FEM for treating multidielectric cases, the CSM when used for field calculations in systems composed of two or more dielectrics increases the cost. This may be understood by considering the fundamental mathematical solutions and the physical mechanisms involved. The CSM is directly based upon physical charges and in every dielectric material polarization processes take place. Whereas in a homogeneous material placed between electrodes the absolute value of its permittivity does not contribute to the field strength (or potentials), but only the flux density D , the field distribution at the boundaries of different materials is heavily distorted due to the dipole charges at the boundaries which may not have counterparts at the adjacent medium. The law of dielectric refraction results from the physical effect and is associated with an infinitely thin layer of bonded charges located in the two media. The

free surface charges physically present due to electrical condition of the interface also contribute to field distortions, but the common dielectric refraction is not related to such additional charges.

This realignment of dipoles within different dielectric materials must therefore be considered within the CSM. An exact solution with CSM must be based upon the physical dipole surface charge density. But continuous surfaces can also be simulated by discrete charges by replacing the surface charge density to metal electrode. This method, originally presented by P. Weiss, will be presented briefly through a simple example [1].

Figure 12 displays a cross-section of a part of an insulation system, in which a metal electrode with fixed potential, $\phi = \phi_c$, meets two adjoining dielectric materials I and II. The actual shapes of the two-dimensional surfaces of the three different boundaries (electrode-dielectric I, electrode-dielectric II, dielectric I-dielectric II) determine the optimal types of discrete charges simulating the problem. Thus, the localized charges 1-7 will represent point charges as well as intersections with line or ring charges. From earlier considerations it is obvious that a part of the charges (nos. 1-3 denoted as n_E) have been placed inside the electrode, i.e. behind the metal surface. However, the same is

true for the charges placed on both sides of the dielectric interface (nos. 4-7), because the influence of the dipolar charges within dielectric I upon the field in dielectric II can be simulated by the discrete charges nos. 4 and 5 within dielectric I and vice versa. A limited number of contour points placed at a $\phi = \text{constant}$ boundary is necessary, which is equal to the number of simulated charges within an electrode, and thus a number ($n_E = 3$) contour points (nos. 1-3) are adequate. For the dielectric interface, however, it will be sufficient for this example to place only two contour points corresponding to the two pairs of simulation charges (nos. 4 and 6, nos. 5 and 7), as each contour point belongs to dielectric I as well as to dielectric II. Equal number of charges, designated by n_B , on both sides of the dielectric interface are thus convenient and they should be placed at positions uniformly distributed between the mutual contour points and adjacent charges respectively. For our example, n_B is equal to 2 only.

Now it is possible to set up a system of equations for our unknown charges based upon well-known boundary conditions. These boundary conditions can be subdivided into three parts as follows :

(1) The electrode-dielectric interface is a boundary with known potential, $\phi = \phi_c$. The absolute magnitude of the surface charge density at this electrode is dependent upon the relative permittivity ϵ_r of the dielectric materials due to the polarization mechanisms in both dielectric materials. Since $D = \epsilon E = \epsilon_r \epsilon_0 E$, where ϵ_0 is the permittivity of vacuum, the absolute magnitudes of our simulation charges would depend upon these material characteristic parameters. It is necessary to take these physical effects into account, which are included within the potential coefficients. For any homogeneous dielectric material, the electric field may be computed independent of relative permittivity ϵ_r , and the potential coefficients are in general always computed by assuming $\epsilon = \epsilon_0$. The absolute magnitudes of the discrete charges used within our system are based upon a superposition of potentials. And thus we can use the known potential at the electrode interface to derive two sets of equations based upon n_E contour points taking only dielectric I into account, for which the charges within dielectric II can be neglected :

$$\sum_{j=1}^{n_E} Q_j P_{ij} + \sum_{j=n_E+1}^{n_E+n_B} Q_j P_{ij} = \phi_c \quad (i)$$

(1-3)
(4-5)

Using eqns. (iii) and (iv) subject to two new boundary conditions, the electric field within dielectric II could be

computed. All Q_j charges within eqn.(i), which are not yet known, define the potentials within this material.

For the computation of the field distribution within dielectric I, the same considerations are applicable. But now we neglect the charges within dielectric I, which results in an equal set of three or n_E equations,

$$\sum_{j=1}^{n_E} Q_j P_{ij} + \sum_{j=n_E+n_B+1}^{n_E+2n_B} Q_j P_{ij} = \phi_c \quad (ii)$$

(1-3) (6-7)

(2) The potential at the dielectric interface is unknown. We know, that due to the continuity of the potential at either side of the interface, the potentials must be equal at each contour point. As the charges within the electrode (nos. 1-3) will not disturb the continuity condition, the potentials due to the charges within the dielectric materials must satisfy the condition.

$$\sum_{j=1}^{n_E} Q_j P_{ij} + \sum_{j=n_E+n_B+1}^{n_E+2n_B} Q_j P_{ij} = \phi_c \quad (iii)$$

(4-5) (6-7)

This equation refers to a number of n_B ($=2$) contour points, giving an equal number of new equations. In these equations charges Q_j are involved, which have not yet been used within eqn. (i) or eqn. (ii) respectively. It should be noticed that this potential continuity condition implies that the field stress components tangential to the interface are equal.

3. Finally, the third boundary condition refers to the continuity of the normal component of the electric flux density crossing the dielectric interface or the discontinuity of the normal components of the field intensity. To include this condition, the "field intensity coefficient" f_{ij} must be considered, which is the contribution of the charge j to that component of the field vector, which is normal to the dielectric boundary at a contour point i . Then for any normal component $(E_n)_i = Q_j f_{ij}$, this condition may be written as

$$\epsilon_I \left[\sum_{j=1}^{n_E} Q_j f_{ij} + \sum_{j=n_E+n_B+1}^{n_E+2n_B} Q_j f_{ij} \right] =$$

(1-3) (6-7)

$$\epsilon_{II} \left[\sum_{j=1}^{n_E} Q_j f_{ij} + \sum_{j=n_E+1}^{n_E+n_B} Q_j f_{ij} \right] \quad (iv)$$

(1-3) (4-5)

where ϵ_I and ϵ_{II} are the permittivities of the two dielectrics. This equation refers again to a number of n_B contour points, and thus a total number of $(n_E + 2n_B)$ linear equations are given for the calculations of the same number of unknown charges. This procedure demonstrates the difficulties involved with the implementation of dielectric boundaries, as a significant number of additional charges increase the computational efforts.

CHAPTER 4

PROGRAMMING FOR THE MULTIDIELECTRIC CASE

This program is quite different from the preceeding programs because of the presence of surface charges on the dielectric. Essential details of the program are given below :

(a) Charge locations : The program involves three sets of charge locations. First, those simulation charges which are inside the electrode; second, those simulation charges which are in the air near the air dielectric interface; third, those which are inside the dielectric near the air dielectric interface.

(b) Contour points : There are three sets of contour points. First, those on the electrode air interface; second, those on the electrode dielectric interface; third, those on the air dielectric interface.

(c) Potential matrix : The potential matrix has coefficient arising out of the following reasons :

- (i) due to potential on the air electrode interface.
- (ii) due to potential on the electrode dielectric interface.
- (iii) due to equating of potentials on the air dielectric interface.
- (iv) due to equating of vertical components of the electric field on the air dielectric interface with

the relative permittivity taken into account.

- (d) Matrix inversion and multiplication with a vector of 1's and 0's at appropriate positions.
- (e) Error calculations : Calculates the error at desired points on the electrode surface.
- (f) Equipotential surface calculation : Calculates the equipotential surface passing through a desired initial point in air or dielectric.
- (g) Tangential field calculation : Calculates the tangential field at the desired points on the interface between air and dielectric.

The program asks for the various charge location, contour points on the electrode, the coefficients of the two boundaries, the relative permittivity of the dielectric with respect to air, the points on the electrode surface where error calculations are desired, the points on the interface where tangential field calculations are desired, the backup and the initial point of the equipotential surface.

The above programme has been run for a sample problem namely a spherical electrode of radius = 10 cm., with its centre 20 cm. above a dielectric block of height 10 cm. and width 20 cm. as shown in Fig. 19.

The equipotential surfaces plotted by using the programme have been shown in Fig. 20.

CONCLUSION

(a) In practice, the appropriate shaping of electrode configurations within insulation systems is an essential task, as field stresses may well be reduced and kept low by this method. Such electrode shape optimization techniques are either based upon an iterative process in which the contour points are shifted after each computation of the field stresses or are based upon a superposition of fixed simulation charges representing the original system and additional "optimization" charges by which the field distribution gets changed due to a given objective function [1].

(b) The application of discrete simulation charges used in the charge simulation technique provide at least a very reliable and efficient method to solve many two- and three-dimensional problems. However, it should be recognized that the option of surface charges at electrodes or dielectric boundaries, i.e. distributed layers of charge sources in free space, offers definite advantages, because in this simulation method the role of physical charges, which are the origin of electric flux densities, is taken directly into account.

The main contributions made in this thesis are as follows:

(a) CSM has been presented in a unified manner. Evolution of CSM from image field theory has been successfully presented.

(b) The thesis has presented successful programs for parallel conductors, sphere-sphere and rod-plane electrode configurations involving single dielectrics.

(c) Important basics for further work on CSM have been developed namely the mathematical theory for plotting the equipotential. The missing links in the theory of multielectric case with rotational symmetry have been brought out and the problem of programming the multielectric case has been successfully developed. The problem of incorporating the vertical components of field on any arbitrarily inclined interface and from any arbitrarily placed charges has also been solved in the program. Apart from this the program has also solved the problem of equipotential surface plotting at the interface and the proper choice of sign of dz .

SUGGESTED WORK

- (1) The program on Multidielectric case which this thesis has presented involves only point charges inside as well as outside the electrode surface. The program can be further extended to include line and ring charges within the electrode surface also.
- (2) The program is valid for axially symmetric cases. Programs involving electrode with non-axial symmetry can also be developed.
- (3) The charge location has essentially been done by hit and trial method which is an open loop programming process. For higher accuracy it is important to adopt closed loop method of error minimization which will have to be incorporated into the program.
- (4) The charge location optimization criteria used in this program is the cumulative square error. Some better methods can be used as suggested in Chapter 2 in this thesis.

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APPENDIX

The realization of homogeneous fields within a finite volume of insulating material is very difficult. Using parallel metal plates of limited dimensions creates the problem of a proper stress control at the edges of the plates. The field problem becomes thus three-dimensional, though a rotational symmetry exists if the parallel plates are circular discs.

Depending upon the material to be tested, the breakdown strength may be very sensitive to local high fields within the whole electrode arrangement. Therefore, the highest stress should only be present in the homogeneous field region, where the plates are in parallel. A certain profile of the electrodes is necessary outside the plane region to limit the dimensions, but the field strength at the curved edges should never exceed the value $E = V/d$, if V is the applied voltage and d the distance between the parallel plates. Rogowski proposed electrodes for uniform fields for axially symmetrical systems whose profile follows the analytical function first introduced by Maxwell,

$$z = \frac{a}{\pi} (w + 1 + e^w) \quad (a)$$

where z and w represent the complex coordinates in the z - and w -planes. Substitution of the coordinates for the complex

values $z = x+iy$ and $w = u+iv$ and separation of the real and imaginary parts gives

$$x = \frac{a}{\pi} (u + 1 + e^u \cos v);$$

$$y = \frac{a}{\pi} (v + e^u \sin v). \quad (b)$$

Assuming two infinite, parallel "plates" in the w -plane, the coordinates of which are given by $v = \pm\pi = \text{const}$, it can be recognized from eqn. (b) that these plates are transformed into the z -plane to the left half-plane only. All other lines $v = \text{const}$ with $-\pi < v < +\pi$ can be assumed to be other equipotential lines, and all lines $u = \text{const}$ with $-\infty \leq u \leq +\infty$ can be assumed to be field lines in the w -plane, representing a uniform field distribution. These lines appear in the z -plane as shown in Fig. (a) providing the electrical field distribution of parallel plates terminating at $x = 0$. The concentration of the equipotential lines, $v = \text{const}$, within the z -plane may well be recognized at, or in the vicinity of, the edges of the plates.

The parallel plates, $v = \pm\pi$, are thus inadequate to fulfill the demand for field distribution whose intensity is limited to the field strength within the homogeneous part of the arrangement, i.e. for $u \leq -\pi$. It is obvious that the field strength along equipotential lines for which $-\pi < v < +\pi$ provide better conditions. For quantitative assessment the

field strength within the z-plane may be computed in several ways, as shown :

From the conjugate complex field strength in the z-plane

$$E_z^* = E_x - iE_y = i \frac{dw}{dz} = i \frac{1}{\frac{dz}{dw}} \quad (c)$$

the absolute values could be computed by $|E_z^*| = \sqrt{E^2 + E^2}$

A second possibility is given by

$$E_z = E_x + iE_y = -\text{grad } v = - \left[\left(\frac{\partial v}{\partial x} \right) + i \left(\frac{\partial v}{\partial y} \right) \right] \quad (d)$$

which needs a partial differentiation only.

Finally, the absolute value of E_z may be computed by

$$|E_z| = \frac{1}{\sqrt{\left(\frac{\partial x}{\partial v} \right)^2 + \left(\frac{\partial y}{\partial v} \right)^2}} \quad (e)$$

a method which is easiest to apply to our separated analytical function, eqn. (b). Combining eqns. (b) and (e), we easily may find the field strength as

$$|E_z| = \frac{\pi}{a \sqrt{1 + e^{2u} + 2e^u \cos v}} = f(u; v)$$

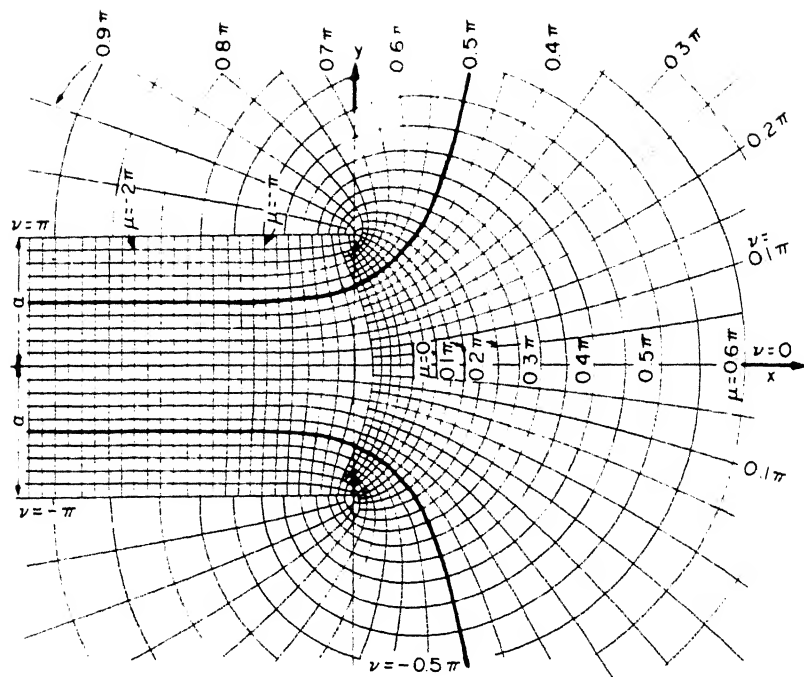


FIG. A. Transformation of a square grid from a w -plane in the displayed z -plane by eqn (A)
Rogowski's profile ($\nu = \pm \pi/2$).

PROGRAMMES

```

PROGRAM PARCYL;
CONST K=18.0E09;
VAR Z1,V,ZC,R,Z0,Z,L,PO,EM,VZ,EZ,F,DZ:REAL;
U,I:INTEGER;

```

```

F1,F2:TEXT;
BEGIN
ASSIGN(F1,'PAR.PRN');
REWRITE(F1);
WRITELN('VOLTAGE,CENTRE,RADIUS ARE');
READLN(V,ZC,R);
WRITELN(F1,'VOLTAGE OF THE CYLINDER=',V:8:4);
WRITELN(F1,'DISTANCE OF CENTRE FROM THE PLATE=',ZC:8:4);
WRITELN(F1,'RADIUS=',R:8:4);
WRITELN;
Z0:=SQRT(SQR(ZC)-SQR(R));
WRITELN(F1,'LOCATION OF LINE CHARGE FROM THE PLATE=',Z0:8:4);
Z1:=(ZC-R);
L:=LN((Z0+Z1)/(Z0-Z1));
PO:=V/(K*L);
WRITELN(F1,'CHARGE PER UNIT LENGTH =',PO);
WRITELN(F1,'=====');
WRITELN('NUMBER OF POINTS BETWEEN CYLINDER AND PLATE =');
READLN(U);
WRITELN(F1,'NUMBER OF POINTS BETWEEN CYLINDER AND PLATE= ',U);
DZ:=(ZC-R)/U;
EM:=K*PO*((1/(Z0-ZC+R))-(1/(Z0+ZC-R)));
WRITELN(F1);
WRITELN(F1,'MAXIMUM FIELD INTENSITY =',EM:8:4);
WRITELN(F1);
FOR I:=0 TO U DO
BEGIN
Z:=I*DZ;
WRITELN (F1,'Z=',Z:8:4);
VZ:=K*PO*(LN(Z0+Z)-LN(Z0-Z));
WRITELN(F1,'VOLTAGE AT Z=',VZ:8:4);
EZ:=K*PO*((1/(Z0-Z))-(1/(Z0+Z)));
WRITELN(F1,'ELECTRIC FIELD AT Z=',EZ:8:4);
F:=EZ/EM;
WRITELN(F1,'F AT Z=',F:8:8);
WRITELN(F1)
END;
END.

```

VOLTAGE OF THE CYLINDER=10000.0000
DISTANCE OF CENTRE FROM THE PLATE= 0.2000
RADIUS= 0.1000
LOCATION OF LINE CHARGE FROM THE PLATE= 0.1732
CHARGE PER UNIT LENGTH = 4.2184762083E-07

=====

NUMBER OF POINTS BETWEEN CYLINDER AND PLATE= 20

MAXIMUM FIELD INTENSITY =75932.5718

Z= 0.0000
VOLTAGE AT Z= 0.0000
ELECTRIC FIELD AT Z= 0.0000
F AT Z=0.00000000

Z= 0.0050
VOLTAGE AT Z=438.5187
ELECTRIC FIELD AT Z=2533.1967
F AT Z=0.03336113

Z= 0.0100
VOLTAGE AT Z=877.7700
ELECTRIC FIELD AT Z=5079.1018
F AT Z=0.06688963

Z= 0.0150
VOLTAGE AT Z=1318.4936
ELECTRIC FIELD AT Z=7650.6370
F AT Z=0.10075567

Z= 0.0200
VOLTAGE AT Z=1761.4443
ELECTRIC FIELD AT Z=10261.1583
F AT Z=0.13513514

Z= 0.0250
VOLTAGE AT Z=2207.3998
ELECTRIC FIELD AT Z=12924.6931
F AT Z=0.17021277

Z= 0.0300
VOLTAGE AT Z=2657.1691
ELECTRIC FIELD AT Z=15656.2004
F AT Z=0.20618557

Z= 0.0350
VOLTAGE AT Z=3111.6020
ELECTRIC FIELD AT Z=18471.8680
F AT Z=0.24326672

Z= 0.0400
VOLTAGE AT Z=3571.5995
ELECTRIC FIELD AT Z=21389.4568
F AT Z=0.28169014

Z= 0.0450
VOLTAGE AT Z=4038.1259

ELECTRIC FIELD AT Z=24428.7094
F AT Z=0.32171582

Z= 0.0500
VOLTAGE AT Z=4512.2225
ELECTRIC FIELD AT Z=27611.8443
F AT Z=0.36363636

Z= 0.0550
VOLTAGE AT Z=4995.0239
ELECTRIC FIELD AT Z=30964.1627
F AT Z=0.40778499

Z= 0.0600
VOLTAGE AT Z=5487.7775
ELECTRIC FIELD AT Z=34514.8053
F AT Z=0.45454545

Z= 0.0650
VOLTAGE AT Z=5991.8671
ELECTRIC FIELD AT Z=38297.7084
F AT Z=0.50436469

Z= 0.0700
VOLTAGE AT Z=6508.8410
ELECTRIC FIELD AT Z=42352.8289
F AT Z=0.55776892

Z= 0.0750
VOLTAGE AT Z=7040.4482
ELECTRIC FIELD AT Z=46727.7365
F AT Z=0.61538462

Z= 0.0800
VOLTAGE AT Z=7588.6824
ELECTRIC FIELD AT Z=51479.7097
F AT Z=0.67796610

Z= 0.0850
VOLTAGE AT Z=8155.8385
ELECTRIC FIELD AT Z=56678.5387
F AT Z=0.74643249

Z= 0.0900
VOLTAGE AT Z=8744.5855
ELECTRIC FIELD AT Z=62410.3329
F AT Z=0.82191781

Z= 0.0950
VOLTAGE AT Z=9358.0615
ELECTRIC FIELD AT Z=68782.7825
F AT Z=0.90584029

Z= 0.1000
VOLTAGE AT Z=10000 0000

```

PROGRAM SSERIES;
uses crt;
CONST K=9.0E09;
pi=3.1419;
VAR B,V,R,Q0,Q1,XNI,QNI,QT,EI,XNF,QNF,C,X1,V0,V1,VT,ERROR:REAL;
ch:char;
N,I:INTEGER;
F1,F2:TEXT;
BEGIN
ASSIGN(F1,'SS.PRN');
REWRITE(F1);
clrscr;
writeln('Give the distance between the centres of spheres');
READLN(B);
writeln('Give the voltage of the spheres');
READLN(V);
writeln('Give the value of Radius of the spheres');
READLN(R);
writeln('=====');
WRITELN(f1,' Distance between the centres of sphere= ',B:12:6);
writeln(f1,' Voltage of the sphere= ',V:12:6);
writeln(f1,' Radius of the sphere= ',R:14:6);
writeln(f1,'=====');
writeln(f1);
writeln('Press any key to Continue');

ch:=readkey;
writeln('Give the no of Charges');
READLN(N);
WRITELN(F1,'NUMBER OF CHARGES=',N);
Q0:=R*V/K;
WRITELN(F1,'Q0=',Q0);
V0:=V-(K*Q0/(B-R));
WRITELN(F1);
X1:=SQR(R)/B;
WRITELN(F1,'X1=',X1);
Q1:=Q0*R/B;
WRITELN(F1,'Q1=',Q1);
V1:=K*Q1*((1/(R-X1))-(1/(B-X1-R)));
XNI:=X1;
QNI:=Q1;
WRITELN(F1);

QT:=Q0+Q1;
VT:=V0+V1;
EI:=K*((Q0/SQR(R))-(Q0/SQR(B-R))+(Q1/SQR(R-X1))-(Q1/SQR(B-R-X1)));
FOR I:=2 TO N DO
BEGIN
XNF:=SQR(R)/(B-XNI);
WRITELN(F1,'X=',XNF);
QNF:=QNI*R/(B-XNI);
WRITELN(F1,'Q=',QNF);
VT:=VT+K*QNF*((1/(R-XNF))-(1/(B-XNF-R)));
QT:=QT+QNF;
EI:=EI+K*((QNF/SQR(R-XNF))-(QNF/SQR(B-R-XNF)));
xni:=xnf;
qni:=qnf;
WRITELN(F1)
END;
WRITELN(f1,'TOTAL CHARGE ON SPHERE=',QT);
WRITELN(F1,'ELECTRIC FIELD AT THE TIP=',EI);
C:=QT*0.5/V;
WRITELN(F1,'CAPACITANCE=',C);
ERROR:=((V-VT)/V)*100;
WRITELN(F1,'ERROR AT THE TIP=',ERROR);
CLOSE(F1)
END.

```

Distance between the centres of sphere= 0.400000
Voltage of the sphere= 10000.000000
Radius of the sphere= 0.100000
=====

NUMBER OF CHARGES=10

Q0= 1.1111111111E-07

X1= 2.5000000000E-02

Q1= 2.7777777778E-08

X= 2.6666666667E-02

Q= 7.4074074074E-09

X= 2.6785714286E-02

Q= 1.9841269841E-09

X= 2.6794258373E-02

Q= 5.3163211057E-10

X= 2.6794871795E-02

Q= 1.4243014243E-10

X= 2.6794915836E-02

Q= 3.8169395778E-11

X= 2.6794918998E-02

Q= 1.0227458681E-11

X= 2.6794919225E-02

Q= 2.7404392924E-12

X= 2.6794919242E-02

Q= 7.3429849526E-13

X= 2.6794919243E-02

Q= 1.9675468881E-13

TOTAL CHARGE ON SPHERE= 1.4900657388E-07

ELECTRIC FIELD AT THE TIP= 1.4575598322E+05

CAPACITANCE= 7.4503286939E-12

ERROR AT THE TIP= 6.4816325903E-05

```

PROGRAM MATCOFF;
CONST N=3; m=1;
type mat=array [1..n,1..n] of real;
      cat=array [1..n,1..2] of real;
      rat=array [1..n,1..m] of real;
VAR RZ:cat;
PG:cat;
charge:rat;
NST:mat;
ZC,R,PJ,QJ,VI,VJ,DH,DL,RI,ZI,THETA,ER,EZ,DZ,DR,EROR,ERROR,A,B,C,D:REAL;
L1,I1,J1,THETAJ,THETA0,VI,VM,G,U1:INTEGER;

NST1,NST2:REAL;
I,J,K,L,S,u,v,T:INTEGER;
F1,F2,F3:TEXT;
procedure inverse(a:mat; VAR b:rat);
CONST NM=50;
      N=3; M=1;
VAR IPIV:ARRAY[1..NM] OF INTEGER;
      INDXR:ARRAY[1..NM] OF INTEGER;
      INDXC:ARRAY[1..NM] OF INTEGER;
      BIG,DUM,PIVINV:REAL;
      I,J,V,U,LL,K,L,P,Q,ICOL,IROW:INTEGER;

BEGIN
  FOR P:=1 TO N DO
    BEGIN
      FOR Q:=1 TO N DO
        BEGIN

```

```

      READ(AIP,Q1);
      END;
      READLN
      END;
FOR P:=1 TO N DO
  BEGIN
    FOR Q:=1 TO M DO
      BEGIN
        BIP,Q1:=1.0;
        END;
      END;
FOR J:=1 TO N DO
  BEGIN
    IPIV[J]:=0;
    END;
  FOR I:=1 TO N DO
    BEGIN
      BIG:=0.0;
      FOR J:=1 TO N DO
        BEGIN
          IF (IPIV[J]<>1) THEN
            BEGIN
              FOR K:=1 TO N DO
                BEGIN
                  IF (IPIV[K]=0) THEN
                    BEGIN
                      IF (ABS(AIJ,K))>BIG THEN
                        BEGIN
                          BIG:=ABS(AIJ,K);
                          IROW:=J;
                          ICOL:=K
                        END;
                      END
                    ELSE
                      IF (IPIV[K]=1 ) THEN
                        BEGIN
                          WRITELN('SINGULAR POINT');
                          READLN
                        END;
                      END
                    END
                  END
                END;
              END;
            END;
            IPIV[ICOL]:=IPIV[ICOL]+1;
            IF (IROW <> ICOL) THEN
              BEGIN
                FOR L:=1 TO N DO
                  BEGIN
                    DUM:=A[IROW,L];
                    A[IROW,L]:=A[ICOL,L];
                    A[ICOL,L]:=DUM
                  END;
                FOR L:=1 TO M DO
                  BEGIN
                    DUM:=B[IROW,L];
                    B[IROW,L]:=B[ICOL,L];
                    B[ICOL,L]:=DUM
                  END;
                END;
                INDXR[I]:=IROW;
                INDXR[I]:=ICOL;
                IF (A[ICOL,ICOL]=0.0) THEN
                  BEGIN
                    WRITELN('SING MATRIX') ;
                    READLN
                  END;

```

```

PIVINV:=(1.0/A[ICOL,ICOL]);
A[ICOL,ICOL]:=1.0;
FOR L:=1 TO N DO
  BEGIN
    A[ICOL,L]:=A[ICOL,L]*PIVINV
  END;
FOR L:=1 TO M DO
  BEGIN
    B[ICOL,L]:=B[ICOL,L]*PIVINV
  END;
FOR LL:=1 TO N DO
  BEGIN
    IF (LL<>ICOL) THEN
      BEGIN
        DUM:=A[LL,ICOL];
        A[LL,ICOL]:=0.0;
        FOR L:=1 TO N DO
          BEGIN
            A[LL,L]:=A[LL,L]-A[ICOL,L]*DUM;
          END;
        FOR L:=1 TO M DO
          BEGIN
            B[LL,L]:=B[LL,L]-B[ICOL,L]*DUM
          END;
        END;
      END;
    END;
  END;
FOR L:=N DOWNT0 1 DO
  BEGIN
    IF (INDXR[IL]<>INDXC[IL]) THEN
      BEGIN
        FOR K:=1 TO N DO
          BEGIN
            DUM:=A[K,INDXR[IL]];
            A[K,INDXR[IL]]:=A[K,INDXC[IL]];
            A[K,INDXC[IL]]:=DUM
          END;
        END;
      END;
    ( FOR U:=1 TO N DO
      BEGIN
        FOR V:=1 TO M DO
          BEGIN
            WRITE(B[U,V]:8:3)
          END;
          WRITELN
        END;
      )
    END;
  END;

```

(=====END OF PROCEDURE INVERSE =====)

```

BEGIN
  ASSIGN(F1,'S31.PRN');
  REWRITE(F1);
  WRITELN('TEST POINTS ');
  WRITELN(F1,'TEST POINTS ');
  FOR I:=1 TO N DO
    BEGIN
      FOR J:=1 TO 2 DO
        BEGIN
          READ(PQ[I,J]);
          WRITE(F1,PQ[I,J]:8:4);
        END;
        READLN;
        WRITELN(F1);
        WRITELN(F1)
      END;
      READLN;
    END;
  END;

```

```

-----');
E LOCATIONS ARE ');
ARGE LOCATIONS ARE ');
DO

DO

, L1:8:4);

=====');
ISTANCE MATRIX IS');
DO

DO

(SQR(PQ[S,1]-RZ[T,1])+SQR(PQ[S,2]-RZ[T,2]));
(SQR(PQ[S,1]-RZ[T,1])+SQR(PQ[S,2]+RZ[T,2]));
1-NST2;
S,T1:8:4);
);

***CALLING THE PROCEDURE INVERSE *****
charge);
=====');
harge vector is');
do

do

arge[u,11:12:8)

=====');
=====ERROR CALCULATION=====)
CENTRE & RADIUS ARE ');
, 'CENTRE & RADIUS ARE ');
R);
, 'CENTRE=', ZC:8:4, ' RADIUS=', R:8:4);
;
DIV THETA0);
);
);
, '-----');
TO (VM+1) DO

V1-1)*THETA0;
'THETA=', THETAJ:8);
THETA=', THETAJ:8);
(THETAJ*3.142/180);
COS(THETAJ*3.142/180);
'PJ=', PJ);
, 'QJ=', QJ);

TO N DO

E IL1,1)*((1/SQRT(SQR(RZ[L1,1]-PJ)+SQR(RZ[L1,2]-QJ)))-(1/SQRT(SQR(RZ[L1,1]+PJ)+SQR(RZ[L1,2]+QJ)))

```

```

WRITELN(F1,'VOLTAGE AT POINT PJ,QJ IS',VJ:8:4);
EROR:=(1-VJ);
ERROR:=ERROR+SQR(EROR);
WRITELN(F1,'ERROR AT PJ,QJ=',EROR:8:4);
WRITELN(F1,'-----');
END;
WRITELN(F1);
WRITELN(F1,'CUMMULATIVE SQUARE ERROR=',ERROR:8:8);
WRITELN(F1);
writeIn(F1);
writeIn(F1,'=====');
writeIn(F1,'=====equipotential surface calculation=====');
DH:=(ZC-R)/5;
DL:=R/7.5;
FOR G:=1 TO 5 DO
BEGIN
RI:=0.0005;
ZI:=(G)*DH;
WRITELN(F1,'RI=',RI:8:4,' ZI=',ZI:8:4);
WRITELN(F1,'-----');
WHILE RI>0.0 DO
BEGIN
ER:=0.0;
EZ:=0.0;
FOR U1:=1 TO N DO
BEGIN
A:=(1/((SQR(RZ[U1,1]-RI))+SQR(RZ[U1,2]-ZI)));
B:=(1/((SQR(RZ[U1,1]-RI))+SQR(RZ[U1,2]+ZI)));
ER:=ER+CHARGE[U1,1]*2*(A-B);
C:=((ZI-RZ[U1,2])/((SQR(RI-RZ[U1,1])+SQR(ZI-RZ[U1,2]))));
D:=((ZI+RZ[U1,2])/((SQR(RI-RZ[U1,1])+SQR(ZI+RZ[U1,2]))));
EZ:=EZ+2*CHARGE[U1,1]*(C-D);
END;
WRITELN(F1,'ER=',ER:12:4,' EZ=',EZ:12:4);
WRITELN(F1,'-----');
IF ER=0.0 THEN
BEGIN
DZ:=0.0;
DR:=DL
END
ELSE
BEGIN
DZ:=DL/SQRT(1+SQR(EZ/ER));
DR:=- (EZ/ER)*DZ
END;
ZI:=ZI+DZ;
RI:=RI+DR;
WRITELN(F1,'RI=',RI:8:4,' ZI=',ZI:8:4);
writeIn('-----');
END;
WRITELN(F1);
WRITELN(F1);
END;
WRITELN(F1,'=====')
END.

```


TEST POINTS

0.0000 0.1000

0.1000 0.2000

0.0000 0.3000

CHARGE LOCATIONS ARE

0.0000 0.1500

0.0000 0.2000

0.0000 0.2500

DISTANCE MATRIX IS

16.0000 8.6667 3.8095

6.1971 7.5746 6.7750

4.4444 8.0000 18.1818

charge vector is

0.01074476

0.12595306

-0.00304584

CENTRE & RADIUS ARE

CENTRE= 0.2000 RADIUS= 0.1000

THETA= 0PJ= 0.0000000000E+00QJ= 1.0000000000E-01

VOLTAGE AT POINT PJ,QJ IS 1.0000

ERROR AT PJ,QJ= -0.0000

THETA= 15PJ= 2.5885183382E-02QJ= 1.0340829600E-01

VOLTAGE AT POINT PJ,QJ IS 0.9935

ERROR AT PJ,QJ= 0.0065

THETA= 30PJ= 5.0005879424E-02QJ= 1.1340085437E-01
VOLTAGE AT POINT PJ,QJ IS 0.9833
ERROR AT PJ,QJ= 0.0167

THETA= 45PJ= 7.0717878687E-02QJ= 1.2929652318E-01
VOLTAGE AT POINT PJ,QJ IS 0.9802
ERROR AT PJ,QJ= 0.0198

THETA= 60PJ= 8.6609328687E-02QJ= 1.5001175954E-01
VOLTAGE AT POINT PJ,QJ IS 0.9843
ERROR AT PJ,QJ= 0.0157

THETA= 75PJ= 9.6596974113E-02QJ= 1.7413449030E-01
VOLTAGE AT POINT PJ,QJ IS 0.9919
ERROR AT PJ,QJ= 0.0081

THETA= 90PJ= 9.9999997925E-02QJ= 2.0002036732E-01
VOLTAGE AT POINT PJ,QJ IS 1.0000
ERROR AT PJ,QJ= -0.0000

THETA= 105PJ= 9.6586429876E-02QJ= 2.2590485599E-01
VOLTAGE AT POINT PJ,QJ IS 1.0066
ERROR AT PJ,QJ= -0.0066

THETA= 120PJ= 8.6588958971E-02QJ= 2.5002351631E-01
VOLTAGE AT POINT PJ,QJ IS 1.0105
ERROR AT PJ,QJ= -0.0105

THETA= 135PJ= 7.0689072013E-02QJ= 2.7073227762E-01
VOLTAGE AT POINT PJ,QJ IS 1.0110
ERROR AT PJ,QJ= -0.0110

THETA= 150PJ= 4.9970599425E-02QJ= 2.8661950816E-01
VOLTAGE AT POINT PJ,QJ IS 1.0080
ERROR AT PJ,QJ= -0.0080

THETA= 165PJ= 2.5845834952E-02QJ= 2.9660224022E-01
VOLTAGE AT POINT PJ,QJ IS 1.0028
ERROR AT PJ,QJ= -0.0028

THETA= 180PJ= 4.0734639662E-05QJ= 2.9999999170E-01
VOLTAGE AT POINT PJ,QJ IS 1.0000
ERROR AT PJ,QJ= -0.0000

CUMMULATIVE SQUARE ERROR=0.00136970

=====

=====equipotential surface calculation=====

RI= 0.0005 ZI= 0.0200

ER= 3.0666 EZ= -2.7872

RI= 0.0095 ZI= 0.0299

ER= 4.6862 EZ= -2.8177

RI= 0.0163 ZI= 0.0413

ER= 6.7173 EZ= -2.8648

RI= 0.0216 ZI= 0.0536

ER= 9.2044 EZ= -2.9360

RI= 0.0256 ZI= 0.0663

ER= 12.2973 EZ= -3.0353

RI= 0.0288 ZI= 0.0792
ER= 16.2657 EZ= -3.1655

RI= 0.0314 ZI= 0.0923
ER= 21.5402 EZ= -3.3279

RI= 0.0334 ZI= 0.1055
ER= 28.7774 EZ= -3.5186

RI= 0.0350 ZI= 0.1187
ER= 38.8662 EZ= -3.7186

RI= 0.0363 ZI= 0.1320
ER= 52.5904 EZ= -3.8807

RI= 0.0373 ZI= 0.1453
ER= 69.9061 EZ= -3.9426

RI= 0.0380 ZI= 0.1586
ER= 91.1068 EZ= -3.8710

RI= 0.0386 ZI= 0.1719
ER= 118.7264 EZ= -3.5263

RI= 0.0390 ZI= 0.1852
ER= 149.8647 EZ= -2.4939

RI= 0.0392 ZI= 0.1986
ER= 166.0374 EZ= -0.5650

RI= 0.0392 ZI= 0.2119
ER= 150.1214 EZ= 1.4559

RI= 0.0391 ZI= 0.2252
ER= 114.8871 EZ= 2.5972

RI= 0.0388 ZI= 0.2386
ER= 81.3018 EZ= 2.8785

RI= 0.0383 ZI= 0.2519
ER= 56.8611 EZ= 2.7225

RI= 0.0377 ZI= 0.2652
ER= 40.9184 EZ= 2.4300

RI= 0.0369 ZI= 0.2785
ER= 30.6781 EZ= 2.1405

RI= 0.0360 ZI= 0.2918
ER= 23.7790 EZ= 1.8903

RI= 0.0349 ZI= 0.3051
ER= 18.8864 EZ= 1.6789

RI= 0.0338 ZI= 0.3184
ER= 15.2907 EZ= 1.5000

RI= 0.0325 ZI= 0.3317
ER= 12.5800 EZ= 1.3479

RI= 0.0310 ZI= 0.3449
ER= 10.4941 EZ= 1.2178

RI= 0.0295 ZI= 0.3582
ER= 8.8605 EZ= 1.1058

RI= 0.0278 ZI= 0.3714
ER= 7.5610 EZ= 1.0087

RI= 0.0261 ZI= 0.3846
ER= 6.5130 EZ= 0.9241

RI= 0.0242 ZI= 0.3978
ER= 5.6573 EZ= 0.8500

RI= 0.0222 ZI= 0.4110
ER= 4.9508 EZ= 0.7846

RI= 0.0201 ZI= 0.4242
ER= 4.3615 EZ= 0.7267

RI= 0.0179 ZI= 0.4373
ER= 3.8656 EZ= 0.6751

RI= 0.0157 ZI= 0.4505
ER= 3.4449 EZ= 0.6289

RI= 0.0133 ZI= 0.4636
ER= 3.0852 EZ= 0.5874

RI= 0.0108 ZI= 0.4767
ER= 2.7757 EZ= 0.5499

RI= 0.0082 ZI= 0.4897
ER= 2.5076 EZ= 0.5160

RI= 0.0055 ZI= 0.5028
ER= 2.2742 EZ= 0.4852

RI= 0.0027 ZI= 0.5158
ER= 2.0697 EZ= 0.4571

RI= -0.0002 ZI= 0.5289

RI= 0.0005 ZI= 0.0400

ER= 6.5816 EZ= -2.8824

RI= 0.0038 ZI= 0.0522
ER= 9.1830 EZ= -2.9743

RI= 0.0100 ZI= 0.0649
ER= 12.4886 EZ= -3.1009

RI= 0.0132 ZI= 0.0778
ER= 16.8634 EZ= -3.2715

RI= 0.0157 ZI= 0.0909
ER= 22.9731 EZ= -3.4988

RI= 0.0177 ZI= 0.1041
ER= 32.0924 EZ= -3.7992

RI= 0.0193 ZI= 0.1173
ER= 46.8322 EZ= -4.1878

RI= 0.0205 ZI= 0.1306
ER= 72.2681 EZ= -4.6341

RI= 0.0213 ZI= 0.1439

ER=	110.8825	EZ=	-4.9221
RI=	0.0219	ZI=	0.1573
ER=	146.6664	EZ=	-5.0689
RI=	0.0224	ZI=	0.1706
ER=	204.7403	EZ=	-5.6044
RI=	0.0227	ZI=	0.1839
ER=	334.3655	EZ=	-5.4069
RI=	0.0230	ZI=	0.1972
ER=	475.3594	EZ=	-1.5145
RI=	0.0230	ZI=	0.2106
ER=	393.6564	EZ=	3.9245
RI=	0.0229	ZI=	0.2239
ER=	227.1643	EZ=	5.2630
RI=	0.0226	ZI=	0.2372
ER=	125.0433	EZ=	4.6779
RI=	0.0221	ZI=	0.2506
ER=	70.9499	EZ=	3.7832
RI=	0.0214	ZI=	0.2639
ER=	46.4706	EZ=	3.0175
RI=	0.0205	ZI=	0.2772
ER=	34.3415	EZ=	2.5052
RI=	0.0195	ZI=	0.2905
ER=	26.3196	EZ=	2.1381
RI=	0.0184	ZI=	0.3038
ER=	20.6131	EZ=	1.8540
RI=	0.0172	ZI=	0.3170
ER=	16.4666	EZ=	1.6266
RI=	0.0159	ZI=	0.3303
ER=	13.3921	EZ=	1.4411
RI=	0.0145	ZI=	0.3436
ER=	11.0651	EZ=	1.2873
RI=	0.0130	ZI=	0.3568
ER=	9.2691	EZ=	1.1583
RI=	0.0113	ZI=	0.3700
ER=	7.8583	EZ=	1.0487
RI=	0.0095	ZI=	0.3833
ER=	6.7324	EZ=	0.9549
RI=	0.0077	ZI=	0.3965
ER=	5.8212	EZ=	0.8737
RI=	0.0057	ZI=	0.4097
ER=	5.0745	EZ=	0.8030
RI=	0.0036	ZI=	0.4228
ER=	4.4558	EZ=	0.7408
RI=	0.0014	ZI=	0.4360

ER= 3.9379 EZ= 0.6860

RI= -0.0009 ZI= 0.4491

RI= 0.0005 ZI= 0.0600

ER= 11.1861 EZ= -3.0576

RI= 0.0040 ZI= 0.0729

ER= 15.2196 EZ= -3.2234

RI= 0.0068 ZI= 0.0859

ER= 20.8187 EZ= -3.4481

RI= 0.0090 ZI= 0.0991

ER= 29.1868 EZ= -3.7554

RI= 0.0107 ZI= 0.1123

ER= 43.0886 EZ= -4.1844

RI= 0.0119 ZI= 0.1256

ER= 70.3377 EZ= -4.7943

RI= 0.0129 ZI= 0.1389

ER= 135.8978 EZ= -5.5199

RI= 0.0134 ZI= 0.1522

ER= 215.9730 EZ= -5.3392

RI= 0.0137 ZI= 0.1655

ER= 230.0174 EZ= -6.1994

RI= 0.0141 ZI= 0.1788

ER= 407.6140 EZ= -8.2807

RI= 0.0144 ZI= 0.1922

ER= 949.4174 EZ= -7.5129

RI= 0.0145 ZI= 0.2055

ER= 1054.5332 EZ= 5.6085

RI= 0.0144 ZI= 0.2188

ER= 446.0281 EZ= 8.2598

RI= 0.0141 ZI= 0.2322

ER= 193.9043 EZ= 6.4009

RI= 0.0137 ZI= 0.2455

ER= 83.2542 EZ= 4.8225

RI= 0.0129 ZI= 0.2588

ER= 45.0874 EZ= 3.4728

RI= 0.0119 ZI= 0.2721

ER= 37.7078 EZ= 2.7895

RI= 0.0109 ZI= 0.2854

ER= 29.5534 EZ= 2.3463

RI= 0.0099 ZI= 0.2987

ER= 23.0106 EZ= 2.0094

RI= 0.0087 ZI= 0.3120

ER= 18.1916 EZ= 1.7446

ER= 3.9379 EZ= 0.6860

RI= -0.0009 ZI= 0.4491

RI= 0.0005 ZI= 0.0600

ER= 11.1861 EZ= -3.0576

RI= 0.0040 ZI= 0.0729

ER= 15.2196 EZ= -3.2234

RI= 0.0068 ZI= 0.0859

ER= 20.8187 EZ= -3.4481

RI= 0.0090 ZI= 0.0991

ER= 29.1868 EZ= -3.7554

RI= 0.0107 ZI= 0.1123

ER= 43.0886 EZ= -4.1844

RI= 0.0119 ZI= 0.1256

ER= 70.3377 EZ= -4.7943

RI= 0.0129 ZI= 0.1389

ER= 135.8978 EZ= -5.5199

RI= 0.0134 ZI= 0.1522

ER= 215.9730 EZ= -5.3392

RI= 0.0137 ZI= 0.1655

ER= 230.0174 EZ= -6.1994

RI= 0.0141 ZI= 0.1788

ER= 407.6140 EZ= -8.2807

RI= 0.0144 ZI= 0.1922

ER= 949.4174 EZ= -7.5129

RI= 0.0145 ZI= 0.2055

ER= 1054.5332 EZ= 5.6085

RI= 0.0144 ZI= 0.2188

ER= 446.0281 EZ= 8.2596

RI= 0.0141 ZI= 0.2322

ER= 193.9043 EZ= 6.4009

RI= 0.0137 ZI= 0.2455

ER= 83.2542 EZ= 4.8225

RI= 0.0129 ZI= 0.2588

ER= 45.0874 EZ= 3.4728

RI= 0.0119 ZI= 0.2721

ER= 37.7078 EZ= 2.7895

RI= 0.0109 ZI= 0.2854

ER= 29.5534 EZ= 2.3463

RI= 0.0099 ZI= 0.2987

ER= 23.0106 EZ= 2.0094

RI= 0.0087 ZI= 0.3120

ER= 18.1916 EZ= 1.7446

RI= 0.0074 ZI= 0.3252
ER= 14.6471 EZ= 1.5324

RI= 0.0060 ZI= 0.3385
ER= 11.9961 EZ= 1.3594

RI= 0.0045 ZI= 0.3517
ER= 9.9739 EZ= 1.2160

RI= 0.0029 ZI= 0.3650
ER= 8.4019 EZ= 1.0957

RI= 0.0012 ZI= 0.3782
ER= 7.1588 EZ= 0.9935

RI= -0.0006 ZI= 0.3914

RI= 0.0005 ZI= 0.0800

ER= 18.1044 EZ= -3.3450

RI= 0.0029 ZI= 0.0931
ER= 25.1636 EZ= -3.6229

RI= 0.0048 ZI= 0.1063
ER= 36.4853 EZ= -4.0141

RI= 0.0063 ZI= 0.1196
ER= 57.8708 EZ= -4.5945

RI= 0.0073 ZI= 0.1329
ER= 114.0555 EZ= -5.5314

RI= 0.0080 ZI= 0.1462
ER= 356.4141 EZ= -6.3551

RI= 0.0082 ZI= 0.1593
ER= 280.7800 EZ= -5.3687

RI= 0.0085 ZI= 0.1728
ER= 344.2901 EZ= -8.2726

RI= 0.0088 ZI= 0.1862
ER= 949.3098 EZ= -13.0141

RI= 0.0090 ZI= 0.1995
ER= 3120.2399 EZ= -1.7146

RI= 0.0090 ZI= 0.2128
ER= 1026.5351 EZ= 13.0084

RI= 0.0088 ZI= 0.2262
ER= 323.2616 EZ= 8.5153

RI= 0.0085 ZI= 0.2395
ER= 122.2365 EZ= 6.0728

RI= 0.0078 ZI= 0.2528
ER= 0.5017 EZ= 4.0303

RI= -0.0054 ZI= 0.2545

RI= 0.0005 ZI= 0.1000

ER= 30.4211 EZ= -3.8164

RI= 0.0022 ZI= 0.1132

ER= 46.1193 EZ= -4.3083

RI= 0.0034 ZI= 0.1265

ER= 81.6683 EZ= -5.0998

RI= 0.0042 ZI= 0.1398

ER= 242.9013 EZ= -6.7084

RI= 0.0046 ZI= 0.1531

ER= 803.6458 EZ= -3.8545

RI= 0.0047 ZI= 0.1665

ER= 290.2484 EZ= -6.8313

RI= 0.0050 ZI= 0.1798

ER= 602.6244 EZ= -11.6852

RI= 0.0052 ZI= 0.1931

ER= 3387.1527 EZ= -23.2938

RI= 0.0053 ZI= 0.2065

ER= 3590.1042 EZ= 23.0556

RI= 0.0052 ZI= 0.2198

ER= 596.7892 EZ= 11.7460

RI= 0.0050 ZI= 0.2331

ER= 206.3640 EZ= 7.4001

RI= 0.0045 ZI= 0.2465

ER= -69.0556 EZ= 5.6461

RI= 0.0056 ZI= 0.2597

ER= 22.1685 EZ= 3.3163

RI= 0.0036 ZI= 0.2729

ER= 36.1367 EZ= 2.7892

RI= 0.0026 ZI= 0.2862

ER= 29.2333 EZ= 2.3533

RI= 0.0015 ZI= 0.2995

ER= 22.8136 EZ= 2.0105

```

PROGRAM RODPLANE;
USES CRT;
CONST N=10;
type
MATRIX1=ARRAY [1..N,1..N] OF REAL;
MATRIX2=ARRAY [1..N,1..1] OF REAL;

(=====)
PROCEDURE INVERSE(A:MATRIX1; VAR B:MATRIX2);
CONST NM=50;

N=10;
M=1;
VAR
INDXR:ARRAY[1..NM] OF INTEGER;
INDXC:ARRAY[1..NM] OF INTEGER;
IPIV:ARRAY[1..NM] OF INTEGER;
BIG,DUM,PIVINV:REAL;
I,J,V,U,LL,K,L,P,Q,ICOL,IROW:INTEGER;
BEGIN {OF PROCEDURE}
  FOR P:=1 TO N DO
    BEGIN
      FOR Q:=1 TO M DO
        BEGIN
          BIP,Q:=1.0;
        END;
      END;
    FOR J:=1 TO N DO
      BEGIN
        IPIV[J]:=0;
      END;
    FOR I:=1 TO N DO
      BEGIN
        BIG:=0.0;
        FOR J:=1 TO N DO
          BEGIN
            IF (IPIV[J]<>1) THEN
              BEGIN
                FOR K:=1 TO N DO
                  BEGIN
                    IF (IPIV[K]=0) THEN
                      BEGIN
                        IF (ABS(A[I,J,K])>=BIG) THEN
                          BEGIN
                            BIG:=ABS(A[I,J,K]);
                            IROW:=J;
                            ICOL:=K
                          END; END
                        ELSE
                          IF (IPIV[K]>1) THEN
                            BEGIN
                              WRITELN('SINGULAR POINT');
                              READLN
                            END;
                        END;
                      END
                    END
                  END
                END
              END
            END
          END
        END
        IPIV[ICOL]:=IPIV[ICOL]+1;
        IF (IROW <> ICOL) THEN
          BEGIN
            FOR L:=1 TO N DO
              BEGIN
                DUM:=A[IROW,L];
                A[IROW,L]:=A[ICOL,L];
                A[ICOL,L]:=DUM
              END;
            END;
            FOR L:=1 TO M DO
              BEGIN
                DUM:=B[IROW,L];
                B[IROW,L]:=B[ICOL,L];
                B[ICOL,L]:=DUM
              END;
            END;
          END;
        INDXR[I]:=IROW;
        INDXR[I]:=ICOL;
        IF (A[ICOL,ICOL]=0.0) THEN
          BEGIN

```

```

WRITELN('***** IT IS A SINGULAR MATRIX *****') ;
READLN
END;
PIVINV:=(1.0/A[ICOL,ICOL]);
A[ICOL,ICOL]:=1.0;
FOR L:=1 TO N DO
  BEGIN
    A[ICOL,L]:=A[ICOL,L]*PIVINV
  END;
FOR L:=1 TO M DO
  BEGIN
    B[ICOL,L]:=B[ICOL,L]*PIVINV
  END;
FOR LL:=1 TO N DO
  BEGIN
    IF (LL<>ICOL) THEN
      BEGIN
        DUM:=A[LL,ICOL];
        A[LL,ICOL]:=0.0;
        FOR L:=1 TO N DO
          BEGIN
            A[LL,L]:=A[LL,L]-A[ICOL,L]*DUM;
          END;
        FOR L:=1 TO M DO
          BEGIN
            B[LL,L]:=B[LL,L]-B[ICOL,L]*DUM
          END;
        END;
      END;
    END;
  END;
FOR L:=N DOWNTO 1 DO
  BEGIN
    IF (INDXR[L]<>INDXC[L]) THEN
      BEGIN
        FOR K:=1 TO N DO
          BEGIN
            DUM:=A[K ,INDXR[L]];
            A[K,INDXC[L]]:=A[K,INDXC[L]]-DUM;
          END;
        END;
      END;
    END;
  END;
WRITELN('=====');
END;
(MAIN PROGRAMME
=====)
CONST M=20; (M)=N+6) Q=10; (Q=M-N)
VAR ZN:ARRAY [1..N] OF REAL; (END POINTS OF THE LINE ELEMENTS)
PQ:ARRAY [1..M,1..2] OF REAL; (CONTOUR POINTS ,CHECK POINTS)
MAT:ARRAY [1..M,1..N] OF REAL; (POTENTIAL COEFFICIENTS)
CAT: MATRIX1;
CHARGE: MATRIX2;
VOL:ARRAY [1..Q] OF REAL;
DRI,elec,error,R0,THETA,R,G,L,A1,D1,D2,ERROR,D21,D22,d11,d12,M1,M2,DH,DL,RI,ZI,ER,EZ:REAL;
E1,E2,G1,G2,DL1,DL2,F1,F2,F3,F4,DZ,DR:REAL;
O,P,B1,C,D,I,J,K,S,T,U,V,I1:INTEGER;
file1:text;
BEGIN
  assign(file1,'san.prn');
  rewrite(file1);
  WRITELN('R,G'); (R=RADIUS OF SPHERICAL PART, G=DISTANCE FROM THE PLANE)
  READLN(R,G);
  WRITELN(file1,'Radius of spherical part =',R:8:4,' distance from plate =',G:8:4);
  WRITELN(file1,'=====');
  WRITELN('L,A1'); (L=LENGTH OF FIRST LINE CHARGE, A1=MULTIPLYING FACTOR FOR LENGTH)

```

```

READLN(L,A1);
WRITELN(file1,'Length of first line charge =',L:8:4,' multiplying factor =',A1:8:4);
WRITELN(file1,'=====');
ZN[1]:=R+G;
WRITELN(file1,ZN[1]:8:4);
ZN[2]:=R+G+L;
WRITELN(file1,ZN[2]:8:4);
FOR I:=3 TO N DO
BEGIN
J:=I-1;
K:=I-2;
ZN[I]:=A1*(ZN[J]-ZN[K])+ZN[J];
WRITELN(file1,ZN[I]:8:4);
END;
WRITELN(file1,'=====');
WRITELN(file1);
FOR B1:=1 TO 6 DO
BEGIN
THETA:=(B1-1)*15*3.1419/180;
PQ[B1,1]:=R*SIN(THETA);
PQ[B1,2]:=G+R*(1-COS(THETA));
WRITE(file1,PQ[B1,1]:8:4,PQ[B1,2]:8:4);
WRITELN(file1);
END;
FOR C:=7 TO (N+6) DO
BEGIN
PQ[C,1]:=R;
PQ[C,2]:=((ZN[C-6]+R+G)/2);
WRITE(file1,PQ[C,1]:8:4,PQ[C,2]:8:4);
WRITELN(file1);
END;
FOR D:=(N+7) TO M DO
BEGIN
THETA:=(3.1419/2)*((D-N-7)/(M-N-6));
writeLn(file1,'theta=',theta:8:4);
PQ[D,1]:=R*SIN(THETA);
PQ[D,2]:=G+R*(1-COS(THETA));
WRITE(file1,PQ[D,1]:8:4,PQ[D,2]:8:4);
WRITELN(file1);
END;
WRITELN(file1,'=====');
FOR U:=1 TO M DO
BEGIN
S:=U;
M1:=(1/SQRT(SQR(PQ[S,1])+SQR(PQ[S,2]-ZN[1])));
M2:=(1/SQRT(SQR(PQ[S,1])+SQR(PQ[S,2]+ZN[1])));
MAT[U,1]:=(M1-M2);
FOR V:=2 TO N DO
BEGIN
D1:=1/(ZN[V]-ZN[V-1]);
if pq[s,1]=0.0 then
begin
d11:=(zn[v]-pq[s,2]);
d12:=(zn[v-1]-pq[s,2]);
d21:=(zn[v-1]+pq[s,2]);
d22:=(zn[v]+pq[s,2]);
mat[u,v]:=d1*ln((d11/d12)*(d21/d22));
end
else
begin
d11:=(ZN[V]-PQ[S,2]+SQRT(SQR(ZN[V]-PQ[S,2])+SQR(PQ[S,1])));
d12:=(ZN[V-1]-PQ[S,2]+SQRT(SQR(ZN[V-1]-PQ[S,2])+SQR(PQ[S,1])));
d21:=(ZN[V-1]+PQ[S,2]+SQRT(SQR(ZN[V-1]+PQ[S,2])+SQR(PQ[S,1])));
d22:=(ZN[V]+PQ[S,2]+SQRT(SQR(ZN[V]+PQ[S,2])+SQR(PQ[S,1])));
MAT[U,V]:=d1*ln((d11/d12)*(d21/d22));
END;

```

```

write(file1,mat[u,v]:8:4)
end;
writeln(file1)
end;
FOR U:=1 TO N DO
BEGIN
FOR V:=1 TO N DO
BEGIN
CAT[U,V]:=MAT[U,V]
END;
END;
INVERSE(CAT,CHARGE);
writeln(file1,'=====');
writeln(file1,'charge vector is');
writeln(file1,'=====');
writeln(file1);
For u:=1 to n do
begin
writeln(file1,CHARGE[U,1]:8:8);
end;
writeln(file1,'=====');
{ERROR CALCULATION
=====}
writeln(file1,'ERROR CALCULATION');
ERROR:=0.0;
FOR I:=(N+1) TO M DO
BEGIN
II:=I-N;
VOL[II]:=0.0;
FOR J:=1 TO N DO
BEGIN
VOL[II]:=VOL[II]+MAT[II,J]*CHARGE[J,1]
END;
WRITELN(file1,'voltage=',VOL[II]:8:8);
ERROR:=ERROR+SQR(1-VOL[II]);
error:=1-vol[II];
writeln(file1,'error=',error:8:8)
END;
writeln(file1,'cumulative square error=',error:8:8);
{CALCULATION OF EQUIPOTENTIAL SURFACES}
writeln(file1,'CALCULATION OF EQUIPOTENTIAL SURFACES');
DH:=G/5;
DRI:=R/5;
FOR O:=1 TO 5 DO
BEGIN
RI:=0.0;
ZI:=O*DH;
WRITELN(file1,'RI=',RI,' ZI=',ZI);
WRITELN('RI=',RI,' ZI=',ZI);
WHILE ZI<(G+R) DO
BEGIN
E1:=EXP(1.5*LN(SQR(RI)+SQR(ZI-ZN[1])));
E2:=EXP(1.5*LN(SQR(RI)+SQR(ZI+ZN[1])));
ER:=CHARGE[1,1]*RI*((1.0/E1)-(1.0/E2));
EZ:=CHARGE[1,1]*(ZI-ZN[1])*((1.0/E1)-(1.0/E2));
FOR P:= 2 TO N DO
BEGIN
G1:=SQRT(SQR(RI)+SQR(ZN[P]-ZI));
G2:=SQRT(SQR(RI)+SQR(ZN[P-1]+ZI));
DL1:=SQRT(SQR(RI)+SQR(ZN[P-1]-ZI));
DL2:=SQRT(SQR(RI)+SQR(ZN[P]+ZI));
IF RI=0.0 THEN
BEGIN
ER:=0.0
END
ELSE

```

```

BEGIN
F1:=(ZN[P]-ZI)/(RI*G1);
F2:=(ZN[P-1]-ZI)/(RI*DL1);
F3:=(ZN[P-1]+ZI)/(RI*G2);
F4:=(ZN[P]+ZI)/(RI*DL2);
ER:=ER-((CHARGE[P,1])/((ZN[P]-ZN[P-1]))*(F1-F2+F3-F4)
END;
EZ:=EZ-((CHARGE[P,1])/((ZN[P]-ZN[P-1]))*((1/G1)-(1/DL1)-(1/G2)+(1/DL2))
END;(OF ER & EZ CALCULATION)
WRITELN('ER=',ER:8:4,' EZ=',EZ:8:4);
WRITELN('ER=',ER:8:4,' EZ=',EZ:8:4);
WRITELN;
(IF ER=0.0 THEN
BEGIN
DZ:=0.0;
DR:=DRI
END
ELSE
BEGIN)
DZ:=-((ER/EZ)*DRI;
(END;);
ZI:=ZI+DZ;
RI:=RI+DRI;
WRITELN(file1,'RI=',RI,' ZI=',ZI);
WRITELN('RI=',RI,' ZI=',ZI);
writeLn('-----');
writeLn('-----');
END;(OF WHILE LOOP)
WRITELN('-----');
WRITELN(file1)
END;(OF O LOOP)
writeLn('-----');
(END OF EQUIPOTENTIAL SURFACE CALCULATION
=====)
writeLn('end of execution');
close(file1)
END.

```

```

program fogo;
USES CRT;
CONST N=7; M=1;
TYPE
MATRIX1=ARRAY [1..N,1..N] OF REAL;
MATRIX2=ARRAY [1..N,1..M] OF REAL;
MATRIX3=ARRAY [1..N,1..2] OF REAL;
VAR XY:ARRAY[1..7,1..7] OF REAL;
PQ:ARRAY[1..8,1..2] OF REAL;
MAT:MATRIX1;
CHARGE:MATRIX2;
B:MATRIX2;
RS:MATRIX3;
RAT:MATRIX1;
VOL:MATRIX2;
ELEC,e221,e222,ER00R,ER0R,X,DRI,DX,P,Q,Y, A1,A2,A11,A12,K11,K12,E11,E12,RI,ZI,ER,EZ,AA1,AA2,
a111,a112,E21,E22,k111,k112,e111,e112,e1o,e2o,KK1,KK2,EE1,EE2,K1K,K2K,WR1,WR2,WZ1,WZ2,DZ,E1,
f,I,11,s1,t1,J,S,G,H,T,p1,q1,o,RU,u,v,mm:INTEGER;
F1,F2:TEXT;
PROCEDURE INVERSE(A:MATRIX1; VAR B:MATRIX2);
CONST NM=50;
      N=7; M=1;
VAR IPIV:ARRAY[1..NM] OF INTEGER;
INDXR:ARRAY[1..NM] OF INTEGER;
INDXC:ARRAY[1..NM] OF INTEGER;
BIG,DUM,PIVINV:REAL;
I,J,V,U,LL,K,L,P,Q,ICOL,IROW:INTEGER;
BEGIN
( FOR P:=1 TO N DO
  BEGIN
    FOR Q:=1 TO N DO
      BEGIN
        READ(file1,A[P,Q]);
      END;
    READLN(file1)
  END; )
FOR P:=1 TO N DO
  BEGIN
    FOR Q:=1 TO M DO
      BEGIN

```

```

      BIP,QI:=1.0;
    END;
  END;
FOR J:=1 TO N DO
  BEGIN
    IPIV[J]:=0;
  END;
FOR I:=1 TO N DO
  BEGIN
    BIG:=0.0;
    FOR J:=1 TO N DO
      BEGIN
        IF (IPIV[J]<>1) THEN
          BEGIN
            FOR K:=1 TO N DO
              BEGIN
                IF (IPIV[K]=0) THEN
                  BEGIN
                    IF (ABS(A[I,J,K])>BIG) THEN
                      BEGIN
                        BIG:=ABS(A[I,J,K]);
                        IROW:=J;
                        ICOL:=K
                      END; END
                    ELSE
                      IF (IPIV[K]>1 ) THEN
                        BEGIN
                          WRITELN('***** SINGULAR POINT *****');
                          writeln;
                          READLN
                        END;
                      END
                    END
                  END
                END;
            END;
            IPIV[ICOL]:=IPIV[ICOL]+1;
            IF (IROW <> ICOL) THEN
              BEGIN
                FOR L:=1 TO N DO
                  BEGIN
                    DUM:=A[IROW,L];
                    A[IROW,L]:=A[ICOL,L];
                    A[ICOL,L]:=DUM
                  END;
                FOR L:=1 TO M DO
                  BEGIN
                    DUM:=B[IROW,L];
                    B[IROW,L]:=B[ICOL,L];
                    B[ICOL,L]:=DUM
                  END;
                END;
                INDXR[I]:=IROW;
                INDXR[I]:=ICOL;
                IF (A[ICOL,ICOL]=0.0) THEN
                  BEGIN
                    WRITELN('***** IT IS A SINGULAR MATRIX *****') ;
                    READLN
                  END;
                PIVINV:=(1.0/A[ICOL,ICOL]);
                A[ICOL,ICOL]:=1.0;
                FOR L:=1 TO N DO
                  BEGIN
                    A[ICOL,L]:=A[ICOL,L]*PIVINV
                  END;
                FOR L:=1 TO M DO
                  BEGIN
                    B[ICOL,L]:=B[ICOL,L]*PIVINV

```



```

END;
FOR LL:=1 TO N DO
  BEGIN
    IF (LL<>ICOL) THEN
      BEGIN
        DUM:=A[LL,ICOL];
        A[LL,ICOL]:=0.0;
        FOR L:=1 TO N DO
          BEGIN
            A[LL,L]:=A[LL,L]-A[ICOL,L]*DUM;
          END;
        FOR L:=1 TO M DO
          BEGIN
            B[LL,L]:=B[LL,L]-B[ICOL,L]*DUM;
          END;
        END;
      END;
    END;
  END;
FOR L:=N DOWNT0 1 DO
  BEGIN
    IF (INDXR[L]<>INDXC[L]) THEN
      BEGIN
        FOR K:=1 TO N DO
          BEGIN
            DUM:=A[K,INDXR[L]];
            A[K,INDXR[L]]:=A[K,INDXC[L]];
            A[K,INDXC[L]]:=DUM;
          END;
        END;
      END;
    END;
  END;

```

```

(END OF PROCEDURE INVERSE )
(=====)

```

```

BEGIN ( main )
  ASSIGN(F1,'RAJ.PRN');
  REWRITE(F1);
  CLRSCR;
  (=====)
  WRITELN(F1,'CONTOUR POINTS,RING RADII & RING LOCATIONS ARE');
  (=====)
  X:=0.5 ;
  DX:=0.50;
  PQ[1,1]:=0.0;
  PQ[1,2]:=0.5;
  WRITE(F1,PQ[1,1]:8:4);
  WRITE(F1,PQ[1,2]:8:4);
  WRITE(F1,' ');
  XY[1,1]:=0.5;
  XY[1,2]:=1.250;
  WRITE(F1,XY[1,1]:8:4);
  WRITE(F1,' ');
  WRITE(F1,XY[1,2]:8:4);
  WRITELN(F1);
  PQ[2,1]:=0.5;
  PQ[2,2]:=0.52;
  WRITE(F1,PQ[2,1]:8:4);
  WRITE(F1,' ');
  WRITE(F1,PQ[2,2]:8:4);
  WRITE(F1,' ');
  WRITE(F1,' ');
  P:=0.5;
  FOR I:=2 TO 7 DO
    BEGIN

```

```

J:=I+1;
X:=X+(1.5*DX/I);
P:=P+DX;
Y:=1.487+0.00266*EXP(3.23*(X));
Q:=Y-1.0;
XY[I,1]:=X;
XY[I,2]:=Y;
PQ[I,1]:=P;
PQ[I,2]:=Q;
WRITE(F1,XY[I,1]:8:4);
WRITE(F1,' ');
WRITE(F1,XY[I,2]:8:4);
Writeln(F1);
WRITE(F1,PQ[I,1]:8:4);
WRITE(F1,' ');
WRITE(F1,PQ[I,2]:8:4);
WRITE(F1,' ');
END;
Writeln(F1);
Writeln(F1,'=====');
Writeln(F1,'POTENTIAL COFFECIENTS ');
Writeln(F1,'=====');
FOR S:=1 TO 7 DO
BEGIN
FOR T:=1 TO 7 DO
BEGIN
A1:=SQRT(SQR(PQ[S,1]+XY[T,1])+SQR(PQ[S,2]-XY[T,2]));
A2:=SQRT(SQR(PQ[S,1]+XY[T,1])+SQR(PQ[S,2]+XY[T,2]));
K1:=2*SQRT(PQ[S,1]*XY[T,1])/A1;
K2:=2*SQRT(PQ[S,1]*XY[T,1])/A2;
IF K1=0.0 THEN
begin
E1:=3.142/2
end
ELSE
BEGIN
E11:=1+0.25*SQRT(K1)+(9/64)*EXP(4*LN(K1));
E12:=(25/256)*EXP(6*LN(K1))+(1225/16384)*EXP(8*LN(K1));
E1:=(3.142/2)*(E11+E12);
END;
IF K2=0.0 THEN
BEGIN
E2:=3.142/2
END
ELSE
BEGIN
E21:=1+0.25*SQRT(K2)+(9/64)*EXP(4*LN(K2))+(25/256)*EXP(6*LN(K2));
E22:=(1225/16384)*EXP(8*LN(K2));
E2:=(3.142/2)*(E21+E22);
END;
MAT[S,T]:=(2/3.142)*((E1/A1)-(E2/A2));
WRITE(F1,MAT[S,T]:8:4);
WRITE(F1,' ');
END;
Writeln(F1);
END;
Writeln(F1,'=====');
(CALLING THE PROCEDURE INVERSE
***** )
INVERSE(MAT, CHARGE );
Writeln(F1,'CHARGE VECTOR IS');
FOR I:=1 TO N DO
BEGIN
Writeln(F1,CHARGE[I,1]:8:4);
END;
Writeln(F1);

```

```

DRI:=0.1;
MM:=1;

```

```

(=====)
=====)

```

```

CLRSCR;
WRITELN('ERROR CALCULATION');
WRITELN('+++++++');
rs[1,1]:=0.25; rs[2,1]:=0.6; rs[3,1]:=0.7; rs[4,1]:=0.8;
rs[1,2]:=0.5;
rs[5,1]:=0.9; rs[6,1]:=1.01; rs[7,1]:=1.1;
for ii:=2 to 7 do
begin
rs[ii,2]:=0.487+0.00266*exp(3.23*rs[ii,1]);
end;
WRITELN(F1,'TEST POINTS ARE');
FOR I:=1 TO N DO
BEGIN
FOR J:=1 TO 2 DO
BEGIN
WRITE(F1,RS[I,J]:8:4);
WRITE(F1,' ');
END;
WRITELN(F1)
END;
WRITELN(F1,'-----');
WRITELN(F1,'POTENTIAL COFFICIENTS FOF TEST POINTS ARE');
for S1:=1 to 7 do
begin
for T1:=1 to 7 do
begin
A111:=SQRT(SQR(RS[S1,1]+XY[T1,1])+SQR(RS[S1,2]-XY[T1,2]));
A112:=SQRT(SQR(RS[S1,1]+XY[T1,1])+SQR(RS[S1,2]+XY[T1,2]));
K111:=2*SQR(RS[S1,1]*XY[T1,1])/A111;
K112:=2*SQR(RS[S1,1]*XY[T1,1])/A112;
IF K111=0.0 THEN
BEGIN
E1o:=3.142/2
END
ELSE
BEGIN
E111:=1+0.25*SQR(K111)+(9/64)*EXP(4*LN(K111));
E112:=(25/256)*EXP(6*LN(K111))+(1225/16384)*EXP(8*LN(K111));
E1o:=(3.142/2)*(E111+E112);
END;
IF K112=0.0 THEN
BEGIN
E2o:=3.142/2
END
ELSE
BEGIN
E221:=1+0.25*SQR(K112)+(9/64)*EXP(4*LN(K112))+(25/256)*EXP(6*LN(K112));
E222:=(1225/16384)*EXP(8*LN(K112));
E2o:=(3.142/2)*(E221+E222);
END;
RAT[S1,T1]:=(2/3.142)*((E1o/A111)-(E2o/A112));
WRITE(F1,RAT[S1,T1]:8:4);
END;
WRITELN(F1);
END;
WRITELN(F1);
CLRSCR;
(MULTIPLICATION OF RAT WITH CHARGE AND ERROR CALCULATION)
=====)
EROOR:=0.0;
FOR P1:=1 TO 7 DO

```

```

J:=0.0;
: 1 TO 7 DO
IJ:=VOL[P1,IJ]+MAT[P1,QIJ]*CHARGE[Q1,IJ]
(F1,'VOLTAGE AT THE TEST POINT=',VOL[P1,IJ]:4:12);
I=VOL[P1,IJ];
EROOR+SQR(1-VOL[P1,IJ]);
(F1,'ERROR AT TH TEST POINT=',EROR:4:12);
(F1,'-----');

(F1);
(F1,'CUMMULATIVE SQUARE ERROR =',EROOR:4:8);
(F1,'equipotential surface calculation');
(F1,'=====');
=1 TO 5 DO

0;
0.1;
N('RI=',RI:8:3,' ZI=',ZI:8:3);
N(F1,'RI=',RI:8:3,' ZI=',ZI:8:3);
(ZI(0.96) DO

0;
0;
:=1 TO 7 DO

AA1:=SQR(SQR(RI+XY[H,1])+SQR(ZI-XY[H,2]));
AA2:=SQR(SQR(RI+XY[H,1])+SQR(ZI+XY[H,2]));
B1:=SQR(SQR(RI-XY[H,1])+SQR(ZI-XY[H,2]));
B2:=SQR(SQR(RI-XY[H,1])+SQR(ZI+XY[H,2]));
KK1:=2*SQR(RI*XY[H,1])/AA1;
KK2:=2*SQR(RI*XY[H,1])/AA2;
IF KK1=0.0 THEN
BEGIN
EE1:=3.142/2
END
ELSE

4
(3.142/2)*((1+(1/4)*SQR(KK1))+(9/64)*EXP(4*LN(KK1))+(25/256)*EXP(6*LN(KK1))+(1225/16384)*EXP(8*LN(KK1)))
K2=0.0 THEN
3.142/2

(3.142/2)*((1+(1/4)*SQR(KK2))+(9/64)*EXP(4*LN(KK2))+(25/256)*EXP(6*LN(KK2))+(1225/16384)*EXP(8*LN(KK2)))
1=0.0 THEN
=(3.142/2)

(3.142/2)*((1-(1/4)*SQR(KK1))-(3/64)*EXP(4*LN(KK1))-(5/256)*EXP(6*LN(KK1))-(175/16384)*EXP(8*LN(KK1)));
2=0.0 THEN
=(3.142/2)

=(3.142/2)*((1-(1/4)*SQR(KK2))-(3/64)*EXP(4*LN(KK2))-(5/256)*EXP(6*LN(KK2))-(175/16384)*EXP(8*LN(KK2)))

```

```

*(SQR(XY[H,1])-SQR(RI)+SQR(ZI -XY[H,2]))*K1K;
*(SQR(XY[H,1])-SQR(RI)+SQR(ZI +XY[H,2]))*K2K;

```

```

=0.0 THEN

```

```

.0

```

```

N

```

```

ER-(CHARGE[H,1]/(3.142*RI))*(((WR1-SQR(B1)*EE1)/(AA1*SQR(B1)))-((WR2-SQR(B2)*EE2)/(AA2*SQR(B2))));

```

```

=((ZI-XY[H,2])*K1K)/(AA1*SQR(B1));

```

```

=((ZI+XY[H,2])*K2K)/(AA2*SQR(B2));

```

```

EZ+(CHARGE[H,1]*(2/3.142)*(WZ1+WZ2))

```

```

TELN(' ER= ',ER:8:3,' EZ= ',EZ:8:3);

```

```

TELN(' ER= ',ER:8:3,' EZ= ',EZ:8:3);

```

```

:=SQR(SQR(ER)+SQR(EZ));

```

```

TELN('ELECTRIC FIELD =',ELEC:8:4);

```

```

TELN('ELECTRIC FIELD =',ELEC:8:4);

```

```

=-(ER/EZ)*DRI;

```

```

*ZI+DZ;

```

```

*RI+DRI;

```

```

TELN('-----');

```

```

TELN(' RI= ',RI:8:3,' ZI= ',ZI:8:3);

```

```

TELN;

```

```

TELN('-----');

```

```

TELN(F1,' RI= ',RI:8:3,' ZI= ',ZI:8:3);

```

```

TELN;

```

```

; (OF WHILE LOOP)

```

```

TELN ('=====');

```

```

TELN (F1,'=====');

```

```

; (OF G LOOP)

```

```

ISE(F1);

```

```

TELN('END OF EXECUTION')

```

```

)

```

CONTOUR POINTS, RING RADII & RING LOCATIONS ARE

	0.0000	0.5000	0.5000	1.2500
0.5000	0.5200		0.8750	1.5319
1.0000	0.5319	1.1250	1.5877	
1.5000	0.5877	1.3125	1.6715	
2.0000	0.6715	1.4625	1.7865	
2.5000	0.7865	1.5875	1.9355	
3.0000	0.9355	1.6946	2.1210	
3.5000	1.1210			

POTENTIAL COEFFICIENTS

0.5600	0.2871	0.2174	0.1743	0.1450	0.1233	0.1060
0.4941	0.2817	0.2195	0.1784	0.1494	0.1274	0.1097
0.3089	0.2221	0.1853	0.1577	0.1364	0.1192	0.1046
0.1897	0.1648	0.1469	0.1317	0.1190	0.1080	0.0979
0.1227	0.1209	0.1134	0.1063	0.1000	0.0941	0.0884
0.0855	0.0913	0.0888	0.0861	0.0836	0.0813	0.0787
0.0637	0.0715	0.0713	0.0709	0.0706	0.0704	0.0700

CHARGE VECTOR IS

-94.3635
-1298.1773
19857.6269
-67115.9749
95338.7670
-61866.7254
15211.9073

TEST POINTS ARE

0.2500	0.5000
0.6000	0.5055
0.7000	0.5125
0.8000	0.5222
0.9000	0.5357
1.0100	0.5565
1.1000	0.5799

POTENTIAL COEFFICIENTS FOR TEST POINTS ARE

0.5397	0.2841	0.2167	0.1743	0.1450	0.1233	0.1060
0.4420	0.2639	0.2083	0.1707	0.1436	0.1228	0.1059
0.4095	0.2561	0.2048	0.1692	0.1431	0.1229	0.1063
0.3776	0.2476	0.2007	0.1674	0.1426	0.1230	0.1068
0.3480	0.2392	0.1966	0.1656	0.1421	0.1234	0.1076
0.3192	0.2307	0.1926	0.1641	0.1421	0.1243	0.1091
0.2991	0.2250	0.1902	0.1636	0.1428	0.1258	0.1110

VOLTAGE AT THE TEST POINT=0.99999997951
ERROR AT TH TEST POINT=0.00000002049

VOLTAGE AT THE TEST POINT=1.00000000370
ERROR AT TH TEST POINT=-0.00000000373

VOLTAGE AT THE TEST POINT=0.99999997765
ERROR AT TH TEST POINT=0.00000002235

VOLTAGE AT THE TEST POINT=0.99999999255
ERROR AT TH TEST POINT=0.00000000745

VOLTAGE AT THE TEST POINT=1.00000001120
ERROR AT TH TEST POINT=-0.00000001118

VOLTAGE AT THE TEST POINT=1.00000000000
ERROR AT TH TEST POINT=0.00000000000

VOLTAGE AT THE TEST POINT=0.99999999814

ERROR AT TH TEST POINT=0.00000000186

CUMMULATIVE SQUARE ERROR =0.00000000
equipotential surface calculation

```
=====
RI= 0.000 ZI= 0.100
RI= 0.100 ZI= 0.100
RI= 0.200 ZI= 0.115
RI= 0.300 ZI= 0.147
RI= 0.400 ZI= 0.201
RI= 0.500 ZI= 0.285
RI= 0.600 ZI= 0.407
RI= 0.700 ZI= 0.561
RI= 0.800 ZI= 0.716
RI= 0.900 ZI= 0.860
RI= 1.000 ZI= 1.017
RI= 0.000 ZI= 0.200
RI= 0.100 ZI= 0.200
RI= 0.200 ZI= 0.214
RI= 0.300 ZI= 0.244
RI= 0.400 ZI= 0.293
RI= 0.500 ZI= 0.367
RI= 0.600 ZI= 0.470
RI= 0.700 ZI= 0.595
RI= 0.800 ZI= 0.728
RI= 0.900 ZI= 0.862
RI= 1.000 ZI= 1.017
RI= 0.000 ZI= 0.300
RI= 0.100 ZI= 0.300
RI= 0.200 ZI= 0.312
RI= 0.300 ZI= 0.338
RI= 0.400 ZI= 0.381
RI= 0.500 ZI= 0.444
RI= 0.600 ZI= 0.527
RI= 0.700 ZI= 0.629
RI= 0.800 ZI= 0.742
RI= 0.900 ZI= 0.867
RI= 1.000 ZI= 1.018
RI= 0.000 ZI= 0.400
RI= 0.100 ZI= 0.400
RI= 0.200 ZI= 0.410
RI= 0.300 ZI= 0.431
RI= 0.400 ZI= 0.465
RI= 0.500 ZI= 0.515
RI= 0.600 ZI= 0.581
RI= 0.700 ZI= 0.662
RI= 0.800 ZI= 0.758
RI= 0.900 ZI= 0.872
RI= 1.000 ZI= 1.019
RI= 0.000 ZI= 0.500
RI= 0.100 ZI= 0.500
RI= 0.200 ZI= 0.507
RI= 0.300 ZI= 0.521
RI= 0.400 ZI= 0.545
RI= 0.500 ZI= 0.581
RI= 0.600 ZI= 0.630
RI= 0.700 ZI= 0.693
RI= 0.800 ZI= 0.774
RI= 0.900 ZI= 0.879
RI= 1.000 ZI= 1.020
```

```

program general;
label 200,500,300,400,600;
CONST CO=9.0e09;
      NE=3;
      NB=7;
      EB=10;
      EBB=17;
      N=17;
TYPE MAT1=ARRAYC1..EBB,1..2J OF REAL;
MAT2=ARRAYC1..EB,1..2J OF REAL;
MAT3=ARRAYC1..EBB,1..EBB OF REAL;
MAT4=ARRAYC1..NB,1..EBB OF REAL;
MAT5=ARRAYC1..NEJ OF REAL;
MAT6=ARRAYC1..EBB,1..1J OF REAL;
MAT7=ARRAYC1..EBB,1..3J OF REAL;
VAR
  C1,NOM,ANS1,G,U,E1,E2,D11,D12,D21,D22,ED1,ED2,M11,M12,M21,M22,I1,I2,P1,P2,P3,Q1,Q2:INTEGER;
  GI,MM,FO,ANS3,LO,H11,OO,H12,H21,H22,ANSO,G1,G2,H1,H2,ANS,X1,Y1,K1,L1,M1,N1,O1,R1,I,J,K:INTEGER;
  RZ:MAT1;
  PQ:MAT2;
  MAT:MAT3;
  TH1:MAT5;
  TH2:MAT4;
  THETA:MAT4;
  CHARGE:MAT6;
  SC:MAT2;
  CS:MAT2;
  HH:MAT7;
  TAN:ARRAYC1..EBB OF REAL;
  ERR:MAT1;
  EROR:ARRAYC1..EBB OF REAL;
  VOL:ARRAYC1..EBB OF REAL;
  CUM,TANG1,RIS,ZIS,ZI,AO,BO,R1E,Z1E,CO,A2,B2,C2,ER,EZ,DR,DZ,DL,EP,R1,EP2:REAL;
  D1,D2,R11,R12,ZI1,ZI2,RIA,ZIA:REAL;
FI,FJ:TEXT;
FUNCTION F(RZ:MAT1;PQ:MAT2;F1,F2:INTEGER):REAL;
  BEGIN
    F:=(1/SGRT(SQR(RZCF1,1J-PQCF2,1J)+SQR(RZCF1,2J-PQCF2,2J)));
  END;
FUNCTION FER(RZ:MAT1;CHARGE:MAT6;RI,ZI:REAL;V:INTEGER):real;
  VAR A,B,C:REAL;
  BEGIN
    A:=RI-RZCV,1J;
    B:=ZI-RZCV,2J;
    C:=EXP(1.5*LN(SQR(A)+SQR(B)));
    FER:=CHARGE*V,1J*(A/C);
  END;
FUNCTION FEZ(RZ:MAT1;CHARGE:MAT6;RI,ZI:REAL;W:INTEGER):real;
  VAR A,B,C:REAL;
  BEGIN
    A:=RI-RZCW,1J;
    B:=ZI-RZCW,2J;
    C:=EXP(1.5*LN(SQR(A)+SQR(B)));
    FEZ:=CHARGE*W,1J*(B/C);
  END;
FUNCTION FV(RZ:MAT1;ERR:MAT1;CHARGE:MAT6;G2,G1:INTEGER):REAL;
  BEGIN
    FV:=CHARGE*G2,1J*(1/SGRT(SQR(RZCG2,1J-ERRCG1,1J)+SQR(RZCG2,2J-ERRCG1,2J)));
  END;
FUNCTION FS(RZ:MAT1;PQ:MAT2;SC:MAT2;U,V,W:INTEGER):REAL;
  VAR L:REAL;
  BEGIN

```



```

      L:=EXP(1.5*LN(SQR(RZCU,1J-PGEV,1J)+SQR(RZCU,2J-PGEV,2J)));
      FB:=((RZCU,1J-PGEV,1J)*SCCW,2J+(RZCU,2J-PGEV,2J)*SCCW,1J)/L
    END;
FUNCTION FH(RZ:MAT1;HH:MAT7;CS:MAT2;PD,LO:INTEGER):REAL;
  VAR LI:REAL;
  BEGIN
    LI:=EXP(1.5*LN(SQR(RZCPO,1J-HHCL0,1J)+SQR(RZCPO,2J-HHCL0,2J)));
    FH:=((RZCPO,1J-HHCL0,1J)*CSCLO,1J+(RZCPO,2J-HHCL0,2J)*CSCLO,2J)/LI
  END;
PROCEDURE INVERSE(A:MAT3; VAR B:MAT6);
CONST NM=50;
N=17;
M=1;
NE=3;
NB=7;
EB=10;
VAR INDXR:ARRAY1..NM OF INTEGER;
    INDXC:ARRAY1..NM OF INTEGER;
    IPIV:ARRAY1..NM OF INTEGER;
    BIG,PIVINV,DUM:REAL;
    I,J,U,V,LL,L,K,P,Q,ICOL,IROW:INTEGER;
BEGIN
  IF PROCEDURE
  FOR P:=1 TO NE DO
  BEGIN
    FOR Q:=1 TO M DO
    BEGIN
      BCF,QD:=1.0;
    END;
  END;
  FOR P:=(NE+1) TO N DO
  BEGIN
    FOR Q:=1 TO M DO
    BEGIN
      BCF,QD:=0.0;
    END;
  END;
  FOR J:=1 TO N DO
  BEGIN
    IF IVEJJ:=0;
  END;
  FOR I:=1 TO N DO
  BEGIN
    BIG:=0.0;
    FOR J:=1 TO N DO
    BEGIN
      IF (IPIVJ>1) THEN
      BEGIN
        FOR K:=1 TO N DO
        BEGIN
          IF (IPIVK=0) THEN
          BEGIN
            IF (ABS(AIJ,KD))>=BIG) THEN
            BEGIN
              BIG:=ABS(AIJ,KD);
              IROW:=J;
              ICOL:=K
            END;
          END;
        ELSE
          IF (IPIVK>1) THEN
          BEGIN
            WRITELN('SINGULAR POINT');

```

```

READLN
END;
END
END
END;
IPIVEICOLJ:=IPIVEICOLD+1;
IF (IROW<>ICOL) THEN
BEGIN
FOR L:=1 TO N DO
BEGIN
DUM:=ACIROW,LJ;
ACIROW,LJ:=ACICOL,LJ;
ACICOL,LJ:=DUM;
END;
FOR L:=1 TO M DO
BEGIN
DUM:=BCIROW,LJ;
BCIROW,LJ:=BEICOL,LJ;
BEICOL,LJ:=DUM;
END;
END;
INDXREID:=IROW;
INDXREID:=ICOL;
IF (ACICOL,ICOLD=0.0) THEN
BEGIN
WRITELN('SINGULAR MATRIX');
READLN
END;
PIVINV:=(1.0/ACICOL,ICOLD);
ACICOL,ICOLD:=1.0;
FOR L:=1 TO N DO
BEGIN
ACICOL,LJ:=ACICOL,LJ*PIVINV
END;
FOR L:=1 TO M DO
BEGIN
BEICOL,LJ:=BEICOL,LJ*PIVINV
END;
FOR LL:=1 TO N DO
BEGIN
IF (LL<>ICOL) THEN
BEGIN
DUM:=ACLL,ICOLD;
ACLL,ICOLD:=0.0;
FOR L:=1 TO N DO
BEGIN
ACLL,LJ:=ACLL,LJ-ACICOL,LJ*DUM;
END;
FOR L:=1 TO M DO
BEGIN
BELL,LJ:=BELL,LJ-BEICOL,LJ*DUM
END;
END;
END;
END;
FOR L:=N DOWNT0 1 DO
BEGIN
IF (INDXRELD<>INDXCOLD) THEN
BEGIN
FOR K:=1 TO N DO
BEGIN
DUM:=ACK,INDXRELD;

```

```

4

    ACK,INDXREL33:=ACK,INDXCCEL33;
    ACK,INDXCCEL33:=DUM
    END;END;
    END;
    WRITELN('=====');
    END;(OF PROCEDURE)
BEGIN(OF MAIN PROGRAMME)
    ASSIGN(FI,'MAT.DAT ');
    REWRITE(FI);
    ASSIGN(FJ,'DAT.PRN');
    RESET(FJ);
    WRITELN(FI,'GIVE THE LOCATION OF SIMULATION CHARGES INSIDE THE ELECTRODE');
    WRITELN('GIVE THE LOCATION OF SIMULATION CHARGES INSIDE THE ELECTRODE');
    FOR E1:=1 TO NE DO
    BEGIN
    FOR E2:=1 TO 2 DO
    BEGIN
    READ(FJ,RZEE1,E2);
    WRITE(FI,RZEE1,E2:8:4,' ');
    END;
    READLN(FJ);
    WRITELN(FI);
    END;
    WRITELN(FI,'GIVE THE LOCATION OF SIMULATION CHARGES INSIDE THE AIR');
    WRITELN('GIVE THE LOCATION OF SIMULATION CHARGES INSIDE THE AIR');
    FOR D11:=1 TO NE DO
    BEGIN
    FOR D12:=1 TO 2 DO
    BEGIN
    READ(FJ,RZC(D11+NE),D12);
    WRITE(FI,RZC(D11+NE),D12:8:4,' ');
    END;
    WRITELN(FI);
    READLN(FJ);
    END;
    WRITELN(FI,'GIVE THE LOCATION OF SIMULATION CHARGES INSIDE THE DIELECTRIC');
    WRITELN('GIVE THE LOCATION OF SIMULATION CHARGES INSIDE THE DIELECTRIC ');
    FOR D21:=1 TO NE DO
    BEGIN
    FOR D22:=1 TO 2 DO
    BEGIN
    READ(FJ,RZC(D21+EB),D22);
    WRITE(FI,RZC(D21+EB),D22:8:4,' ');
    END;
    READLN(FJ);
    WRITELN(FI);
    END;
    WRITELN(FI);
    WRITELN(FI,'GIVE THE NUMBER OF CONTOUR POINTS ON THE AIR-E INTERFACE');
    WRITELN('GIVE THE NUMBER OF CONTOUR POINTS ON THE AIR-E INTERFACE');
    READLN(FJ,ED1);
    WRITELN(FI,ED1);
    ED2:=NE-ED1;
    IF (ED1>0.0) THEN
    BEGIN
    WRITELN(FI,'GIVE THE LOCATION OF ABOVE CONTOUR POINTS');
    WRITELN('GIVE THE LOCATION OF ABOVE CONTOUR POINTS');
    FOR M11:=1 TO ED1 DO
    BEGIN
    FOR M12:=1 TO 2 DO
    BEGIN
    READ(FJ,PGIM11,M12);

```

```

WRITE(FI,PQCM11,M12J:8:4,' ');
END;
READLN(FJ);
WRITELN(FI);
END;
END;
IF (ED2>0.0) THEN
BEGIN
WRITELN(FI,'GIVE THE LOCATION OF CONTOUR POINTS ON THE THE D-E INTERFACE');
WRITELN('GIVE THE LOCATION OF CONTOUR POINTS ON THE THE D-E INTERFACE');
FOR M21:=1 TO ED2 DO
BEGIN
FOR M22:=1 TO 2 DO
BEGIN
READ(PQC(M21+ED1),M22J);
WRITE(FI,PQC(M21+ED1),M22J:8:4,' ');
END;
READLN;
WRITELN(FI);
END;
END;
WRITELN(FI,'CONTOUR POINTS ON THE AIR-D INTERFACE ARE');
WRITELN('CONTOUR POINTS ON THE AIR-D INTERFACE ARE');
FOR I1:=1 TO NB DO
BEGIN
FOR I2:=1 TO 2 DO
BEGIN
PQC(NE+I1),I2J:=(RZC(NE+I1),I2J+RZC(EB+I1),I2J)/2;
WRITE(FI,PQC(NE+I1),I2J:8:4,' ');
END;
WRITELN(FI);
END;
WRITELN(FI);
WRITELN('GIVE THE RELATIVE PERMEABILITY OF D');
WRITELN(FI,'GIVE THE RELATIVE PERMEABILITY OF D');
READLN(EP2);
WRITELN(FI,EP2:8:4);
WRITELN(FI);
{calculating the theta matrix}
=====
FOR P1:=1 TO NB DO
BEGIN
IF (RZC(NE+P1),1J-RZC(EB+P1),1J)=0.0 THEN
TANG1:=1.0E10
ELSE
TANG1:=(RZC(NE+P1,2J)-RZC(EB+P1,2J))/(RZC(NE+P1,1J)-RZC(EB+P1,1J));
TH1CP1J:=ARCTAN(TANG1);
END;
{-----}
FOR P1:=1 TO NB DO
BEGIN
SCCP1,1J:=ABS(SIN(TH1CP1J));
SCCP1,2J:=ABS(COS(TH1CP1J))
END;
{-----}
{calculating the potential matrix}
=====
IF (ED1>0.0) THEN
BEGIN
FOR X1:=1 TO ED1 DO
BEGIN
FOR Y1:=1 TO NE DO

```

```

      BEGIN
        MATCX1,Y1D:=(CD)*F(RZ,PG,Y1,X1);
      END;
      FOR Y1:=(NE+1) TO EB DO
        BEGIN
          MATCX1,Y1D:=0.0;
        END;
        FOR Y1:=(EB+1) TO EBB DO
          BEGIN
            MATCX1,Y1D:=(CD)*F(RZ,PG,Y1,X1);
          END;
        END;
      END;
    END;
  END;
  (OF ED1 ROWS CALCULATION)
  END;
  (OF ED1)0.0 )
  (-----)
  FOR K1:=(ED1+1) TO NE DO
    BEGIN
      FOR L1:=1 TO NE DO
        BEGIN
          MATCK1,L1D:=(CD)*F(RZ,PG,L1,K1);
        END;
        FOR L1:=(NE+1) TO EB DO
          BEGIN
            MATCK1,L1D:=(CD)*F(RZ,PG,L1,K1);
          END;
          FOR L1:=(EB+1) TO EBB DO
            BEGIN
              MATCK1,L1D:=0.0;
            END;
          END;
        END;
      END;
    END;
  (-----)
  FOR M1:=(NE+1) TO EB DO
    BEGIN
      FOR N1:=1 TO NE DO
        BEGIN
          MATCM1,N1D:=0.0;
        END;
        FOR N1:=(NE+1) TO EB DO
          BEGIN
            MATCM1,N1D:=- (CD)*F(RZ,PG,N1,M1);
          END;
          FOR N1:=(EB+1) TO EBB DO
            BEGIN
              MATCM1,N1D:=(CD)*F(RZ,PG,N1,M1);
            END;
          END;
        END;
      END;
    END;
  (-----)
  FOR O1:=(EB+1) TO EBB DO
    BEGIN
      FOR R1:=1 TO NE DO
        BEGIN
          MATCO1,R1D:=(EP2-1)*(CD)*F3(RZ,PG,SC,R1,O1-NE,O1-EB)
        END;
        FOR R1:=(NE+1) TO EB DO
          BEGIN
            MATCO1,R1D:=EP2*CD*F3(RZ,PG,SC,R1,O1-NE,O1-EB)
          END;
          FOR R1:=(EB+1) TO EBB DO
            BEGIN
              MATLO1,R1D:=- (CD)*F3(RZ,PG,SC,R1,O1-NE,O1-EB)
            END;
          END;
        END;
      END;
    END;
  (-----)

```

```

FOR I:=1 TO EBB DO
BEGIN
  FOR J:=1 TO EB DO
  BEGIN
    WRITE(MATC1,JJ:8,' ');
  END;
  WRITELN;
END;
WRITELN('=====');
FOR I:=1 TO EBB DO
BEGIN
  FOR J:=(EB+1) TO EBB DO
  BEGIN
    WRITE(MATC1,JJ:8,' ');
  END;
  WRITELN;
END;
{+++++}
inverse(mat,charge);
{+++++}
WRITELN(F1,'CHARGE VECTOR IS');
FOR CI:=1 TO N DO
BEGIN
  WRITELN(F1,CHARGECC1,1J:8);
  WRITELN(CHARGECC1,1J:8);
END;
{error calculation
=====}
writein(F1,'do you want to calculate the error. if yes then write 1 else write 0');
writein('do you want to calculate the error. if yes then write 1 else write 0');
READLN(ANSO);
WRITELN(F1,ANSO);
IF ANSO= 1 THEN
BEGIN
  WRITELN(F1,'GIVE THE NUMBER OF SUCH TEST POINTS ON THE AIR-E INTERFACE');
  WRITELN('GIVE THE NUMBER OF SUCH TEST POINTS ON THE AIR-E INTERFACE');
  READLN(H1);
  IF H1>0.0 THEN
  BEGIN
    WRITELN(F1,'GIVE THE LOCATION OF SUCH POINTS');
    WRITELN('GIVE THE LOCATION OF SUCH POINTS');
    FOR H11:=1 TO H1 DO
    BEGIN
      FOR H12:=1 TO 2 DO
      BEGIN
        READ(ERRCH11,H12J);
        WRITE(F1,ERRCH11.H12J:8:4,' ');
        WRITE(ERRCH11,H12J:8:4,' ');
      END;
      READLN;
      WRITELN ;
      WRITELN(F1);
    END;
  END;
  WRITELN(F1,'GIVE THE NUMBER OF TEST POINTS ON THE D-E INTERFACE');
  WRITELN('GIVE THE NUMBER OF TEST POINTS ON THE D-E INTERFACE');
  READLN(H2);
  IF H2>0.0 THEN
  BEGIN
    WRITELN(F1,'GIVE THE LOCATION OF THESE TEST POINTS');
    WRITELN('GIVE THE LOCATION OF THESE TEST POINTS');
    FOR H21:=1 TO H2 DO

```

```

BEGIN
FOR H22:=1 TO 2 DO
BEGIN
READ(ERRCH21,H223);
WRITE(ERRCH21,H223:8:4,' ');
WRITE(F1,ERRCH21,H223:8:4,' ');
END;
READLN;
WRITELN(F1);
WRITELN
END;
END;
FOR G1:=1 TO (H1+H2) DO
BEGIN
VOLCG13:=0.0;
END;
IF H1>0.0 THEN
BEGIN
FOR G1:=1 TO H1 DO
BEGIN
FOR G2:=1 TO NE DO
BEGIN
VOLCG13:=VOLCG13+CO*FV(RZ,ERR,CHARGE,G2,G1)
END;
FOR G2:=(EB+1) TO EBB DO
BEGIN
VOLCG13:=VOLCG13+CO*FV(RZ,ERR,CHARGE,G2,G1)
END;
END;
END;
IF H2>0.0 THEN
BEGIN
FOR G1:=(H1+1) TO (H1+H2) DO
BEGIN
FOR G2:=1 TO NE DO
BEGIN
VOLCG13:=VOLCG13+CO*FV(RZ,ERR,CHARGE,G2,G1)
END;
FOR G2:=(NE+1) TO EB DO
BEGIN
VOLCG13:=VOLCG13+CO*FV(RZ,ERR,CHARGE,G2,G1)
END;
END;
END;
WRITELN('THE ERROR VEVTOR IS');
WRITELN(F1,'THE ERROR VEVTOR IS');
CUM:=0.0;
FOR G1:=1 TO (H1+H2) DO
BEGIN
EROREG13:=VOLCG13-1;
WRITELN(F1,EROREG13:8:4);
WRITELN(EROREG13:8:4);
CUM:=CUM+SGR(EROREG13)
END;
WRITELN(F1,'CUMMULATIVE SQUARE ERROR IS');
WRITELN('CUMMULATIVE SQUARE ERROR IS');
WRITELN(F1,CUM:8:4);
WRITELN(CUM:8:4);
END;
WRITELN(F1,'END OF ERROR CALCULATION');
(END OF ERROR CALCULATION
=====)

```

```

WRITELN('DO YOU WANT TO CALCULATE THE EQUIPOTENTIAL SURFACE. IF YES THEN');
WRITELN('WRITE 1 ELSE WRITE 0');
WRITELN(FI,'DO YOU WANT TO CALCULATE THE EQUIPOTENTIAL SURFACE. IF YES THEN');
WRITELN(FI,' WRITE 1 ELSE WRITE 0');
READLN(ANS1);
WRITELN(FI,ANS1);
WRITELN(ANS1);
IF ANS1=1 THEN
BEGIN
WRITELN(FI,'calculating the equipotential surface');
{calculating the equipotential surface
=====}
200: WRITELN(FI,'GIVE THE INITIAL POINT OF THE DESIRED EQUIPOTENTIAL SURFACE');
WRITELN('GIVE THE INITIAL POINT OF THE DESIRED EQUIPOTENTIAL SURFACE');
READLN(RIS,ZIS);
WRITELN(FI,RIS:8:4,ZIS:8:4);
WRITELN(FI,'GIVE THE EXTENTION POINT OF THE EQUIPOTENTIAL SURFACE');
WRITELN('GIVE THE EXTENTION POINT OF THE EQUIPOTENTIAL SURFACE');
READLN(RI,ZI);
WRITELN(FI,RI:8:4,ZI:8:4);
WRITELN(RI:8:4,ZI:8:4);

WRITELN(FI,'GIVE THE CONSTANTS OF THE FIRST BOUNDARY LINE :ax+by+c=0 SUCH THAT THE');
WRITELN(FI,'STARTING POINT FALLS IN THE REGION:ax+by+c<=0');
WRITELN('GIVE THE CONSTANTS OF THE FIRST BOUNDARY LINE :ax+by+c=0 SUCH THAT THE');
WRITELN('STARTING POINT FALLS IN THE REGION:ax+by+c<=0');
WRITE('A=');
READLN(A0);
WRITELN(A0:8:4);
WRITE('B=');
READLN(B0);
WRITELN(B0:8:4);
WRITE('C=');
READLN(C0);
WRITELN(C0:8:4);
WRITE(FI,'A=');
WRITELN(FI,A0:8:4);
WRITE(FI,'B=');
WRITELN(FI,B0:8:4);
WRITE(FI,'C=');
WRITELN(FI,C0:8:4);

WRITELN('GIVE THE CONSTANTS OF THE SECOND BOUNDARY LINE:ax+by+c=0 SUCH THAT THE');
WRITELN('STARTING POINT FALLS IN THE REGION:ax+by+c<=0');
WRITE('A=');
READLN(A2);
WRITELN(A2:8:4);
WRITE('B=');
READLN(B2);
WRITELN(B2:8:4);
WRITE('C=');
READLN(C2);
WRITELN(C2:8:4);

WRITELN('GIVE THE RELATIVE PERMEABILITY OF THE INITIAL POINT');
READLN(EP);
WRITELN('GIVE THE LENGTH OF INFINITSIMAL ELEMENT ALONG THE EQUIPOTENTIAL SURFACE');
READLN(DL);
WRITELN(DL:8:4);
WRITELN(FI,'GIVE THE CONSTANTS OF THE SECOND BOUNDARY LINE:ax+by+c=0 SUCH THAT THE');
WRITELN(FI,'STARTING POINT FALLS IN THE REGION:ax+by+c<=0');
WRITE(FI,'A=');
WRITELN(FI,A2:8:4);
WRITE(FI,'B=');

```



```

        WRITELN(F1,B2:8:4);
        WRITE(F1,'C=');
        WRITELN(F1,C2:8:4);
    WRITELN(F1,'GIVE THE RELATIVE PERMEABILITY OF THE INITIAL POINT');
    WRITELN(F1,EP:8:4);
    WRITELN(F1,'GIVE THE LENGTH OF INFINITSIMAL ELEMENT ALONG THE EQUIPOTENTIAL SURFACE');
    WRITELN(F1,DL:8:4);
    {-----}
500:IF ((A0*R1)+(B0*Z1)+C0) < 0.0 THEN
BEGIN {OF FIRST IF LOOP}
    IF ((A2*R1)+(B2*Z1)+C2) < 0.0 THEN
    BEGIN {OF SECOND IF LOOP}
        ER:=0.0;
        EZ:=0.0;
        FOR U:=1 TO NE DO
        BEGIN {OF FOR LOOP}
            ER:=ER+(CO)*FER(RZ,CHARGE,R1,Z1,U);
            EZ:=EZ+(CO)*FEZ(RZ,CHARGE,R1,Z1,U);
        END; {OF FOR LOOP}
        IF EP=EP2 THEN
        BEGIN {OF SECOND IF LOOP}
            FOR U:=(NE+1) TO EE DO
            BEGIN {OF SECOND FOR LOOP}
                ER:=ER+(CO)*FER(RZ,CHARGE,R1,Z1,U);
                EZ:=EZ+(CO)*FEZ(RZ,CHARGE,R1,Z1,U);
            END; {OF SECOND FOR LOOP}
        END
    END
    ELSE
    BEGIN
        FOR U:=(EE+1) TO EBE DO
        BEGIN
            ER:=ER+(CO)*FER(RZ,CHARGE,R1,Z1,U);
            EZ:=EZ+(CO)*FEZ(RZ,CHARGE,R1,Z1,U);
        END;
    END; {OF SECOND IF LOOP}
    WRITELN('ER=',ER:8,' EZ=',EZ:8);
    IF ER=0.0 THEN
    BEGIN
        DZ:=0.0;
        DR:=DL;
        R11:=R1+DR;
        R12:=R1-DR;
        Z1:=Z1;
        R1E:=2*R1-R1S;
        Z1E:=2*Z1-Z1S;
        D1:=ABS(R11-R1E);
        D2:=ABS(R12-R1E);
    END
    ELSE
    BEGIN
        DZ:= DL/SQRT(1+SGR(EZ/ER));
        DR:=(EZ/ER)*DZ;
        R11:=R1+DR;
        R12:=R1-DR;
        Z11:=Z1+DZ;
        Z12:=Z1-DZ;
        R1E:=2*R1-R1S;
        Z1E:=2*Z1-Z1S;
        D1:=SGR(R11-R1E)+SGR(Z11-Z1E);
        D2:=SGR(R12-R1E)+SGR(Z12-Z1E);
    END;
    RIS:=R1;

```

```

ZIS:=ZI;
IF D1<D2 THEN
BEGIN
RI:=RI1;
ZI:=ZI1
END
ELSE
BEGIN
RI:=RI2;
ZI:=ZI2
END;
IF (AO*RI)+(BO*ZI)+CO>0.00000 THEN
BEGIN
RIA:=(BO*(RI-ZI-R1*ZIS)+CO*(RI-R1))/(AO*(RI-RIS)+BO*(ZI-ZIS));
ZIA:=(AO*(ZIS*RI-ZI*RIS)+CO*(ZIS-ZI))/(BO*(ZI-ZIS)+AO*(RI-RIS));
WRITELN('RIA=',RIA:8:4,' ZIA=',ZIA:8:4);
WRITELN(FI,'RIA=',RIA:8:4,' ZIA=',ZIA:8:4);
END;
IF (A2*RI)+(B2*ZI)+C2>0.00000 THEN
BEGIN
RIA:=(B2*(RI-ZI-R1*ZIS)+C2*(RI-R1))/(A2*(RI-RIS)+B2*(ZI-ZIS));
ZIA:=(A2*(ZIS*RI-ZI*RIS)+C2*(ZIS-ZI))/(B2*(ZI-ZIS)+A2*(RI-RIS));
WRITELN('RIA=',RIA:8:4,' ZIA=',ZIA:8:4);
WRITELN(FI,'RIA=',RIA:8:4,' ZIA=',ZIA:8:4);
END;
WRITELN('RI=',RI:8:4,' ZI=',ZI:8:4);
WRITELN;
WRITELN(FI,'RI=',RI:8:4,' ZI=',ZI:8:4);
GOTO 500;
END
ELSE
BEGIN
GOTO 400;
END;(OF OF SECOND IF LOOP)
END
ELSE
BEGIN
GOTO 400;
END;(OF FIRST IF LOOP)
400: WRITE('DO YOU WANT TO CALCULATE MORE EQUIPOTENTIAL SURFACE');
WRITELN('IF YES THEN WRITE -1- ELSE WRITE-0-');
WRITE(FI,'DO YOU WANT TO CALCULATE MORE EQUIPOTENTIAL SURFACE');
WRITELN(FI,'IF YES THEN WRITE -1- ELSE WRITE-0-');
READLN(ANS);
WRITELN(FI,ANS);
IF ANS=1 THEN
GOTO 200
ELSE
GOTO 300;
END
ELSE
BEGIN
GOTO 300
END;
=====
writein(fi,' calculation of tangential field component');
300: WRITELN('DO YOU WANT TO CALCULATE THE TANGENTIAL FIELD COMPONENTS');
WRITELN('IF YES THEN WRITE 1 ELSE WRITE 0');
WRITELN(FI,'DO YOU WANT TO CALCULATE THE TANGENTIAL FIELD COMPONENTS');
WRITELN(FI,'IF YES THEN WRITE 1 ELSE WRITE 0');

READLN(ANS2);

```

```

        WRITELN(FI,ANS3);
        WRITELN(ANS3);
IF ANS3=1 THEN
BEGIN
WRITELN(FI,'GIVE THE NUMBER OF SUCH POINTS');
WRITELN('GIVE THE NUMBER OF SUCH POINTS');
READLN(FJ,NOM);
WRITELN(FI,NOM);
WRITELN(NOM);
WRITELN(FI,'GIVE THE LOCATION AND SLOPE OF NORMAL AT SUCH POINTS ');
WRITELN('GIVE THE LOCATION AND SLOPE OF NORMAL AT SUCH POINTS ');
FOR MM:=1 TO NOM DO
BEGIN
FOR OO:=1 TO 3 DO
BEGIN
READ(FJ,HHOEMM,OO);
WRITE(FI,HHOEMM,OO:8:4,' ');
END;
WRITELN(FI);
READLN(FJ);
END;
{-----}
FOR MM:=1 TO NOM DO
BEGIN
CSOEMM,1:=ABS(COS(ARCTAN(HHOEMM,3)));
CSOEMM,2:=ABS(SIN(ARCTAN(HHOEMM,3)));
END;
{-----}
WRITELN('TANGENTIAL FIELD VECTOR IS');
WRITELN(FI,'TANGENTIAL FIELD VECTOR IS');
FOR LO:=1 TO NOM DO
BEGIN
TANEOLO:=0.0;
FOR PO:=1 TO NE DO
BEGIN
TANEOLO:=TANEOLO+ CO*CHARGEEOLO,1)*FH(RZ,HH,CS,PO,LO);
END;
FOR PO:=(NE+1) TO EB DO
BEGIN
TANEOLO:=TANEOLO+CO*CHARGEEOLO,1)*FH(RZ,HH,CS,PO,LO)
END;
WRITELN(FI,TANEOLO:12:6);
WRITE(HHEOLO,1:8:3,TANEOLO:12:6);
WRITELN;
END;
END
ELSE
BEGIN
GOTO 600
END;
{-----}
600:WRITELN(FI,'END OF EXECUTION ');
close(fi);
close(fj);
END.

```

INPUT FILE = DAT.PRN

1.35
1.3
1.25
105 0.09
105 0.01
09 0.11
0 0.11
09 0.11
105 0.09
105 0.01
095 0.09
095 0.01
09 0.09
0 0.09
09 0.09
095 0.09
095 0.01

CHARGE LOCATIONS INSIDE THE ELECTRODE

CHARGE LOCATIONS INSIDE THE AIR

CHARGE LOCATIONS IN THE DIELECTRIC

Number of Points on the electrode-Air interface (Contour points)

Location of Contour Points on the electrode-Air interface.

Number of Points on the Air-Dielectric interface where tangential components of Electric field is desired.

Location of Points on the Air-Dielectric interface where $E_{\text{tangential}}$ is desired

0.1 1E10
01 0.1 1E10
02 0.1 1E10
03 0.1 1E10
04 0.1 1E10
05 0.1 1E10
06 0.1 1E10
07 0.1 1E10
08 0.1 1E10
09 0.1 1E10

GIVE THE LOCATION OF SIMULATION CHARGES INSIDE THE ELECTRODE

0.0000 0.3500
0.0000 0.3000
0.0000 0.2500

GIVE THE LOCATION OF SIMULATION CHARGES INSIDE THE AIR

-0.1050 0.0900
-0.1050 0.0100
-0.0900 0.1100
0.0000 0.1100
0.0900 0.1100
0.1050 0.0900
0.1050 0.0100

GIVE THE LOCATION OF SIMULATION CHARGES INSIDE THE DIELECTRIC

-0.0950 0.0900
-0.0950 0.0100
-0.0900 0.0900
0.0000 0.0900
0.0900 0.0900
0.0950 0.0900
0.0950 0.0100

GIVE THE NUMBER OF CONTOUR POINTS ON THE AIR-E INTERFACE

5

GIVE THE LOCATION OF ABOVE CONTOUR POINTS

0.0000 0.4000
0.1000 0.3000
0.0000 0.2000

CONTOUR POINTS ON THE AIR-D INTERFACE ARE

-0.1000 0.0900
-0.1000 0.0100
-0.0900 0.1000
0.0000 0.1000
0.0900 0.1000
0.1000 0.0900
0.1000 0.0100

GIVE THE RELATIVE PERMEABILITY OF D

6.0000

CHARGE VECTOR IS

-1.2E-15
1.1E-11
1.5E-14
9.4E-16
6.4E-16
-1.5E-14
-2.0E-14
-1.5E-14
9.4E-16
6.4E-16
8.7E-15
8.7E-16
-2.2E-14
-2.0E-14
-2.2E-14
8.7E-15
8.7E-16

do you want to calculate the error. if yes then write 1 else write 0

1

GIVE THE NUMBER OF SUCH TEST POINTS ON THE AIR-E INTERFACE

GIVE THE LOCATION OF SUCH POINTS

0.0000 0.4000

```

0.0701 0.3701
0.1000 0.3000
0.0701 0.2299
0.0000 0.2000
GIVE THE NUMBER OF TEST POINTS ON THE D-E INTERFACE
THE ERROR VECTOR IS
-0.0000
0.0088
-0.0000
0.0088
-0.0000
CUMMULATIVE SQUARE ERROR IS
0.0002
END OF ERROR CALCULATION
DO YOU WANT TO CALCULATE THE EQUIPOTENTIAL SURFACE. IF YES THEN
WRITE 1 ELSE WRITE 0
1
calculating the equipotential surface
GIVE THE INITIAL POINT OF THE DESIRED EQUIPOTENTIAL SURFACE
0.0000 0.0200
GIVE THE EXTENSION POINT OF THE EQUIPOTENTIAL SURFACE
0.0000 0.0200
GIVE THE CONSTANTS OF THE FIRST BOUNDARY LINE : $ax+by+c=0$  SUCH THAT THE
STARTING POINT FALLS IN THE REGION: $ax+by+c \leq 0$ 
A= 1.0000
B= 0.0000
C= -0.1000
GIVE THE CONSTANTS OF THE SECOND BOUNDARY LINE: $ax+by+c=0$  SUCH THAT THE
STARTING POINT FALLS IN THE REGION: $ax+by+c \leq 0$ 
A= 0.0000
B= 1.0000
C= -0.1000
GIVE THE RELATIVE PERMEABILITY OF THE INITIAL POINT
6.0000
GIVE THE LENGTH OF INFINITSIMAL ELEMENT ALONG THE EQUIPOTENTIAL SURFACE
0.0020
R1= 0.0020 Z1= 0.0200
R1= 0.0040 Z1= 0.0200
R1= 0.0060 Z1= 0.0200
R1= 0.0080 Z1= 0.0201
R1= 0.0100 Z1= 0.0201
R1= 0.0120 Z1= 0.0203
R1= 0.0140 Z1= 0.0203
R1= 0.0160 Z1= 0.0204
R1= 0.0180 Z1= 0.0205
R1= 0.0200 Z1= 0.0206
R1= 0.0220 Z1= 0.0208
R1= 0.0240 Z1= 0.0209
R1= 0.0260 Z1= 0.0211
R1= 0.0280 Z1= 0.0213
R1= 0.0300 Z1= 0.0215
R1= 0.0319 Z1= 0.0217
R1= 0.0339 Z1= 0.0219
R1= 0.0359 Z1= 0.0221
R1= 0.0379 Z1= 0.0224
R1= 0.0399 Z1= 0.0227
R1= 0.0419 Z1= 0.0229
R1= 0.0438 Z1= 0.0233
R1= 0.0458 Z1= 0.0235
R1= 0.0478 Z1= 0.0239
R1= 0.0498 Z1= 0.0243
R1= 0.0517 Z1= 0.0246

```

RI= 0.0537 ZI= 0.0249
 RI= 0.0557 ZI= 0.0253
 RI= 0.0576 ZI= 0.0257
 RI= 0.0596 ZI= 0.0261
 RI= 0.0615 ZI= 0.0265
 RI= 0.0635 ZI= 0.0269
 RI= 0.0654 ZI= 0.0274
 RI= 0.0674 ZI= 0.0279
 RI= 0.0693 ZI= 0.0283
 RI= 0.0713 ZI= 0.0288
 RI= 0.0732 ZI= 0.0293
 RI= 0.0751 ZI= 0.0298
 RI= 0.0771 ZI= 0.0304
 RI= 0.0790 ZI= 0.0309
 RI= 0.0809 ZI= 0.0315
 RI= 0.0828 ZI= 0.0320
 RI= 0.0847 ZI= 0.0326
 RI= 0.0866 ZI= 0.0332
 RI= 0.0886 ZI= 0.0338
 RI= 0.0905 ZI= 0.0344
 RI= 0.0923 ZI= 0.0351
 RI= 0.0942 ZI= 0.0357
 RI= 0.0961 ZI= 0.0364
 RI= 0.0980 ZI= 0.0371
 RI= 0.0999 ZI= 0.0378
 RIA= 0.1000 ZIA= 0.0378
 RI= 0.1018 ZI= 0.0385

DO YOU WANT TO CALCULATE MORE EQUIPOTENTIAL SURFACE IF YES THEN WRITE -1- ELSE WRITE -0-
1

GIVE THE INITIAL POINT OF THE DESIRED EQUIPOTENTIAL SURFACE

0.0999 0.0378

GIVE THE EXTENSION POINT OF THE EQUIPOTENTIAL SURFACE

0.1000 0.0378

GIVE THE CONSTANTS OF THE FIRST BOUNDARY LINE : $ax+by+c=0$ SUCH THAT THE STARTING POINT FALLS IN THE REGION: $ax+by+c \leq 0$

A= 1.0000

B= 0.0000

C= -0.2000

GIVE THE CONSTANTS OF THE SECOND BOUNDARY LINE: $ax+by+c=0$ SUCH THAT THE STARTING POINT FALLS IN THE REGION: $ax+by+c \leq 0$

A= 0.0000

B= 1.0000

C= -0.3000

GIVE THE RELATIVE PERMEABILITY OF THE INITIAL POINT

1.0000

GIVE THE LENGTH OF INFINITSIMAL ELEMENT ALONG THE EQUIPOTENTIAL SURFACE

0.0020

RI= 0.1019 ZI= 0.0385
 RI= 0.1037 ZI= 0.0392
 RI= 0.1056 ZI= 0.0400
 RI= 0.1075 ZI= 0.0407
 RI= 0.1093 ZI= 0.0415
 RI= 0.1112 ZI= 0.0422
 RI= 0.1130 ZI= 0.0430
 RI= 0.1148 ZI= 0.0438
 RI= 0.1167 ZI= 0.0446
 RI= 0.1185 ZI= 0.0454
 RI= 0.1203 ZI= 0.0462
 RI= 0.1221 ZI= 0.0471
 RI= 0.1239 ZI= 0.0479
 RI= 0.1257 ZI= 0.0486
 RI= 0.1276 ZI= 0.0496

RI= 0.1293 ZI= 0.0505
 RI= 0.1311 ZI= 0.0514
 RI= 0.1329 ZI= 0.0523
 RI= 0.1347 ZI= 0.0532
 RI= 0.1365 ZI= 0.0542
 RI= 0.1382 ZI= 0.0551
 RI= 0.1400 ZI= 0.0561
 RI= 0.1417 ZI= 0.0570
 RI= 0.1435 ZI= 0.0580
 RI= 0.1452 ZI= 0.0590
 RI= 0.1469 ZI= 0.0600
 RI= 0.1487 ZI= 0.0610
 RI= 0.1504 ZI= 0.0621
 RI= 0.1521 ZI= 0.0631
 RI= 0.1538 ZI= 0.0642
 RI= 0.1555 ZI= 0.0652
 RI= 0.1572 ZI= 0.0663
 RI= 0.1588 ZI= 0.0674
 RI= 0.1605 ZI= 0.0685
 RI= 0.1622 ZI= 0.0696
 RI= 0.1638 ZI= 0.0707
 RI= 0.1655 ZI= 0.0719
 RI= 0.1671 ZI= 0.0730
 RI= 0.1687 ZI= 0.0742
 RI= 0.1703 ZI= 0.0754
 RI= 0.1720 ZI= 0.0766
 RI= 0.1736 ZI= 0.0778
 RI= 0.1751 ZI= 0.0790
 RI= 0.1767 ZI= 0.0802
 RI= 0.1783 ZI= 0.0814
 RI= 0.1799 ZI= 0.0827
 RI= 0.1814 ZI= 0.0839
 RI= 0.1830 ZI= 0.0852
 RI= 0.1845 ZI= 0.0865
 RI= 0.1860 ZI= 0.0878
 RI= 0.1875 ZI= 0.0891
 RI= 0.1891 ZI= 0.0904
 RI= 0.1906 ZI= 0.0917
 RI= 0.1920 ZI= 0.0931
 RI= 0.1935 ZI= 0.0944
 RI= 0.1950 ZI= 0.0958
 RI= 0.1965 ZI= 0.0971
 RI= 0.1979 ZI= 0.0985
 RI= 0.1993 ZI= 0.0999
 RIA= 0.2000 ZIA= 0.1005

RI= 0.2008 ZI= 0.1013

DO YOU WANT TO CALCULATE MORE EQUIPOTENTIAL SURFACE IF YES THEN WRITE -1- ELSE WRITE 0-

1
GIVE THE INITIAL POINT OF THE DESIRED EQUIPOTENTIAL SURFACE

0.0000 0.0400

GIVE THE EXTENSION POINT OF THE EQUIPOTENTIAL SURFACE

0.0000 0.0400

GIVE THE CONSTANTS OF THE FIRST BOUNDARY LINE: $ax+by+c=0$ SUCH THAT THE STARTING POINT FALLS IN THE REGION: $ax+by+c \leq 0$

A= 1.0000

B= 0.0000

C= -0.1000

GIVE THE CONSTANTS OF THE SECOND BOUNDARY LINE: $ax+by+c=0$ SUCH THAT THE STARTING POINT FALLS IN THE REGION: $ax+by+c \leq 0$

A= 0.0000

B= 1.0000

C= -0.1000

GIVE THE RELATIVE PERMEABILITY OF THE INITIAL POINT

6.0000

GIVE THE LENGTH OF INFINITSIMAL ELEMENT ALONG THE EQUIPOTENTIAL SURFACE

0.0020

RI= 0.0020 ZI= 0.0400

RI= 0.0040 ZI= 0.0400

RI= 0.0060 ZI= 0.0400

RI= 0.0080 ZI= 0.0401

RI= 0.0100 ZI= 0.0401

RI= 0.0120 ZI= 0.0402

RI= 0.0140 ZI= 0.0403

RI= 0.0160 ZI= 0.0404

RI= 0.0180 ZI= 0.0405

RI= 0.0200 ZI= 0.0407

RI= 0.0220 ZI= 0.0408

RI= 0.0240 ZI= 0.0410

RI= 0.0260 ZI= 0.0412

RI= 0.0280 ZI= 0.0414

RI= 0.0299 ZI= 0.0416

RI= 0.0319 ZI= 0.0418

RI= 0.0339 ZI= 0.0420

RI= 0.0359 ZI= 0.0423

RI= 0.0379 ZI= 0.0426

RI= 0.0399 ZI= 0.0428

RI= 0.0418 ZI= 0.0431

RI= 0.0438 ZI= 0.0435

RI= 0.0458 ZI= 0.0438

RI= 0.0478 ZI= 0.0441

RI= 0.0497 ZI= 0.0445

RI= 0.0517 ZI= 0.0449

RI= 0.0536 ZI= 0.0453

RI= 0.0556 ZI= 0.0457

RI= 0.0576 ZI= 0.0461

RI= 0.0595 ZI= 0.0465

RI= 0.0615 ZI= 0.0470

RI= 0.0634 ZI= 0.0475

RI= 0.0653 ZI= 0.0480

RI= 0.0673 ZI= 0.0485

RI= 0.0692 ZI= 0.0490

RI= 0.0711 ZI= 0.0495

RI= 0.0731 ZI= 0.0501

RI= 0.0750 ZI= 0.0506

RI= 0.0769 ZI= 0.0512

RI= 0.0788 ZI= 0.0518

RI= 0.0807 ZI= 0.0524

RI= 0.0826 ZI= 0.0530

RI= 0.0845 ZI= 0.0536

RI= 0.0864 ZI= 0.0543

RI= 0.0883 ZI= 0.0550

RI= 0.0902 ZI= 0.0556

RI= 0.0920 ZI= 0.0563

RI= 0.0939 ZI= 0.0570

RI= 0.0958 ZI= 0.0577

RI= 0.0976 ZI= 0.0585

RI= 0.0995 ZI= 0.0592

RIA= 0.1000 ZIA= 0.0594

RI= 0.1014 ZI= 0.0600

DO YOU WANT TO CALCULATE MORE EQUIPOTENTIAL SURFACE? IF YES THEN WRITE -1- ELSE WRITE -0-

1

GIVE THE INITIAL POINT OF THE DESIRED EQUIPOTENTIAL SURFACE

0.0995 0.0592

GIVE THE EXTENSION POINT OF THE EQUIPOTENTIAL SURFACE

0.1000 0.0594
 GIVE THE CONSTANTS OF THE FIRST BOUNDARY LINE : $ax+by+c=0$ SUCH THAT THE
 STARTING POINT FALLS IN THE REGION: $ax+by+c \leq 0$
 A= 1.0000
 B= 0.0000
 C= -0.2000
 GIVE THE CONSTANTS OF THE SECOND BOUNDARY LINE: $ax+by+c=0$ SUCH THAT THE
 STARTING POINT FALLS IN THE REGION: $ax+by+c \leq 0$
 A= 0.0000
 B= 1.0000
 C= -0.3000
 GIVE THE RELATIVE PERMEABILITY OF THE INITIAL POINT
 1.0000
 GIVE THE LENGTH OF INFINITSIMAL ELEMENT ALONG THE EQUIPOTENTIAL SURFACE
 0.0020

RI=	0.1019	ZI=	0.0801
RI=	0.1037	ZI=	0.0809
RI=	0.1056	ZI=	0.0817
RI=	0.1074	ZI=	0.0824
RI=	0.1093	ZI=	0.0832
RI=	0.1111	ZI=	0.0840
RI=	0.1129	ZI=	0.0848
RI=	0.1148	ZI=	0.0856
RI=	0.1166	ZI=	0.0864
RI=	0.1184	ZI=	0.0872
RI=	0.1202	ZI=	0.0881
RI=	0.1220	ZI=	0.0889
RI=	0.1238	ZI=	0.0898
RI=	0.1256	ZI=	0.0907
RI=	0.1274	ZI=	0.0916
RI=	0.1292	ZI=	0.0925
RI=	0.1309	ZI=	0.0934
RI=	0.1327	ZI=	0.0944
RI=	0.1345	ZI=	0.0954
RI=	0.1362	ZI=	0.0963
RI=	0.1379	ZI=	0.0973
RI=	0.1397	ZI=	0.0983
RI=	0.1414	ZI=	0.0994
RI=	0.1431	ZI=	0.0804
RI=	0.1448	ZI=	0.0814
RI=	0.1465	ZI=	0.0825
RI=	0.1482	ZI=	0.0836
RI=	0.1498	ZI=	0.0847
RI=	0.1515	ZI=	0.0858
RI=	0.1532	ZI=	0.0869
RI=	0.1548	ZI=	0.0881
RI=	0.1564	ZI=	0.0892
RI=	0.1581	ZI=	0.0904
RI=	0.1597	ZI=	0.0915
RI=	0.1613	ZI=	0.0927
RI=	0.1629	ZI=	0.0939
RI=	0.1645	ZI=	0.0952
RI=	0.1661	ZI=	0.0964
RI=	0.1676	ZI=	0.0976
RI=	0.1692	ZI=	0.0989
RI=	0.1707	ZI=	0.1001
RI=	0.1723	ZI=	0.1014
RI=	0.1738	ZI=	0.1027
RI=	0.1753	ZI=	0.1040
RI=	0.1768	ZI=	0.1053
RI=	0.1783	ZI=	0.1067
RI=	0.1798	ZI=	0.1080

RI= 0.1813 ZI= 0.1093
RI= 0.1827 ZI= 0.1107
RI= 0.1842 ZI= 0.1121
RI= 0.1856 ZI= 0.1135
RI= 0.1871 ZI= 0.1149
RI= 0.1885 ZI= 0.1163
RI= 0.1899 ZI= 0.1177
RI= 0.1913 ZI= 0.1191
RI= 0.1927 ZI= 0.1206
RI= 0.1941 ZI= 0.1220
RI= 0.1954 ZI= 0.1235
RI= 0.1968 ZI= 0.1250
RI= 0.1981 ZI= 0.1264
RI= 0.1995 ZI= 0.1279
RIA= 0.2000 ZIA= 0.1288
RI= 0.2008 ZI= 0.1294

DO YOU WANT TO CALCULATE MORE EQUIPOTENTIAL SURFACE IF YES THEN WRITE -1- ELSE WRITE -0-
1

GIVE THE INITIAL POINT OF THE DESIRED EQUIPOTENTIAL SURFACE

0.0000 0.0600

GIVE THE EXTENSION POINT OF THE EQUIPOTENTIAL SURFACE

#0.0000 0.0600

GIVE THE CONSTANTS OF THE FIRST BOUNDARY LINE : $ax+by+c=0$ SUCH THAT THE
STARTING POINT FALLS IN THE REGION: $ax+by+c \leq 0$

A= 1.0000

B= 0.0000

C= -0.1000

GIVE THE CONSTANTS OF THE SECOND BOUNDARY LINE: $ax+by+c=0$ SUCH THAT THE
STARTING POINT FALLS IN THE REGION: $ax+by+c \leq 0$

A= 0.0000

B= 1.0000

C= -0.1000

GIVE THE RELATIVE PERMEABILITY OF THE INITIAL POINT

6.0000

GIVE THE LENGTH OF INFINITSIMAL ELEMENT ALONG THE EQUIPOTENTIAL SURFACE

0.0020

RI= 0.0020 ZI= 0.0600

RI= 0.0040 ZI= 0.0600

RI= 0.0060 ZI= 0.0600

RI= 0.0080 ZI= 0.0601

RI= 0.0100 ZI= 0.0601

RI= 0.0120 ZI= 0.0602

RI= 0.0140 ZI= 0.0603

RI= 0.0160 ZI= 0.0604

RI= 0.0180 ZI= 0.0605

RI= 0.0200 ZI= 0.0607

RI= 0.0220 ZI= 0.0608

RI= 0.0240 ZI= 0.0610

RI= 0.0260 ZI= 0.0612

RI= 0.0280 ZI= 0.0614

RI= 0.0299 ZI= 0.0616

RI= 0.0319 ZI= 0.0618

RI= 0.0339 ZI= 0.0621

RI= 0.0359 ZI= 0.0624

RI= 0.0379 ZI= 0.0626

RI= 0.0398 ZI= 0.0629

RI= 0.0418 ZI= 0.0633

RI= 0.0438 ZI= 0.0636

RI= 0.0458 ZI= 0.0640

RI= 0.0477 ZI= 0.0643

RI= 0.0497 ZI= 0.0647

RI= 0.0516 ZI= 0.0651

RI= 0.0536 ZI= 0.0656

RI= 0.0555 ZI= 0.0660

RI= 0.0575 ZI= 0.0665

RI= 0.0594 ZI= 0.0670

RI= 0.0614 ZI= 0.0675

RI= 0.0633 ZI= 0.0680

RI= 0.0652 ZI= 0.0685

RI= 0.0671 ZI= 0.0691

RI= 0.0691 ZI= 0.0697

RI= 0.0710 ZI= 0.0703

RI= 0.0729 ZI= 0.0709

RI= 0.0748 ZI= 0.0715

RI= 0.0767 ZI= 0.0722

RI= 0.0786 ZI= 0.0728

RI= 0.0804 ZI= 0.0735

RI= 0.0823 ZI= 0.0743

RI= 0.0842 ZI= 0.0749
 RI= 0.0860 ZI= 0.0756
 RI= 0.0879 ZI= 0.0764
 RI= 0.0898 ZI= 0.0771
 RI= 0.0916 ZI= 0.0779
 RI= 0.0935 ZI= 0.0786
 RI= 0.0953 ZI= 0.0794
 RI= 0.0971 ZI= 0.0802
 RI= 0.0990 ZI= 0.0809
 RIA= 0.1000 ZIA= 0.0814
 RI= 0.1008 ZI= 0.0817
 DO YOU WANT TO CALCULATE MORE EQUIPOTENTIAL SURFACE IF YES THEN WRITE -1- ELSE WRITE -0-
 1
 GIVE THE INITIAL POINT OF THE DESIRED EQUIPOTENTIAL SURFACE
 0.0990 0.0809
 GIVE THE EXTENSION POINT OF THE EQUIPOTENTIAL SURFACE
 0.1000 0.0814
 GIVE THE CONSTANTS OF THE FIRST BOUNDARY LINE : $ax+by+c=0$ SUCH THAT THE
 STARTING POINT FALLS IN THE REGION: $ax+by+c \leq 0$
 A= 1.0000
 B= 0.0000
 C= -0.2000
 GIVE THE CONSTANTS OF THE SECOND BOUNDARY LINE: $ax+by+c=0$ SUCH THAT THE
 STARTING POINT FALLS IN THE REGION: $ax+by+c \leq 0$
 A= 0.0000
 B= 1.0000
 C= -0.3000
 GIVE THE RELATIVE PERMEABILITY OF THE INITIAL POINT
 1.0000
 GIVE THE LENGTH OF INFINITSIMAL ELEMENT ALONG THE EQUIPOTENTIAL SURFACE
 0.0020
 RI= 0.1020 ZI= 0.0817
 RI= 0.1039 ZI= 0.0822
 RI= 0.1058 ZI= 0.0827
 RI= 0.1077 ZI= 0.0834
 RI= 0.1096 ZI= 0.0841
 RI= 0.1115 ZI= 0.0848
 RI= 0.1133 ZI= 0.0856
 RI= 0.1151 ZI= 0.0864
 RI= 0.1170 ZI= 0.0872
 RI= 0.1188 ZI= 0.0881
 RI= 0.1206 ZI= 0.0889
 RI= 0.1224 ZI= 0.0898
 RI= 0.1241 ZI= 0.0907
 RI= 0.1259 ZI= 0.0917
 RI= 0.1277 ZI= 0.0926
 RI= 0.1294 ZI= 0.0936
 RI= 0.1311 ZI= 0.0946
 RI= 0.1329 ZI= 0.0956
 RI= 0.1346 ZI= 0.0967
 RI= 0.1363 ZI= 0.0977
 RI= 0.1380 ZI= 0.0988
 RI= 0.1397 ZI= 0.0999
 RI= 0.1413 ZI= 0.1010
 RI= 0.1430 ZI= 0.1021
 RI= 0.1446 ZI= 0.1032
 RI= 0.1463 ZI= 0.1044
 RI= 0.1479 ZI= 0.1055
 RI= 0.1495 ZI= 0.1067
 RI= 0.1511 ZI= 0.1079
 RI= 0.1527 ZI= 0.1091
 RI= 0.1543 ZI= 0.1103

RI= 0.1559 ZI= 0.1115
 RI= 0.1574 ZI= 0.1128
 RI= 0.1590 ZI= 0.1141
 RI= 0.1605 ZI= 0.1153
 RI= 0.1621 ZI= 0.1166
 RI= 0.1636 ZI= 0.1179
 RI= 0.1651 ZI= 0.1192
 RI= 0.1666 ZI= 0.1206
 RI= 0.1681 ZI= 0.1219
 RI= 0.1695 ZI= 0.1233
 RI= 0.1710 ZI= 0.1246
 RI= 0.1724 ZI= 0.1260
 RI= 0.1739 ZI= 0.1274
 RI= 0.1753 ZI= 0.1288
 RI= 0.1767 ZI= 0.1302
 RI= 0.1781 ZI= 0.1317
 RI= 0.1795 ZI= 0.1331
 RI= 0.1809 ZI= 0.1346
 RI= 0.1823 ZI= 0.1360
 RI= 0.1836 ZI= 0.1375
 RI= 0.1849 ZI= 0.1390
 RI= 0.1863 ZI= 0.1405
 RI= 0.1876 ZI= 0.1420
 RI= 0.1889 ZI= 0.1435
 RI= 0.1902 ZI= 0.1450
 RI= 0.1914 ZI= 0.1466
 RI= 0.1927 ZI= 0.1481
 RI= 0.1939 ZI= 0.1497
 RI= 0.1952 ZI= 0.1513
 RI= 0.1964 ZI= 0.1528
 RI= 0.1976 ZI= 0.1544
 RI= 0.1988 ZI= 0.1560
 RI= 0.2000 ZI= 0.1577
 RIA= 0.2000 ZIA= 0.1577
 RI= 0.2012 ZI= 0.1593

DO YOU WANT TO CALCULATE MORE EQUIPOTENTIAL SURFACE IF YES THEN WRITE -1- ELSE WRITE -0-

1
GIVE THE INITIAL POINT OF THE DESIRED EQUIPOTENTIAL SURFACE

0.0000 0.0800

GIVE THE EXTENSION POINT OF THE EQUIPOTENTIAL SURFACE

0.0000 0.0800

GIVE THE CONSTANTS OF THE FIRST BOUNDARY LINE : $ax+by+c=0$ SUCH THAT THE STARTING POINT FALLS IN THE REGION: $ax+by+c \leq 0$

A= 1.0000

B= 0.0000

C= -0.1000

GIVE THE CONSTANTS OF THE SECOND BOUNDARY LINE: $ax+by+c=0$ SUCH THAT THE STARTING POINT FALLS IN THE REGION: $ax+by+c \leq 0$

A= 0.0000

B= 1.0000

C= -0.1000

GIVE THE RELATIVE PERMEABILITY OF THE INITIAL POINT

6.0000

GIVE THE LENGTH OF INFINITSIMAL ELEMENT ALONG THE EQUIPOTENTIAL SURFACE

0.0020

RI= 0.0020 ZI= 0.0800

RI= 0.0040 ZI= 0.0800

RI= 0.0060 ZI= 0.0800

RI= 0.0080 ZI= 0.0800

RI= 0.0100 ZI= 0.0800

RI= 0.0120 ZI= 0.0800

RI= 0.0140 ZI= 0.0800

RI= 0.0160 ZI= 0.0803
 RI= 0.0180 ZI= 0.0803
 RI= 0.0200 ZI= 0.0804
 RI= 0.0220 ZI= 0.0806
 RI= 0.0240 ZI= 0.0807
 RI= 0.0260 ZI= 0.0809
 RI= 0.0280 ZI= 0.0811
 RI= 0.0300 ZI= 0.0813
 RI= 0.0319 ZI= 0.0815
 RI= 0.0339 ZI= 0.0817
 RI= 0.0359 ZI= 0.0820
 RI= 0.0379 ZI= 0.0823
 RI= 0.0399 ZI= 0.0826
 RI= 0.0418 ZI= 0.0830
 RI= 0.0438 ZI= 0.0833
 RI= 0.0458 ZI= 0.0837
 RI= 0.0477 ZI= 0.0841
 RI= 0.0497 ZI= 0.0845
 RI= 0.0516 ZI= 0.0850
 RI= 0.0536 ZI= 0.0855
 RI= 0.0555 ZI= 0.0860
 RI= 0.0574 ZI= 0.0865
 RI= 0.0594 ZI= 0.0870
 RI= 0.0613 ZI= 0.0876
 RI= 0.0632 ZI= 0.0882
 RI= 0.0651 ZI= 0.0888
 RI= 0.0670 ZI= 0.0895
 RI= 0.0688 ZI= 0.0902
 RI= 0.0707 ZI= 0.0909
 RI= 0.0726 ZI= 0.0917
 RI= 0.0744 ZI= 0.0925
 RI= 0.0762 ZI= 0.0933
 RI= 0.0780 ZI= 0.0942
 RI= 0.0798 ZI= 0.0952
 RI= 0.0815 ZI= 0.0962
 RI= 0.0831 ZI= 0.0973
 RI= 0.0847 ZI= 0.0985
 RI= 0.0862 ZI= 0.0999
 RIA= 0.0863 ZIA= 0.1000
 RI= 0.0873 ZI= 0.1015

DO YOU WANT TO CALCULATE MORE EQUIPOTENTIAL SURFACE IF YES THEN WRITE -1- ELSE WRITE -0-
1

GIVE THE INITIAL POINT OF THE DESIRED EQUIPOTENTIAL SURFACE

0.0862 0.0999

GIVE THE EXTENSION POINT OF THE EQUIPOTENTIAL SURFACE

0.0863 0.1000

GIVE THE CONSTANTS OF THE FIRST BOUNDARY LINE $ax+by+c=0$ SUCH THAT THE STARTING POINT FALLS IN THE REGION $ax+by+c \leq 0$

A= 1.0000

B= 0.0000

C= -0.2000

GIVE THE CONSTANTS OF THE SECOND BOUNDARY LINE $ax+by+c=0$ SUCH THAT THE STARTING POINT FALLS IN THE REGION $ax+by+c \leq 0$

A= 0.0000

B= 1.0000

C= -0.3000

GIVE THE RELATIVE PERMEABILITY OF THE INITIAL POINT

0.0000

GIVE THE LENGTH OF INFINITESIMAL ELEMENT ALONG THE EQUIPOTENTIAL SURFACE

0.0020

RI= 0.0852 ZI= 0.1007

RI= 0.0901 ZI= 0.1012

RI=	0.0921	ZI=	0.1016
RI=	0.0941	ZI=	0.1019
RI=	0.0960	ZI=	0.1022
RI=	0.0980	ZI=	0.1026
RI=	0.0999	ZI=	0.1031
RI=	0.1018	ZI=	0.1037
RI=	0.1037	ZI=	0.1043
RI=	0.1056	ZI=	0.1050
RI=	0.1075	ZI=	0.1058
RI=	0.1093	ZI=	0.1066
RI=	0.1111	ZI=	0.1074
RI=	0.1129	ZI=	0.1083
RI=	0.1147	ZI=	0.1092
RI=	0.1165	ZI=	0.1101
RI=	0.1182	ZI=	0.1111
RI=	0.1200	ZI=	0.1121
RI=	0.1217	ZI=	0.1131
RI=	0.1234	ZI=	0.1141
RI=	0.1251	ZI=	0.1152
RI=	0.1268	ZI=	0.1162
RI=	0.1285	ZI=	0.1173
RI=	0.1302	ZI=	0.1184
RI=	0.1318	ZI=	0.1195
RI=	0.1335	ZI=	0.1207
RI=	0.1351	ZI=	0.1218
RI=	0.1367	ZI=	0.1230
RI=	0.1383	ZI=	0.1242
RI=	0.1399	ZI=	0.1254
RI=	0.1415	ZI=	0.1266
RI=	0.1431	ZI=	0.1278
RI=	0.1446	ZI=	0.1291
RI=	0.1462	ZI=	0.1304
RI=	0.1477	ZI=	0.1316
RI=	0.1492	ZI=	0.1329
RI=	0.1507	ZI=	0.1343
RI=	0.1522	ZI=	0.1356
RI=	0.1537	ZI=	0.1369
RI=	0.1552	ZI=	0.1383
RI=	0.1567	ZI=	0.1396
RI=	0.1581	ZI=	0.1410
RI=	0.1595	ZI=	0.1424
RI=	0.1610	ZI=	0.1438
RI=	0.1624	ZI=	0.1452
RI=	0.1638	ZI=	0.1467
RI=	0.1651	ZI=	0.1481
RI=	0.1665	ZI=	0.1496
RI=	0.1679	ZI=	0.1511
RI=	0.1692	ZI=	0.1525
RI=	0.1705	ZI=	0.1540
RI=	0.1718	ZI=	0.1555
RI=	0.1731	ZI=	0.1571
RI=	0.1744	ZI=	0.1586
RI=	0.1757	ZI=	0.1601
RI=	0.1769	ZI=	0.1617
RI=	0.1782	ZI=	0.1633
RI=	0.1794	ZI=	0.1648
RI=	0.1805	ZI=	0.1664
RI=	0.1816	ZI=	0.1680
RI=	0.1828	ZI=	0.1697
RI=	0.1842	ZI=	0.1713
RI=	0.1853	ZI=	0.1729
RI=	0.1865	ZI=	0.1745

RI= 0.1876 ZI= 0.1762
RI= 0.1887 ZI= 0.1779
RI= 0.1898 ZI= 0.1795
RI= 0.1909 ZI= 0.1812
RI= 0.1920 ZI= 0.1829
RI= 0.1930 ZI= 0.1846
RI= 0.1940 ZI= 0.1863
RI= 0.1951 ZI= 0.1881
RI= 0.1961 ZI= 0.1898
RI= 0.1970 ZI= 0.1915
RI= 0.1980 ZI= 0.1933
RI= 0.1990 ZI= 0.1950
RI= 0.1999 ZI= 0.1968
RIA= 0.2000 ZIA= 0.1970
RI= 0.2008 ZI= 0.1986

DO YOU WANT TO CALCULATE MORE EQUIPOTENTIAL SURFACE IF YES THEN WRITE -1- ELSE WRITE-0-
1

GIVE THE INITIAL POINT OF THE DESIRED EQUIPOTENTIAL SURFACE

0.0000 0.0900

GIVE THE EXTENSION POINT OF THE EQUIPOTENTIAL SURFACE

0.0000 0.0900

GIVE THE CONSTANTS OF THE FIRST BOUNDARY LINE : $ax+by+c=0$ SUCH THAT THE
STARTING POINT FALLS IN THE REGION: $ax+by+c \leq 0$

A= 1.0000

B= 0.0000

C= -0.1000

GIVE THE CONSTANTS OF THE SECOND BOUNDARY LINE: $ax+by+c=0$ SUCH THAT THE
STARTING POINT FALLS IN THE REGION: $ax+by+c \leq 0$

A= 0.0000

B= 1.0000

C= -0.1000

GIVE THE RELATIVE PERMEABILITY OF THE INITIAL POINT

6.0000

GIVE THE LENGTH OF INFINITSIMAL ELEMENT ALONG THE EQUIPOTENTIAL SURFACE
0.0020

RI= 0.0020 ZI= 0.0900

RI= 0.0040 ZI= 0.0900

RI= 0.0060 ZI= 0.0899

RI= 0.0080 ZI= 0.0899

RI= 0.0100 ZI= 0.0898

RI= 0.0120 ZI= 0.0898

RI= 0.0140 ZI= 0.0898

RI= 0.0160 ZI= 0.0897

RI= 0.0180 ZI= 0.0898

RI= 0.0200 ZI= 0.0898

RI= 0.0220 ZI= 0.0899

RI= 0.0240 ZI= 0.0900

RI= 0.0260 ZI= 0.0901

RI= 0.0280 ZI= 0.0902

RI= 0.0300 ZI= 0.0904

RI= 0.0320 ZI= 0.0906

RI= 0.0340 ZI= 0.0909

RI= 0.0359 ZI= 0.0911

RI= 0.0379 ZI= 0.0914

RI= 0.0399 ZI= 0.0917

RI= 0.0419 ZI= 0.0921

RI= 0.0438 ZI= 0.0924

RI= 0.0458 ZI= 0.0928

RI= 0.0477 ZI= 0.0933

RI= 0.0497 ZI= 0.0937

RI= 0.0516 ZI= 0.0942

RI= 0.0536 ZI= 0.0947

RI= 0.0555 ZI= 0.0952

RI= 0.0574 ZI= 0.0958

RI= 0.0593 ZI= 0.0964

RI= 0.0612 ZI= 0.0970

RI= 0.0631 ZI= 0.0976

RI= 0.0650 ZI= 0.0983

RI= 0.0669 ZI= 0.0990

RI= 0.0687 ZI= 0.0998

RIA= 0.0698 RIA= 0.1000

RI= 0.0705 ZI= 0.1000

DO YOU WANT TO CALCULATE MORE EQUIPOTENTIAL SURFACE IF YES THEN WRITE -1- ELSE WRITE-0-
1

GIVE THE INITIAL POINT OF THE DESIRED EQUIPOTENTIAL SURFACE

0.0687 0.0998

GIVE THE EXTENSION POINT OF THE EQUIPOTENTIAL SURFACE

0.0692 0.1000

GIVE THE CONSTANTS OF THE FIRST BOUNDARY LINE : $ax+by+c=0$ SUCH THAT THE
STARTING POINT FALLS IN THE REGION: $ax+by+c \leq 0$

A= 1.0000

B= 0.0000

C= -0.2000

GIVE THE CONSTANTS OF THE SECOND BOUNDARY LINE: $ax+by+c=0$ SUCH THAT THE
STARTING POINT FALLS IN THE REGION: $ax+by+c \leq 0$

A= 0.0000

B= 1.0000

C= -0.3000

GIVE THE RELATIVE PERMEABILITY OF THE INITIAL POINT

1.0000

GIVE THE LENGTH OF INFINITSIMAL ELEMENT ALONG THE EQUIPOTENTIAL SURFACE

0.0020

RI= 0.0710 ZI= 0.1008

RI= 0.0729 ZI= 0.1016

RI= 0.0747 ZI= 0.1024

RI= 0.0765 ZI= 0.1032

RI= 0.0784 ZI= 0.1040

RI= 0.0802 ZI= 0.1048

RI= 0.0821 ZI= 0.1055

RI= 0.0839 ZI= 0.1063

RI= 0.0858 ZI= 0.1070

RI= 0.0876 ZI= 0.1077

RI= 0.0895 ZI= 0.1084

RI= 0.0914 ZI= 0.1091

RI= 0.0932 ZI= 0.1098

RI= 0.0951 ZI= 0.1105

RI= 0.0970 ZI= 0.1112

RI= 0.0989 ZI= 0.1120

RI= 0.1007 ZI= 0.1128

RI= 0.1025 ZI= 0.1136

RI= 0.1044 ZI= 0.1144

RI= 0.1062 ZI= 0.1153

RI= 0.1079 ZI= 0.1162

RI= 0.1097 ZI= 0.1171

RI= 0.1115 ZI= 0.1180

RI= 0.1132 ZI= 0.1190

RI= 0.1150 ZI= 0.1200

RI= 0.1167 ZI= 0.1210

RI= 0.1184 ZI= 0.1220

RI= 0.1201 ZI= 0.1231

RI= 0.1218 ZI= 0.1242

RI= 0.1235 ZI= 0.1253

RI= 0.1251 ZI= 0.1264

RI= 0.1268 ZI= 0.1275

RI= 0.1284 ZI= 0.1286

RI= 0.1300 ZI= 0.1298

RI= 0.1317 ZI= 0.1310

RI= 0.1333 ZI= 0.1322

RI= 0.1348 ZI= 0.1334

RI= 0.1364 ZI= 0.1346

RI= 0.1380 ZI= 0.1359

RI= 0.1395 ZI= 0.1372

RI= 0.1410 ZI= 0.1384

RI= 0.1425 ZI= 0.1397

RI= 0.1441 ZI= 0.1410

RI= 0.1456 ZI= 0.1424

RI= 0.1471 ZI= 0.1437

RI= 0.1485 ZI= 0.1451

RI= 0.1500 ZI= 0.1464

RI= 0.1515 ZI= 0.1478
 RI= 0.1529 ZI= 0.1492
 RI= 0.1543 ZI= 0.1506
 RI= 0.1557 ZI= 0.1520
 RI= 0.1571 ZI= 0.1535
 RI= 0.1585 ZI= 0.1549
 RI= 0.1599 ZI= 0.1564
 RI= 0.1612 ZI= 0.1579
 RI= 0.1625 ZI= 0.1593
 RI= 0.1639 ZI= 0.1608
 RI= 0.1652 ZI= 0.1624
 RI= 0.1665 ZI= 0.1639
 RI= 0.1677 ZI= 0.1654
 RI= 0.1690 ZI= 0.1670
 RI= 0.1702 ZI= 0.1685
 RI= 0.1715 ZI= 0.1701
 RI= 0.1727 ZI= 0.1717
 RI= 0.1739 ZI= 0.1733
 RI= 0.1751 ZI= 0.1749
 RI= 0.1763 ZI= 0.1765
 RI= 0.1774 ZI= 0.1782
 RI= 0.1786 ZI= 0.1798
 RI= 0.1797 ZI= 0.1815
 RI= 0.1808 ZI= 0.1831
 RI= 0.1819 ZI= 0.1848
 RI= 0.1830 ZI= 0.1865
 RI= 0.1840 ZI= 0.1882
 RI= 0.1851 ZI= 0.1899
 RI= 0.1861 ZI= 0.1916
 RI= 0.1871 ZI= 0.1933
 RI= 0.1881 ZI= 0.1951
 RI= 0.1891 ZI= 0.1968
 RI= 0.1901 ZI= 0.1985
 RI= 0.1910 ZI= 0.2003
 RI= 0.1919 ZI= 0.2021
 RI= 0.1929 ZI= 0.2039
 RI= 0.1938 ZI= 0.2056
 RI= 0.1946 ZI= 0.2074
 RI= 0.1955 ZI= 0.2092
 RI= 0.1963 ZI= 0.2111
 RI= 0.1972 ZI= 0.2129
 RI= 0.1980 ZI= 0.2147
 RI= 0.1988 ZI= 0.2165
 RI= 0.1996 ZI= 0.2184
 RIA= 0.2000 ZIA= 0.2194
 RI= 0.2003 ZI= 0.2202

DO YOU WANT TO CALCULATE MORE EQUIPOTENTIAL SURFACE IF YES THEN WRITE -1- ELSE WRITE -0-

1
GIVE THE INITIAL POINT OF THE DESIRED EQUIPOTENTIAL SURFACE

0.0000 0.1200

GIVE THE EXTENSION POINT OF THE EQUIPOTENTIAL SURFACE

0.0000 0.1200

GIVE THE CONSTANTS OF THE FIRST BOUNDARY LINE $ax+by+c=0$ SUCH THAT THE STARTING POINT FALLS IN THE REGION $ax+by+c=0$

A= 1.0000

B= 0.0000

C= -0.2000

GIVE THE CONSTANTS OF THE SECOND BOUNDARY LINE $ax+by+c=0$ SUCH THAT THE STARTING POINT FALLS IN THE REGION $ax+by+c=0$

A= 0.0000

B= 1.0000

C= -0.3000

GIVE THE RELATIVE PERMEABILITY OF THE INITIAL POINT

1.0000

GIVE THE LENGTH OF INFINITSIMAL ELEMENT ALONG THE EQUIPOTENTIAL SURFACE

0.0020

RI=	0.0020	ZI=	0.1200
RI=	0.0040	ZI=	0.1200
RI=	0.0060	ZI=	0.1200
RI=	0.0080	ZI=	0.1201
RI=	0.0100	ZI=	0.1201
RI=	0.0120	ZI=	0.1202
RI=	0.0140	ZI=	0.1203
RI=	0.0160	ZI=	0.1204
RI=	0.0180	ZI=	0.1205
RI=	0.0200	ZI=	0.1207
RI=	0.0220	ZI=	0.1209
RI=	0.0240	ZI=	0.1211
RI=	0.0260	ZI=	0.1213
RI=	0.0279	ZI=	0.1215
RI=	0.0299	ZI=	0.1218
RI=	0.0319	ZI=	0.1221
RI=	0.0339	ZI=	0.1224
RI=	0.0358	ZI=	0.1228
RI=	0.0378	ZI=	0.1231
RI=	0.0398	ZI=	0.1235
RI=	0.0417	ZI=	0.1239
RI=	0.0437	ZI=	0.1244
RI=	0.0456	ZI=	0.1248
RI=	0.0476	ZI=	0.1252
RI=	0.0495	ZI=	0.1256
RI=	0.0514	ZI=	0.1264
RI=	0.0534	ZI=	0.1269
RI=	0.0553	ZI=	0.1275
RI=	0.0572	ZI=	0.1281
RI=	0.0591	ZI=	0.1287
RI=	0.0610	ZI=	0.1293
RI=	0.0629	ZI=	0.1300
RI=	0.0647	ZI=	0.1307
RI=	0.0666	ZI=	0.1314
RI=	0.0685	ZI=	0.1321
RI=	0.0703	ZI=	0.1328
RI=	0.0722	ZI=	0.1336
RI=	0.0740	ZI=	0.1344
RI=	0.0759	ZI=	0.1352
RI=	0.0777	ZI=	0.1360
RI=	0.0795	ZI=	0.1368
RI=	0.0813	ZI=	0.1377
RI=	0.0831	ZI=	0.1385
RI=	0.0849	ZI=	0.1394
RI=	0.0867	ZI=	0.1403
RI=	0.0885	ZI=	0.1413
RI=	0.0902	ZI=	0.1422
RI=	0.0920	ZI=	0.1432
RI=	0.0937	ZI=	0.1442
RI=	0.0954	ZI=	0.1452
RI=	0.0972	ZI=	0.1462
RI=	0.0989	ZI=	0.1472
RI=	0.1006	ZI=	0.1483
RI=	0.1022	ZI=	0.1494
RI=	0.1039	ZI=	0.1505
RI=	0.1056	ZI=	0.1516
RI=	0.1072	ZI=	0.1528
RI=	0.1088	ZI=	0.1539

RI=	0.1105	ZI=	0.1551
RI=	0.1121	ZI=	0.1563
RI=	0.1136	ZI=	0.1575
RI=	0.1152	ZI=	0.1587
RI=	0.1168	ZI=	0.1600
RI=	0.1183	ZI=	0.1612
RI=	0.1199	ZI=	0.1625
RI=	0.1214	ZI=	0.1638
RI=	0.1229	ZI=	0.1651
RI=	0.1244	ZI=	0.1665
RI=	0.1259	ZI=	0.1678
RI=	0.1273	ZI=	0.1692
RI=	0.1288	ZI=	0.1706
RI=	0.1302	ZI=	0.1720
RI=	0.1316	ZI=	0.1734
RI=	0.1330	ZI=	0.1748
RI=	0.1344	ZI=	0.1763
RI=	0.1357	ZI=	0.1777
RI=	0.1371	ZI=	0.1792
RI=	0.1384	ZI=	0.1807
RI=	0.1397	ZI=	0.1822
RI=	0.1410	ZI=	0.1837
RI=	0.1423	ZI=	0.1853
RI=	0.1436	ZI=	0.1868
RI=	0.1448	ZI=	0.1884
RI=	0.1460	ZI=	0.1900
RI=	0.1473	ZI=	0.1916
RI=	0.1485	ZI=	0.1932
RI=	0.1496	ZI=	0.1948
RI=	0.1508	ZI=	0.1964
RI=	0.1519	ZI=	0.1981
RI=	0.1530	ZI=	0.1997
RI=	0.1541	ZI=	0.2014
RI=	0.1552	ZI=	0.2031
RI=	0.1563	ZI=	0.2048
RI=	0.1573	ZI=	0.2065
RI=	0.1584	ZI=	0.2082
RI=	0.1594	ZI=	0.2099
RI=	0.1604	ZI=	0.2116
RI=	0.1613	ZI=	0.2134
RI=	0.1623	ZI=	0.2152
RI=	0.1632	ZI=	0.2169
RI=	0.1641	ZI=	0.2187
RI=	0.1650	ZI=	0.2205
RI=	0.1659	ZI=	0.2223
RI=	0.1668	ZI=	0.2241
RI=	0.1676	ZI=	0.2259
RI=	0.1684	ZI=	0.2277
RI=	0.1692	ZI=	0.2296
RI=	0.1700	ZI=	0.2314
RI=	0.1707	ZI=	0.2332
RI=	0.1715	ZI=	0.2351
RI=	0.1722	ZI=	0.2370
RI=	0.1729	ZI=	0.2389
RI=	0.1735	ZI=	0.2408
RI=	0.1742	ZI=	0.2427
RI=	0.1749	ZI=	0.2446
RI=	0.1754	ZI=	0.2465
RI=	0.1760	ZI=	0.2484
RI=	0.1765	ZI=	0.2503
RI=	0.1771	ZI=	0.2522
RI=	0.1778	ZI=	0.2541

RI= 0.1781 ZI= 0.2561
 RI= 0.1786 ZI= 0.2580
 RI= 0.1791 ZI= 0.2600
 RI= 0.1795 ZI= 0.2619
 RI= 0.1799 ZI= 0.2639
 RI= 0.1803 ZI= 0.2658
 RI= 0.1807 ZI= 0.2678
 RI= 0.1811 ZI= 0.2698
 RI= 0.1814 ZI= 0.2717
 RI= 0.1817 ZI= 0.2737
 RI= 0.1820 ZI= 0.2757
 RI= 0.1823 ZI= 0.2777
 RI= 0.1825 ZI= 0.2797
 RI= 0.1827 ZI= 0.2817
 RI= 0.1829 ZI= 0.2836
 RI= 0.1831 ZI= 0.2856
 RI= 0.1833 ZI= 0.2876
 RI= 0.1834 ZI= 0.2896
 RI= 0.1835 ZI= 0.2916
 RI= 0.1836 ZI= 0.2936
 RI= 0.1837 ZI= 0.2956
 RI= 0.1838 ZI= 0.2976
 RI= 0.1838 ZI= 0.2996
 RIA= 0.1838 ZIA= 0.3000
 RI= 0.1838 ZI= 0.3016

DO YOU WANT TO CALCULATE THE EQUIPOTENTIAL SURFACE. IF YES THEN
WRITE 1 ELSE WRITE 0

1
 calculating the equipotential surface
 GIVE THE INITIAL POINT OF THE DESIRED EQUIPOTENTIAL SURFACE
 0.0000 0.1400
 GIVE THE EXTENTION POINT OF THE EQUIPOTENTIAL SURFACE
 0.0000 0.1400

GIVE THE CONSTANTS OF THE FIRST BOUNDARY LINE : $ax+by+c=0$ SUCH THAT THE
STARTING POINT FALLS IN THE REGION: $ax+by+c \leq 0$

A= 1.0000
 B= 0.0000
 C= -0.2000

GIVE THE CONSTANTS OF THE SECOND BOUNDARY LINE: $ax+by+c=0$ SUCH THAT THE
STARTING POINT FALLS IN THE REGION: $ax+by+c \leq 0$

A= 0.0000
 B= 1.0000
 C= -0.3000

GIVE THE RELATIVE PERMEABILITY OF THE INITIAL POINT
1.0000

GIVE THE LENGTH OF INFINITSIMAL ELEMENT ALONG THE EQUIPOTENTIAL SURFACE
0.0030

RI= 0.0030 ZI= 0.1400
 RI= 0.0060 ZI= 0.1401
 RI= 0.0090 ZI= 0.1402
 RI= 0.0120 ZI= 0.1403
 RI= 0.0150 ZI= 0.1405
 RI= 0.0180 ZI= 0.1408
 RI= 0.0210 ZI= 0.1411
 RI= 0.0239 ZI= 0.1415
 RI= 0.0269 ZI= 0.1419
 RI= 0.0299 ZI= 0.1424
 RI= 0.0328 ZI= 0.1429
 RI= 0.0358 ZI= 0.1435
 RI= 0.0387 ZI= 0.1442
 RI= 0.0416 ZI= 0.1449
 RI= 0.0445 ZI= 0.1456

RI=	0.0474	ZI=	0.1460
RI=	0.0500	ZI=	0.1473
RI=	0.0531	ZI=	0.1488
RI=	0.0560	ZI=	0.1498
RI=	0.0588	ZI=	0.1508
RI=	0.0618	ZI=	0.1518
RI=	0.0644	ZI=	0.1528
RI=	0.0671	ZI=	0.1538
RI=	0.0698	ZI=	0.1548
RI=	0.0726	ZI=	0.1562
RI=	0.0752	ZI=	0.1575
RI=	0.0779	ZI=	0.1589
RI=	0.0805	ZI=	0.1603
RI=	0.0832	ZI=	0.1618
RI=	0.0857	ZI=	0.1633
RI=	0.0883	ZI=	0.1649
RI=	0.0908	ZI=	0.1665
RI=	0.0933	ZI=	0.1682
RI=	0.0958	ZI=	0.1699
RI=	0.0982	ZI=	0.1717
RI=	0.1006	ZI=	0.1735
RI=	0.1029	ZI=	0.1753
RI=	0.1053	ZI=	0.1772
RI=	0.1076	ZI=	0.1792

RI= 0.1098 ZI= 0.1811
 RI= 0.1120 ZI= 0.1832
 RI= 0.1142 ZI= 0.1852
 RI= 0.1163 ZI= 0.1873
 RI= 0.1184 ZI= 0.1895
 RI= 0.1205 ZI= 0.1917
 RI= 0.1225 ZI= 0.1939
 RI= 0.1245 ZI= 0.1961
 RI= 0.1264 ZI= 0.1984
 RI= 0.1283 ZI= 0.2008
 RI= 0.1301 ZI= 0.2031
 RI= 0.1319 ZI= 0.2055
 RI= 0.1337 ZI= 0.2080
 RI= 0.1354 ZI= 0.2104
 RI= 0.1371 ZI= 0.2129
 RI= 0.1387 ZI= 0.2155
 RI= 0.1402 ZI= 0.2180
 RI= 0.1418 ZI= 0.2206
 RI= 0.1432 ZI= 0.2232
 RI= 0.1447 ZI= 0.2259
 RI= 0.1460 ZI= 0.2285
 RI= 0.1474 ZI= 0.2312
 RI= 0.1486 ZI= 0.2339
 RI= 0.1499 ZI= 0.2367
 RI= 0.1510 ZI= 0.2394
 RI= 0.1522 ZI= 0.2422
 RI= 0.1532 ZI= 0.2450
 RI= 0.1542 ZI= 0.2478
 RI= 0.1552 ZI= 0.2507
 RI= 0.1561 ZI= 0.2535
 RI= 0.1570 ZI= 0.2564
 RI= 0.1578 ZI= 0.2593
 RI= 0.1585 ZI= 0.2622
 RI= 0.1592 ZI= 0.2651
 RI= 0.1599 ZI= 0.2681
 RI= 0.1605 ZI= 0.2710
 RI= 0.1610 ZI= 0.2739
 RI= 0.1615 ZI= 0.2769
 RI= 0.1619 ZI= 0.2799
 RI= 0.1623 ZI= 0.2829
 RI= 0.1626 ZI= 0.2858
 RI= 0.1629 ZI= 0.2888
 RI= 0.1631 ZI= 0.2918
 RI= 0.1632 ZI= 0.2948
 RI= 0.1633 ZI= 0.2978
 RIA= 0.1634 ZIA= 0.3000
 RI= 0.1634 ZI= 0.3008

DO YOU WANT TO CALCULATE MORE EQUIPOTENTIAL SURFACE IF YES THEN WRITE -1- ELSE WRITE 0-1

GIVE THE INITIAL POINT OF THE DESIRED EQUIPOTENTIAL SURFACE.

0.0000 0.1600

GIVE THE EXTENTION POINT OF THE EQUIPOTENTIAL SURFACE

0.0000 0.1600

GIVE THE CONSTANTS OF THE FIRST BOUNDARY LINE $ax+by+c=0$ SUCH THAT THE STARTING POINT FALLS IN THE REGION $ax+by+c \leq 0$

A= 1.0000

B= 0.0000

C= -0.2000

GIVE THE CONSTANTS OF THE SECOND BOUNDARY LINE $ax+by+c=0$ SUCH THAT THE STARTING POINT FALLS IN THE REGION $ax+by+c \leq 0$

A= 0.0000

B= 1.0000

C= -0.3000

GIVE THE RELATIVE PERMEABILITY OF THE INITIAL POINT

1.0000

GIVE THE LENGTH OF INFINITSIMAL ELEMENT ALONG THE EQUIPOTENTIAL SURFACE

0.0030

RI=	0.0030	ZI=	0.1600
RI=	0.0060	ZI=	0.1601
RI=	0.0090	ZI=	0.1602
RI=	0.0120	ZI=	0.1604
RI=	0.0150	ZI=	0.1606
RI=	0.0180	ZI=	0.1607
RI=	0.0209	ZI=	0.1613
RI=	0.0239	ZI=	0.1618
RI=	0.0269	ZI=	0.1623
RI=	0.0298	ZI=	0.1628
RI=	0.0327	ZI=	0.1635
RI=	0.0357	ZI=	0.1642
RI=	0.0386	ZI=	0.1649
RI=	0.0415	ZI=	0.1657
RI=	0.0443	ZI=	0.1666
RI=	0.0472	ZI=	0.1675
RI=	0.0500	ZI=	0.1685
RI=	0.0528	ZI=	0.1696
RI=	0.0556	ZI=	0.1707
RI=	0.0584	ZI=	0.1719
RI=	0.0611	ZI=	0.1731
RI=	0.0638	ZI=	0.1744
RI=	0.0665	ZI=	0.1758
RI=	0.0691	ZI=	0.1772
RI=	0.0717	ZI=	0.1786
RI=	0.0743	ZI=	0.1801
RI=	0.0769	ZI=	0.1817
RI=	0.0794	ZI=	0.1833
RI=	0.0819	ZI=	0.1850
RI=	0.0843	ZI=	0.1868
RI=	0.0868	ZI=	0.1885
RI=	0.0891	ZI=	0.1904
RI=	0.0915	ZI=	0.1923
RI=	0.0938	ZI=	0.1942
RI=	0.0960	ZI=	0.1962
RI=	0.0982	ZI=	0.1982
RI=	0.1004	ZI=	0.2003
RI=	0.1025	ZI=	0.2024
RI=	0.1046	ZI=	0.2046
RI=	0.1066	ZI=	0.2068
RI=	0.1086	ZI=	0.2090
RI=	0.1105	ZI=	0.2113
RI=	0.1124	ZI=	0.2137
RI=	0.1142	ZI=	0.2160
RI=	0.1160	ZI=	0.2185
RI=	0.1177	ZI=	0.2209
RI=	0.1194	ZI=	0.2234
RI=	0.1211	ZI=	0.2259
RI=	0.1226	ZI=	0.2285
RI=	0.1241	ZI=	0.2311
RI=	0.1256	ZI=	0.2337
RI=	0.1270	ZI=	0.2363
RI=	0.1284	ZI=	0.2390
RI=	0.1298	ZI=	0.2417
RI=	0.1309	ZI=	0.2444
RI=	0.1321	ZI=	0.2472
RI=	0.1332	ZI=	0.2500

RI= 0.1342 ZI= 0.2528
 RI= 0.1352 ZI= 0.2556
 RI= 0.1362 ZI= 0.2585
 RI= 0.1370 ZI= 0.2613
 RI= 0.1379 ZI= 0.2642
 RI= 0.1386 ZI= 0.2671
 RI= 0.1393 ZI= 0.2701
 RI= 0.1400 ZI= 0.2730
 RI= 0.1405 ZI= 0.2759
 RI= 0.1410 ZI= 0.2789
 RI= 0.1415 ZI= 0.2819
 RI= 0.1419 ZI= 0.2848
 RI= 0.1422 ZI= 0.2878
 RI= 0.1424 ZI= 0.2908
 RI= 0.1426 ZI= 0.2938
 RI= 0.1428 ZI= 0.2968
 RI= 0.1428 ZI= 0.2998
 RIA= 0.1428 ZIA= 0.3000
 RI= 0.1428 ZI= 0.3028

DO YOU WANT TO CALCULATE MORE EQUIPOTENTIAL SURFACE IF YES THEN WRITE -1- ELSE WRITE -0-

1

GIVE THE INITIAL POINT OF THE DESIRED EQUIPOTENTIAL SURFACE

0.0000 0.1800

GIVE THE EXTENSION POINT OF THE EQUIPOTENTIAL SURFACE

0.0000 0.1800

GIVE THE CONSTANTS OF THE FIRST BOUNDARY LINE : $ax+by+c=0$ SUCH THAT THE STARTING POINT FALLS IN THE REGION: $ax+by+c \leq 0$

A= 1.0000

B= 0.0000

C= -0.2000

GIVE THE CONSTANTS OF THE SECOND BOUNDARY LINE: $ax+by+c=0$ SUCH THAT THE STARTING POINT FALLS IN THE REGION: $ax+by+c \leq 0$

A= 0.0000

B= 1.0000

C= -0.3000

GIVE THE RELATIVE PERMEABILITY OF THE INITIAL POINT

1.0000

GIVE THE LENGTH OF INFINITSIMAL ELEMENT ALONG THE EQUIPOTENTIAL SURFACE

0.0030

RI= 0.0000 ZI= 0.1800
 RI= 0.0060 ZI= 0.1801
 RI= 0.0090 ZI= 0.1802
 RI= 0.0120 ZI= 0.1804
 RI= 0.0150 ZI= 0.1807
 RI= 0.0180 ZI= 0.1811
 RI= 0.0209 ZI= 0.1816
 RI= 0.0239 ZI= 0.1821
 RI= 0.0268 ZI= 0.1827
 RI= 0.0297 ZI= 0.1832
 RI= 0.0326 ZI= 0.1841
 RI= 0.0355 ZI= 0.1849
 RI= 0.0384 ZI= 0.1858
 RI= 0.0412 ZI= 0.1867
 RI= 0.0441 ZI= 0.1877
 RI= 0.0469 ZI= 0.1888
 RI= 0.0498 ZI= 0.1900
 RI= 0.0524 ZI= 0.1912
 RI= 0.0551 ZI= 0.1925
 RI= 0.0577 ZI= 0.1939
 RI= 0.0604 ZI= 0.1953
 RI= 0.0630 ZI= 0.1968
 RI= 0.0655 ZI= 0.1984

R1= 0.0681 Z1= 0.2000
 R1= 0.0705 Z1= 0.2017
 R1= 0.0730 Z1= 0.2034
 R1= 0.0754 Z1= 0.2051
 R1= 0.0777 Z1= 0.2071
 R1= 0.0800 Z1= 0.2090
 R1= 0.0825 Z1= 0.2110
 R1= 0.0845 Z1= 0.2130
 R1= 0.0867 Z1= 0.2151
 R1= 0.0888 Z1= 0.2173
 R1= 0.0908 Z1= 0.2194
 R1= 0.0928 Z1= 0.2217
 R1= 0.0947 Z1= 0.2240
 R1= 0.0964 Z1= 0.2263
 R1= 0.0984 Z1= 0.2287
 R1= 0.1002 Z1= 0.2311
 R1= 0.1019 Z1= 0.2336
 R1= 0.1035 Z1= 0.2361
 R1= 0.1051 Z1= 0.2387
 R1= 0.1066 Z1= 0.2413
 R1= 0.1081 Z1= 0.2439
 R1= 0.1095 Z1= 0.2465
 R1= 0.1108 Z1= 0.2492
 R1= 0.1120 Z1= 0.2520
 R1= 0.1132 Z1= 0.2547
 R1= 0.1143 Z1= 0.2575
 R1= 0.1154 Z1= 0.2603
 R1= 0.1164 Z1= 0.2631
 R1= 0.1173 Z1= 0.2659
 R1= 0.1181 Z1= 0.2689
 R1= 0.1189 Z1= 0.2718
 R1= 0.1196 Z1= 0.2747
 R1= 0.1202 Z1= 0.2776
 R1= 0.1207 Z1= 0.2806
 R1= 0.1212 Z1= 0.2836
 R1= 0.1216 Z1= 0.2865
 R1= 0.1220 Z1= 0.2895
 R1= 0.1222 Z1= 0.2925
 R1= 0.1224 Z1= 0.2953
 R1= 0.1225 Z1= 0.2980
 R1A= 0.1225 Z1A= 0.3000
 R1= 0.1226 Z1= 0.3015

DO YOU WANT TO CALCULATE THE EQUIPOTENTIAL SURFACE. IF YES THEN
WRITE 1 ELSE WRITE 0

1

calculating the equipotential surface

GIVE THE INITIAL POINT OF THE DESIRED EQUIPOTENTIAL SURFACE

0.0000 0.2000

GIVE THE EXTENSION POINT OF THE EQUIPOTENTIAL SURFACE

0.0000 0.2000

GIVE THE CONSTANTS OF THE FIRST BOUNDARY LINE : $ax+by+c=0$ SUCH THAT THE
STARTING POINT FALLS IN THE REGION: $ax+by+c \leq 0$

A= 1.0000

B= 0.0000

C= -0.2000

GIVE THE CONSTANTS OF THE SECOND BOUNDARY LINE: $ax+by+c=0$ SUCH THAT THE
STARTING POINT FALLS IN THE REGION: $ax+by+c \geq 0$

A= 0.0000

B= 1.0000

C= -1.0000

GIVE THE RELATIVE PERMEABILITY OF THE INITIAL POINT

0.0000

GIVE THE LENGTH OF INFINITSIMAL ELEMENT ALONG THE EQUIPOTENTIAL SURFACE

0.0200

R1= 0.0200 Z1= 0.2000

R1= 0.0356 Z1= 0.2500

R1= 0.0581 Z1= 0.2715

R1= 0.0746 Z1= 0.2835

R1= 0.0864 Z1= 0.2884

R1= 0.1008 Z1= 0.2957

R1= 0.1093 Z1= 0.2708

R1= 0.1145 Z1= 0.2901

R1= 0.1162 Z1= 0.3100

R1= 0.1145 Z1= 0.3300

R1= 0.1095 Z1= 0.3493

R1= 0.1015 Z1= 0.3675

R1= 0.0908 Z1= 0.3848

R1= 0.0765 Z1= 0.3988

R1A= 0.0763 Z1A= 0.3990

R1= 0.0637 Z1= 0.4111

DO YOU WANT TO CALCULATE MORE EQUIPOTENTIAL SURFACE IF YES THEN WRITE -1- ELSE WRITE 0-

1

GIVE THE INITIAL POINT OF THE INITIAL EQUIPOTENTIAL SURFACE

0.0000 0.0000

GIVE THE EXTENSION POINT OF THE EQUIPOTENTIAL SURFACE

0.0000 0.2000

GIVE THE COEFFICIENTS OF THE FIRST BOUNDARY LINE $ax+by+c=0$ SUCH THAT THE STARTING POINT FALLS IN THE REGION $ax+by+c > 0$

A= 1.0000

B= 1.0000

C= -0.0000

GIVE THE COEFFICIENTS OF THE SECOND BOUNDARY LINE $ax+by+c=0$ SUCH THAT THE STARTING POINT FALLS IN THE REGION $ax+by+c < 0$

A= 0.0000

B= 1.0000

C= -0.3550

GIVE THE RELATIVE PERMEABILITY OF THE INITIAL POINT

1.0000

GIVE THE LENGTH OF INFINITSIMAL ELEMENT ALONG THE EQUIPOTENTIAL SURFACE

0.0020

R1= 0.0020 Z1= 0.2000

R1= 0.0040 Z1= 0.2000

R1= 0.0060 Z1= 0.2001

R1= 0.0080 Z1= 0.2002

R1= 0.0100 Z1= 0.2004

R1= 0.0120 Z1= 0.2006

R1= 0.0140 Z1= 0.2008

R1= 0.0160 Z1= 0.2011

R1= 0.0180 Z1= 0.2014

R1= 0.0200 Z1= 0.2018

R1= 0.0220 Z1= 0.2021

R1= 0.0240 Z1= 0.2026

R1= 0.0260 Z1= 0.2031

R1= 0.0280 Z1= 0.2036

R1= 0.0300 Z1= 0.2042

R1= 0.0320 Z1= 0.2048

R1= 0.0340 Z1= 0.2054

R1= 0.0360 Z1= 0.2060

R1= 0.0380 Z1= 0.2066

R1= 0.0400 Z1= 0.2072

R1= 0.0420 Z1= 0.2078

R1= 0.0440 Z1= 0.2084

R1= 0.0460 Z1= 0.2090

R1= 0.0480 Z1= 0.2096

R1=	0.0481	Z1=	0.2118
R1=	0.0498	Z1=	0.2127
R1=	0.0516	Z1=	0.2137
R1=	0.0535	Z1=	0.2147
R1=	0.0554	Z1=	0.2158
R1=	0.0574	Z1=	0.2169
R1=	0.0595	Z1=	0.2180
R1=	0.0615	Z1=	0.2192
R1=	0.0636	Z1=	0.2204
R1=	0.0657	Z1=	0.2216
R1=	0.0678	Z1=	0.2228
R1=	0.0699	Z1=	0.2241
R1=	0.0720	Z1=	0.2254
R1=	0.0741	Z1=	0.2268
R1=	0.0762	Z1=	0.2282
R1=	0.0783	Z1=	0.2296
R1=	0.0804	Z1=	0.2310
R1=	0.0825	Z1=	0.2324
R1=	0.0846	Z1=	0.2339
R1=	0.0867	Z1=	0.2354
R1=	0.0888	Z1=	0.2370
R1=	0.0909	Z1=	0.2385
R1=	0.0930	Z1=	0.2401
R1=	0.0951	Z1=	0.2417
R1=	0.0972	Z1=	0.2434
R1=	0.0993	Z1=	0.2450
R1=	0.1014	Z1=	0.2467
R1=	0.1035	Z1=	0.2484
R1=	0.1056	Z1=	0.2501
R1=	0.1077	Z1=	0.2519
R1=	0.1098	Z1=	0.2536
R1=	0.1119	Z1=	0.2554
R1=	0.1140	Z1=	0.2572
R1=	0.1161	Z1=	0.2590
R1=	0.1182	Z1=	0.2608
R1=	0.1203	Z1=	0.2627
R1=	0.1224	Z1=	0.2645
R1=	0.1245	Z1=	0.2664
R1=	0.1266	Z1=	0.2683
R1=	0.1287	Z1=	0.2702
R1=	0.1308	Z1=	0.2721
R1=	0.1329	Z1=	0.2740
R1=	0.1350	Z1=	0.2760
R1=	0.1371	Z1=	0.2779
R1=	0.1392	Z1=	0.2798
R1=	0.1413	Z1=	0.2818
R1=	0.1434	Z1=	0.2838
R1=	0.1455	Z1=	0.2857
R1=	0.1476	Z1=	0.2877
R1=	0.1497	Z1=	0.2897
R1=	0.1518	Z1=	0.2917
R1=	0.1539	Z1=	0.2937
R1=	0.1560	Z1=	0.2957
R1=	0.1581	Z1=	0.2977
R1=	0.1602	Z1=	0.2997
R1=	0.1623	Z1=	0.3017
R1=	0.1644	Z1=	0.3037
R1=	0.1665	Z1=	0.3057
R1=	0.1686	Z1=	0.3077
R1=	0.1707	Z1=	0.3097
R1=	0.1728	Z1=	0.3117
R1=	0.1749	Z1=	0.3137

[illegible]

5

TANGENTIAL FIELD CALCULATION

DO YOU WANT TO CALCULATE THE TANGENTIAL FIELD COMPONENTS
IF YES THEN WRITE 1 ELSE WRITE 0

1

GIVE THE NUMBER OF SUCH POINTS

10

GIVE THE LOCATION AND SLOPE OF NORMAL AT SUCH POINTS

0.0000	0.1000	10000000000.0000
0.0100	0.1000	10000000000.0000
0.0200	0.1000	10000000000.0000
0.0300	0.1000	10000000000.0000
0.0400	0.1000	10000000000.0000
0.0500	0.1000	10000000000.0000
0.0600	0.1000	10000000000.0000
0.0700	0.1000	10000000000.0000
0.0800	0.1000	10000000000.0000
0.0900	0.1000	10000000000.0000

(-----)

Er=4

TANGENTIAL FIELD VECTOR IS

-0.051615
356.420084
0.106885
0.002207
0.000254
-0.016162
-0.034436
-0.074776
0.017159
0.039238

(-----)

Er=6

TANGENTIAL FIELD VECTOR IS

-0.108789
356.452848
0.127197
0.002924
0.001031
-0.019305
-0.041022
-0.089340
0.025388
0.047371

(-----)

Er=8

TANGENTIAL FIELD VECTOR IS

-0.118267
356.470924
0.138461
0.003367
0.001132
-0.021057
-0.044685
-0.097446
0.029236
0.051992

(-----)

Er=10

TANGENTIAL FIELD VECTOR IS

-0.124271
356.482375
0.145615
0.003666

FIGURES

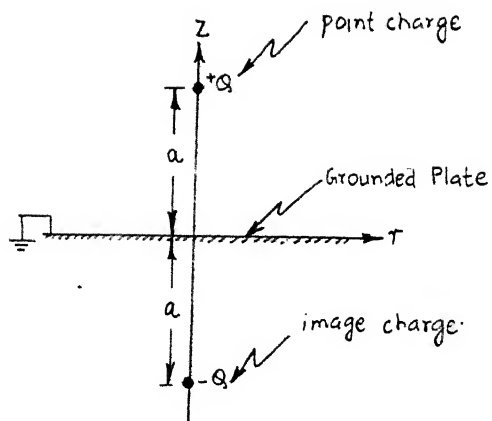


fig.1. Point Charge and grounded
Conducting Plate (or Earth)

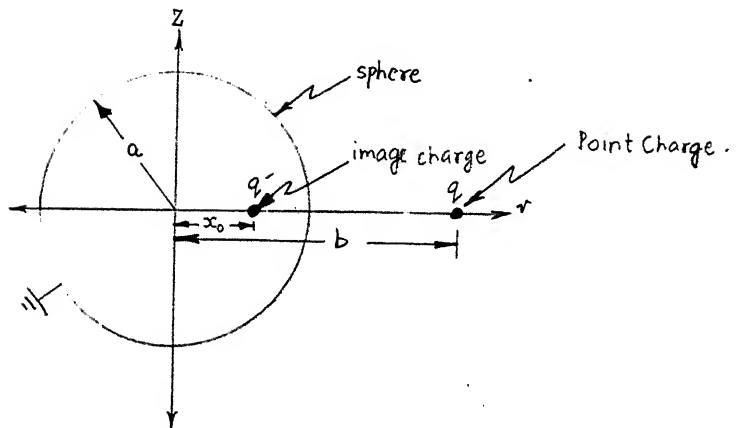


fig.2. Grounded Conducting Sphere and
a Point Charge Outside it.

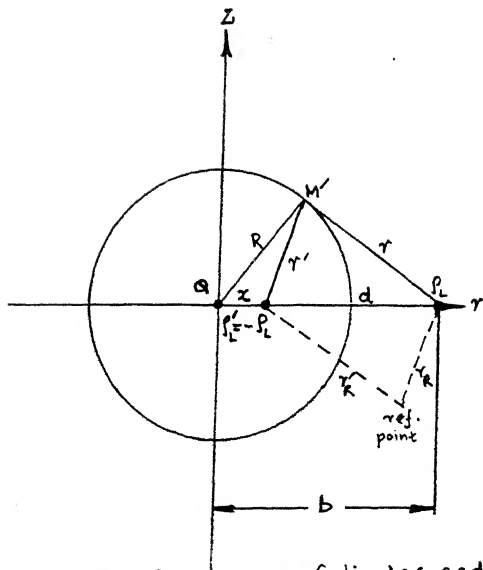


fig3. Conducting Cylinder and a Line Charge.

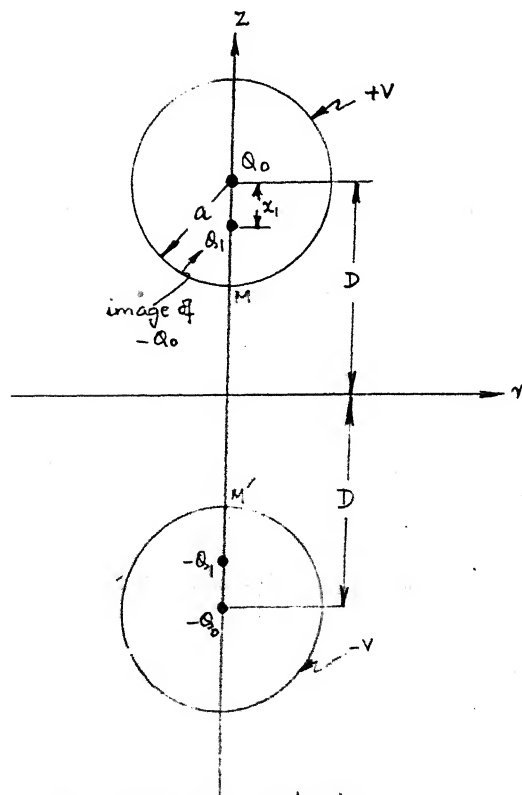


fig4. Spherical electrodes

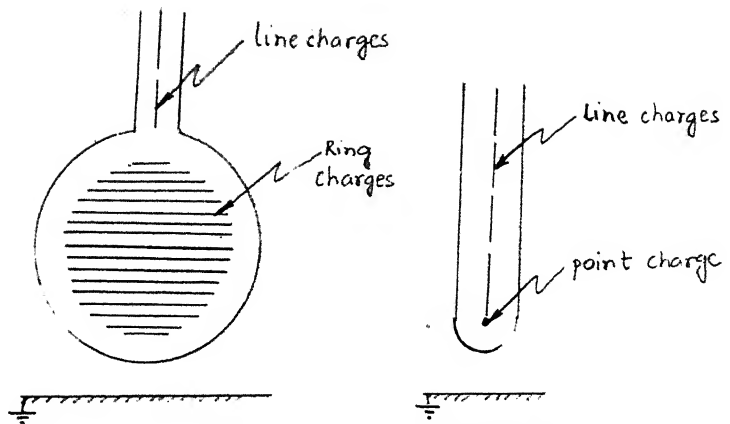


fig.5. Representation Of Surfaces Using Point , Line and Ring charges.

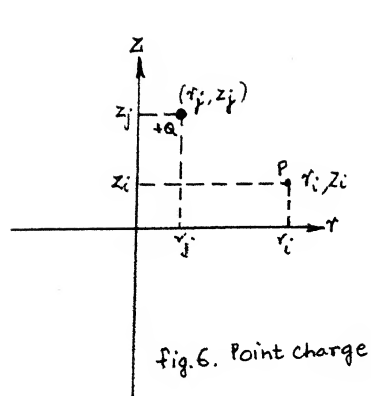


fig.6. Point charge

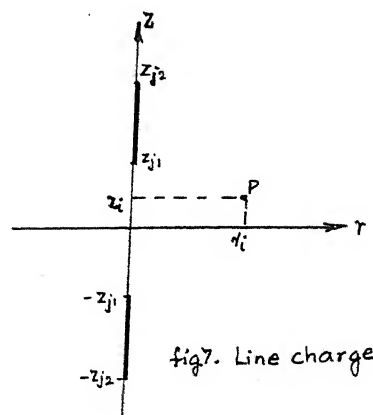


fig.7. Line charge

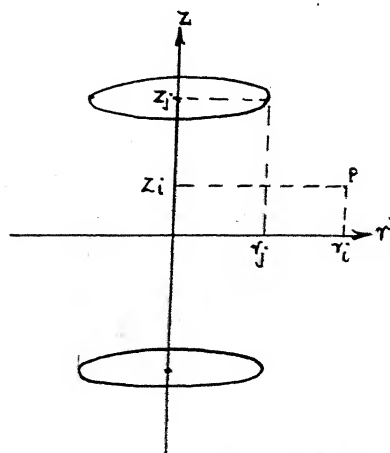


fig.8. Ring Charge

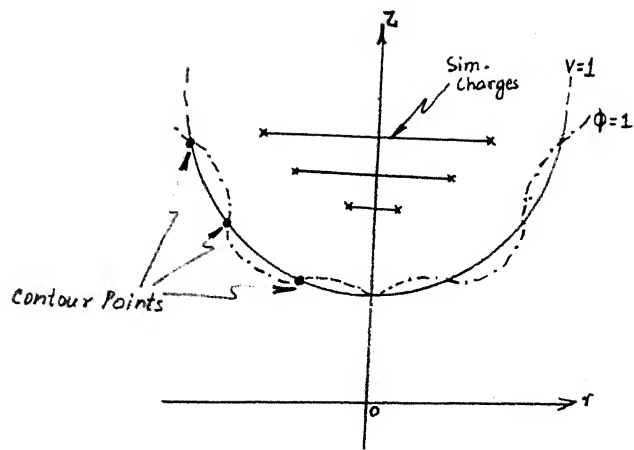


fig.9. Comparision of an existing, —, and a Simulated, ---, surface of an electrode.

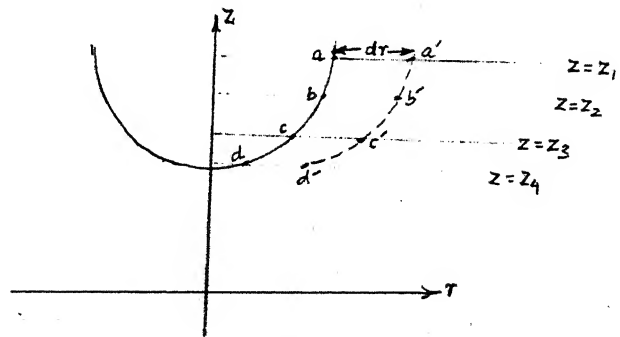


fig.10. Equipotential Surface Plotting

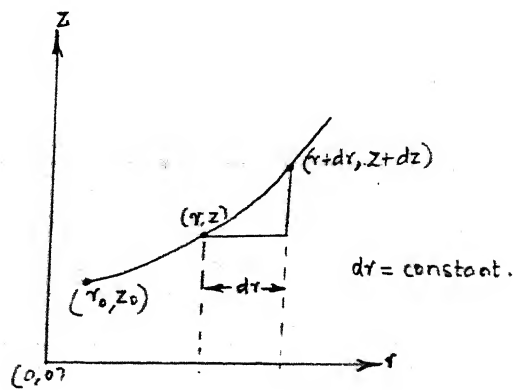


fig.11. Equipotential Surface Plotting.

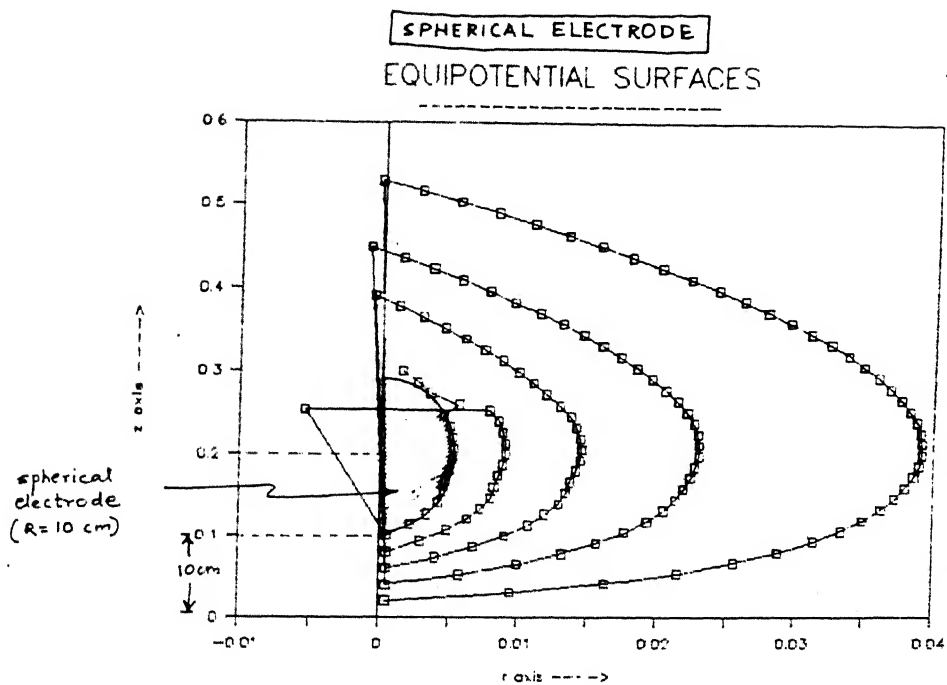


fig. 12.

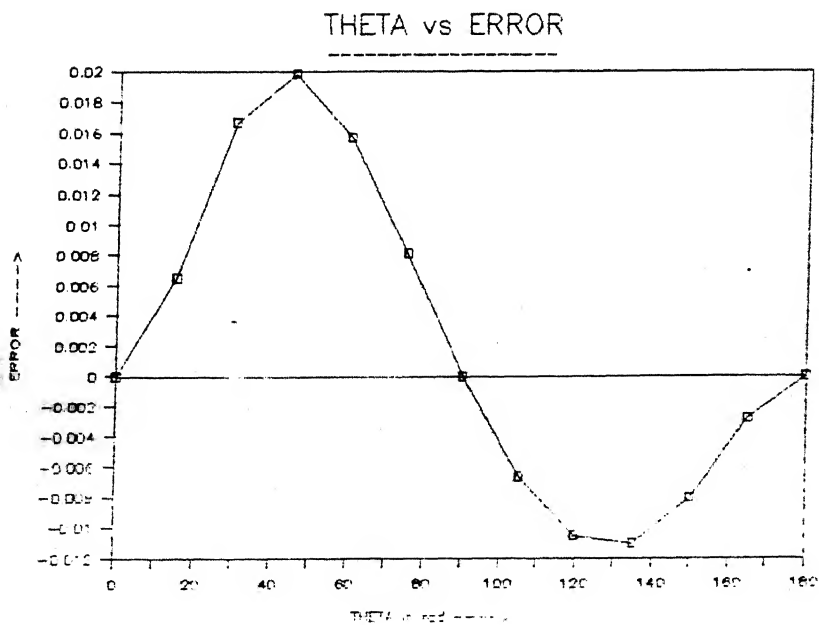


fig. 13.

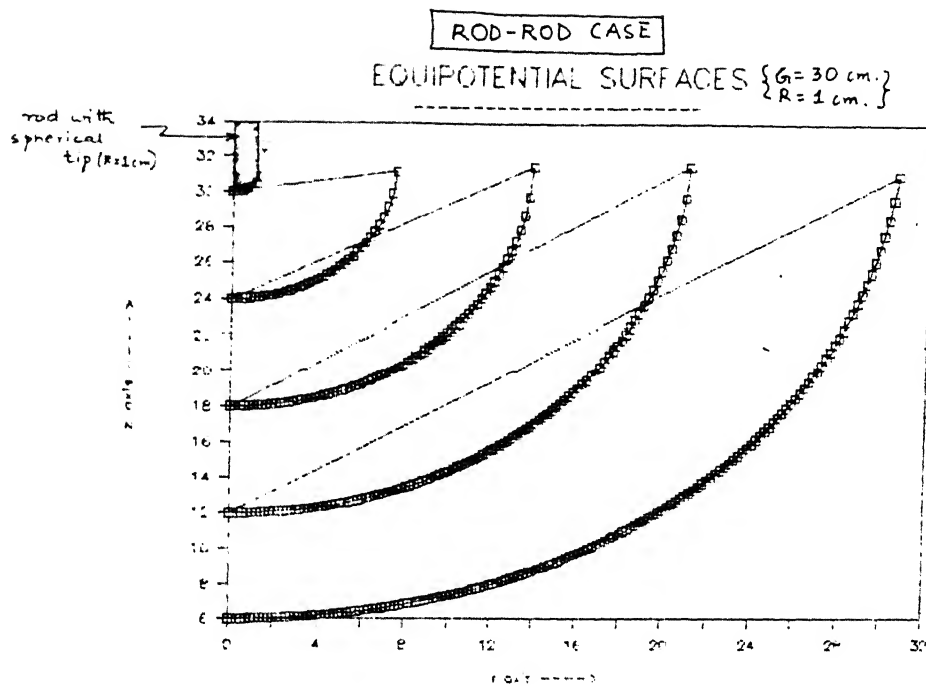


fig. 14

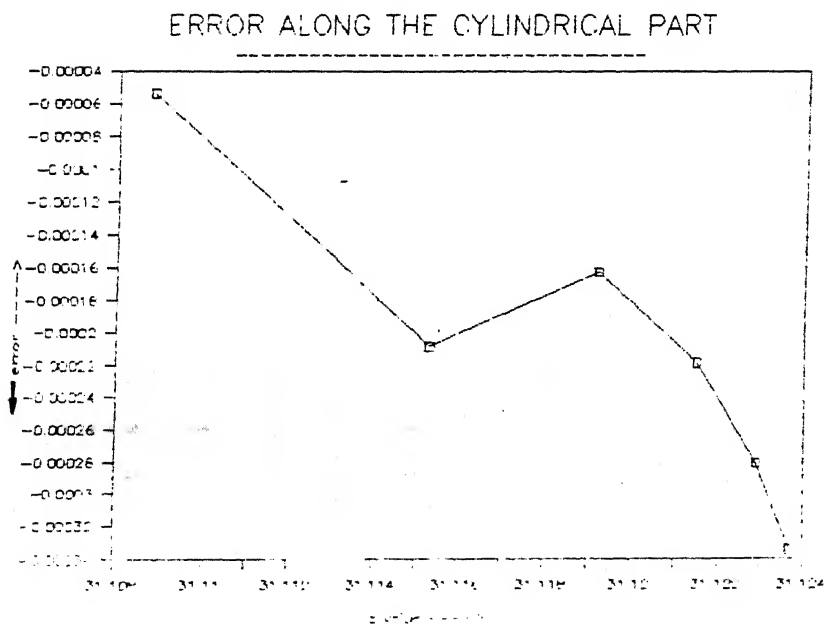


fig. 15

NO OF CHARGES vs ERROR

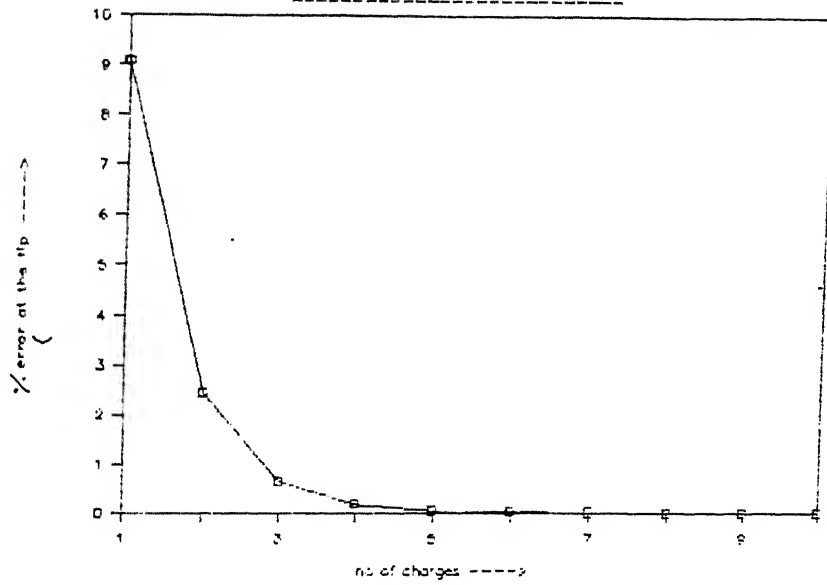


fig. 16

ROGOWSKI SURFACE EQUIPOTENTIAL SURFACES

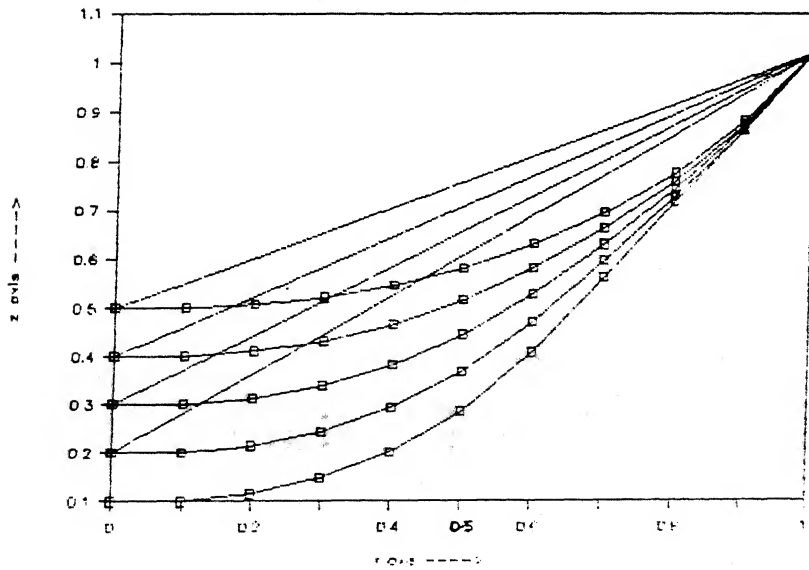
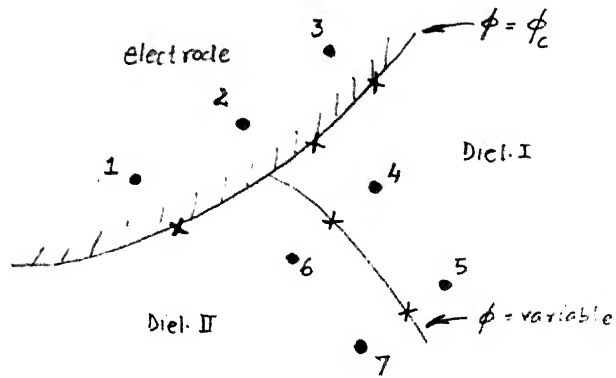


fig. 17



• charges
X Contour Points.

fig. 18 Simulation of dielectric boundary by discrete charges.

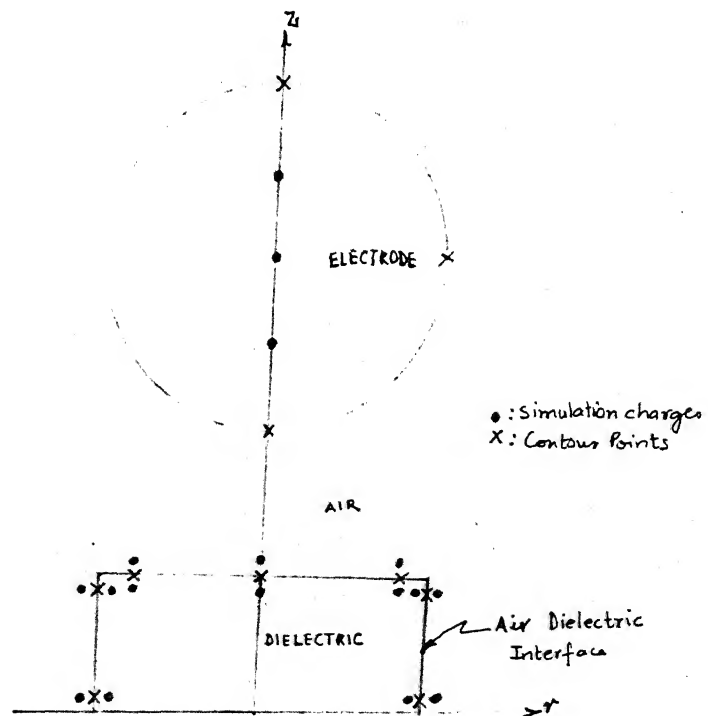


fig. 19. The multidielectric case sample problem

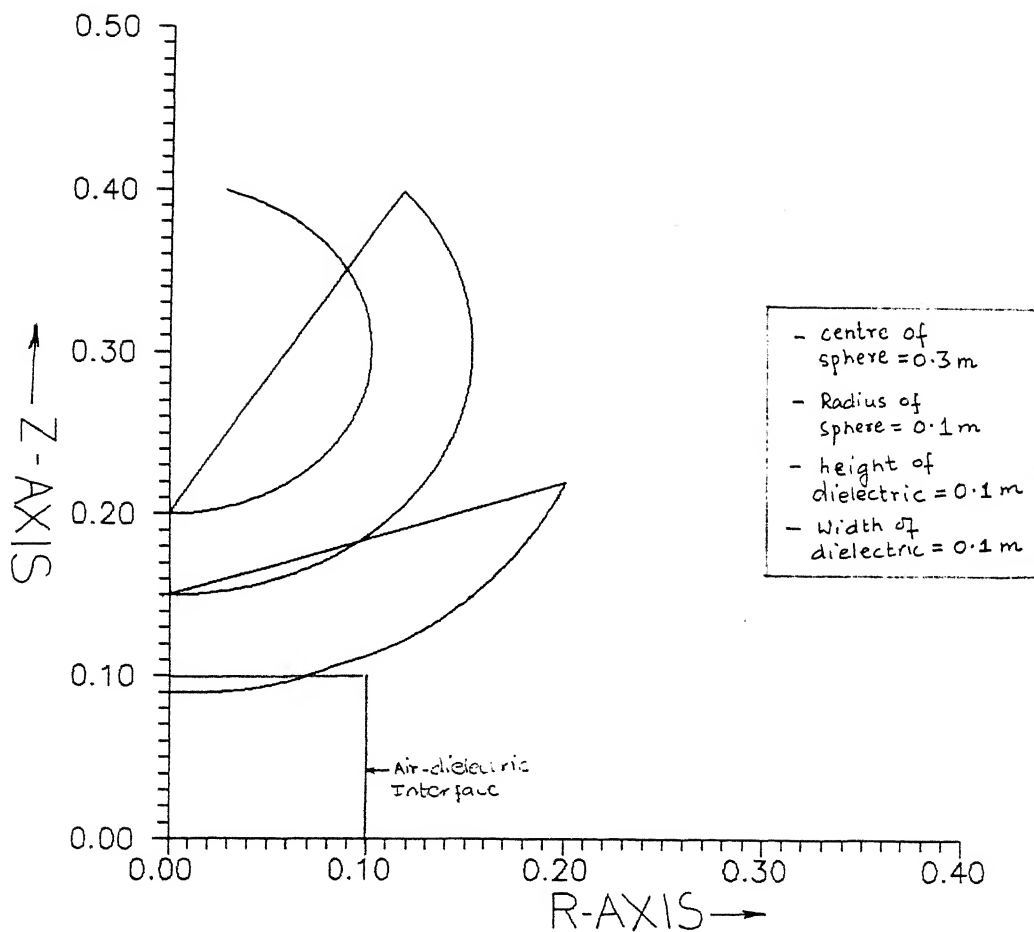


fig.20 Equipotential Surface for the sphere-dielectric problem

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